

Design Example Report

| | |
|------------------------|---|
| Title | 52 W_{NOM} and 82 W_{PK} Power Multi-Output Flyback Converter with One CV and One CC Using InnoMux™2-EP IMX2268C |
| Specification | 90 VAC – 265 VAC Input; 12 V / 2 A _{NOM} / 4.5 A _{PK} , 60 V – 75 V / 380 mA Outputs |
| Application | 32" TV PSU |
| Author | Applications Engineering Department |
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Summary and Features

Unique single-stage conversion, multiple-output, flyback architecture enabling:

- High efficiency across the universal line range
- High regulation accuracy - independently regulated 12 V / 2 A nominal and 4.5 A peak CV output
- One CC (LED) output with wide string voltage range of 60 V to 75 V
- Configurable for
 - Analog dimming mode
 - Straight PWM dimming mode
 - Filtered PWM dimming mode
 - Hybrid dimming mode
- Safety features
 - Output overvoltage protection (OVP), eliminating the need for a fault protection optocoupler
 - Output power limit set independently for each output
 - Accurate thermal protection with hysteretic shutdown
 - Input voltage monitor with accurate brown-in/brown-out and overvoltage protection
- Audible noise is 24 dBA in operation mode, and 19 dBA in standby mode

InnoMux2-EP is the industry first single chip AC/DC with isolated, safety-rated integrated multiple feedbacks. In addition, the pulse sharing significantly reduces the audible noise to enable use in quiet appliances.

The control chip incorporates isolated feedback and communication channels, combining all the benefits of secondary-side control with the simplicity of primary-side regulation.

The new architecture achieves accurate cross regulation across multiple outputs and high overall efficiency while simplifying the overall system by obviating the need for post-regulation. The single-stage converter reduces board size significantly and reduces the part count compared to the equivalent conventional converter based on multiple conversion stage topology.

PATENT INFORMATION

The products and applications illustrated herein (including transformer construction and circuits external to the products) may be covered by one or more U.S. and foreign patents, or potentially by pending U.S. and foreign patent applications assigned to Power Integrations. A complete list of Power Integrations' patents may be found at www.power.com. Power Integrations grants its customers a license under certain patent rights as set forth at <https://www.power.com/company/intellectual-property-licensing/>.



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Important Note:

Although this board is designed to satisfy safety isolation requirements, the engineering prototype has not been agency approved. Therefore, all testing should be performed using an isolation transformer to provide the AC input to the prototype board.



1 Introduction

This engineering report describes a Switch Mode Power Supply (SMPS) intended for TV applications. The SMPS utilizes the Power Integrations' InnoMux2-EP controller. The controller implements a multiplexing power control algorithm. Energy stored in the primary winding of the transformer during primary conduction interval is subsequently delivered to only one of the converter's main outputs (CV1 or LED). More specifically, this is achieved by controlling the switch SW1 (Figure 1). Utilizing a single magnetic component (transformer TX 1), the controller directs the energy flow as needed to all outputs based on respective loading requirements, thus keeping each output accurately controlled. If the energy pulse needs to be delivered to the CV1 output, SW1 is turned ON prior to the end of the primary conduction interval. Otherwise, if SW1 is OFF, the energy is delivered to the LED output via the rectification diode D1.

The SMPS has one Constant Voltage (CV) output, 12 V / 2 A_{NOM} / 4.5 A_{PK} and a single string Constant Current (CC) output, capable of delivering maximum of 0.38 A current into an LED stack with voltage from 60 V to 75 V. The current through the LED stack is controlled from zero to maximum by 2 PWM dimming signals (DIM1 and DIM2). The Power Supply Unit (PSU) can deliver a total maximum continuous output power of 52 W and peak output power of 82 W, with universal mains input (from 90 VAC to 265 VAC).

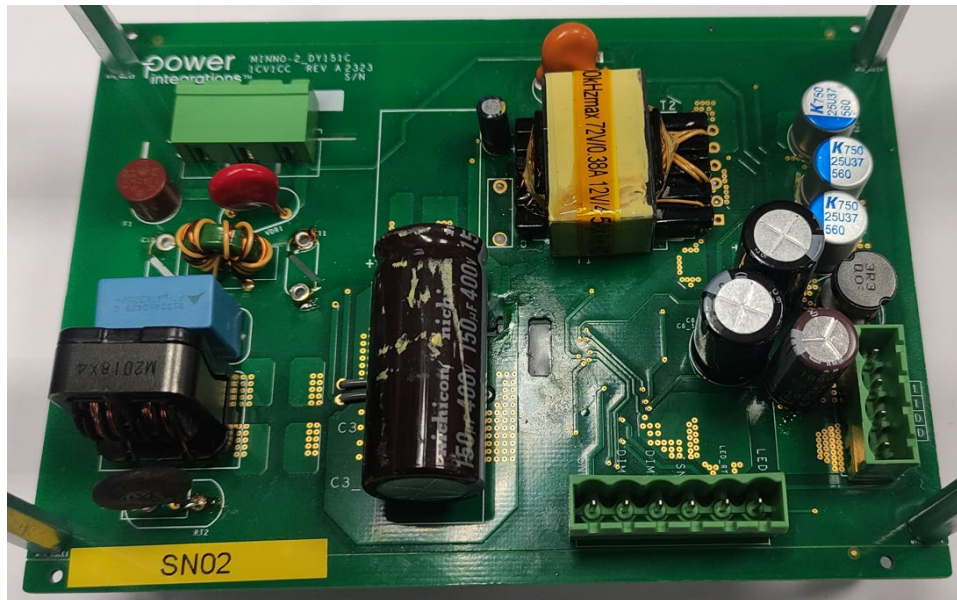


Figure 1 – PCB, Top View.

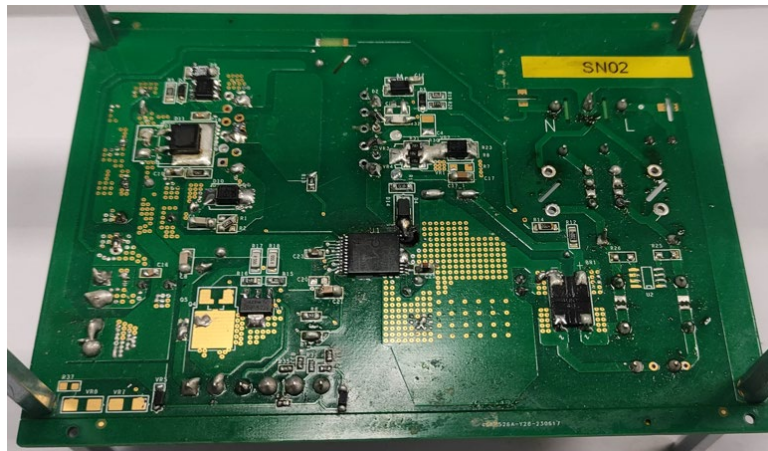


Figure 2 – PCB, Bottom View.

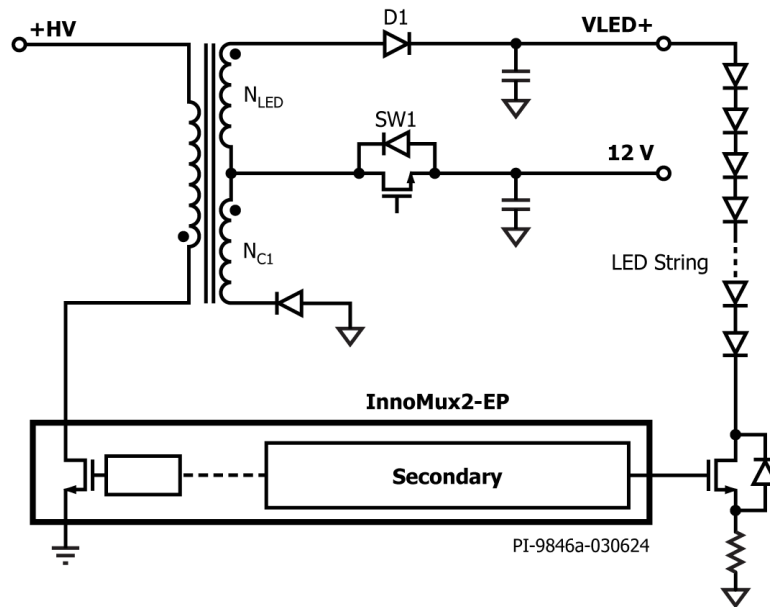


Figure 3 – DER-714 High Level Schematic.

The VCV1 and VLED pins continuously sense the output voltages. If the voltage of any of the outputs drops below regulation level, the multi-output controller InnoMux2-EP sends a request for pulse to primary-side controller. This type of pulse-by-pulse regulation results in quick response and excellent cross regulation. For the described multiplexing algorithm to work correctly, it is essential that the reflected voltage of each winding must be higher than that of the preceding lower output voltage winding to effectively steer the power:

$$\frac{V_{CV1}}{N_{C1}} < \frac{V_{LED}}{N_{C1} + N_{LED}}$$

Transformer with stacked or independent secondaries may be used as appropriate. The document contains the power supply specification, schematic, bill of materials, transformer documentation, printed circuit layout, and performance data.

2 Power Supply Specification

The table below represents the minimum acceptable performance of the design. The actual performance is illustrated in the results section.

| Description | Symbol | Min | Typ | Max | Units | Comment |
|---------------------------|----------------------------|---------------------------|-------|------|-------|--|
| Input | | | | | | |
| Voltage | V_{IN} | 90 | | 265 | VAC | 2 / 3 Wire Input. |
| Frequency | f_{LINE} | 47 | 50/60 | 64 | Hz | |
| Output | | | | | | |
| Output Voltage 1 | V_{OUT1} | 11.4 | 12 | 12.6 | V | ±5%. 20 MHz Bandwidth. |
| Output Ripple Voltage 1 | V_{RIPPLE1} | | | 120 | mV | |
| Output Current 1 | I_{OUT1} | 0 | | 2 | A | |
| Output Peak Current 1 | I_{OUT1_PK} | | 4.5 | | A | |
| LED Voltage | V_{OUT2} | 60 | 72 | 75 | V | |
| LED Current | I_{OUT2} | 0 | 0.38 | 0.38 | A | |
| Total Output Power | | | | | | |
| Continuous Output Power | P_{OUT} | | 52 | | W | |
| Efficiency | | | | | | |
| Full Load | η | 85 | | | % | Measured at 115 / 230 VAC, P _{OUT} 25 °C. Measured at 230 VAC 25 °C, 12 V 10 mA, STDBY Pin Pulled Low. |
| No-Load Input Power | | | | <0.3 | W | |
| Environmental | | | | | | |
| Conducted EMI Safety | | Meets CISPR22B / EN55022B | | | | |
| Surge Common Mode | | | | 2 | kV | Combination Wave, 12 Ω Common Mode. |
| Surge Differential Mode | | | | 1 | kV | Combination Wave, 2 Ω Differential Mode. |
| ESD | | ±2 | | ±15 | kV | Air Discharge. |
| | | ±2 | | ±8 | | Contact Discharge. |
| Ambient Temperature | T_{AMB} | 0 | | 40 | °C | Free Convection, Sea Level. |

4 Circuit Description

4.1 Input Rectifier and EMI Filter

Fuse F1 isolates the circuit and provides protection from component failure, and the common mode chokes L1 and L2 with capacitor C2 attenuation for EMI. Bridge rectifier BR1 rectifies the AC line voltage and provides a full wave rectified DC voltage across the filter capacitor C3. Varistor VDR1 provides protection against differential voltage surges. Resistor RT2 (NTC) limits the inrush current. Capacitor C9 is used to mitigate the common mode EMI.

4.2 Primary-Side

4.2.1 Primary Switch Arrangements

The transformer primary is connected between the input DC bus (TXPRI+) and the drain D of the integrated primary switch of InnoMux2-EP (U1 pin 24).

A Zener type primary clamp (R11, R29, R30, R31, VR2, C17, D4) is used to limit the peak drain voltage of U1 at the instant of turn-off of the switch inside U1.

4.2.2 Primary-Side Controller Power Source and OVP Protection

The primary-side controller is part of the InnoMux2-EP IC (U1). It is self-starting, using an internal high-voltage current source to charge the BPP capacitor C25, when AC voltage is first applied to the converter input. During normal operation (steady-state) the primary-side of the controller is powered from an auxiliary winding on the main transformer. The voltage across this winding is rectified and filtered using diode D2 and capacitor C29, and then connected to the BPP pin via a current limiting resistor R20.

4.2.3 Primary-Side OVP, Brown-In and Brown-Out Protection

A crude primary-side output overvoltage protection (OVP) is implemented by Zener diode D5 and the series resistor R19. In the event of an uncontrolled overvoltage at the output, the auxiliary winding voltage increases and causes breakdown of D5 which then causes a current to flow into the BPP pin of IC U1. If this current exceeds I_{SD} threshold, InnoMux2-EP controller will latch off and prevent any further increase in output voltage.

Resistor R12 and R14 provide input voltage sense protection for undervoltage and overvoltage conditions.

4.2.4 Primary Peak Current Limit

The value of capacitor C25 is used to set the maximum primary current to STANDARD or to INCREASED level. In this case 4.7 μ F capacitance sets the primary-side controller peak current limit to its INCREASED level of 2.6 A.

4.3 Secondary-Side

The secondary-side of the InnoMux2-EP IC (U1) is powered from the 5 V BPS rail generated internally. Capacitor C23 is a local decoupling capacitor.

4.3.1 Primary to Secondary-Side Communication

The secondary-side of the InnoMux2-EP IC (U1) sends a request to the primary-side controller to initiate a switching cycle, by sending a pulse via the internal FluxLink, a galvanically isolated communication channel.

4.3.2 InnoMux2-EP Power Supply

During start-up the InnoMux2-EP secondary-side controller is powered from LED rail via R10 or from FWD pin. There is a local decoupling capacitor C21 connected close to the VLED pin of U1. R10 and C21 are optional. An internal regulator reduces the LED+ voltage to 5 V and outputs it to the BPS bus (U1 pin 6).

In steady-state the voltage on VCV1 (U1 pin 10) exceeds $V_{CV1_{MIN}}$ (7.4 V to 9.3 V). The internal BPS regulator input is switched from VLED to VCV1 pin to reduce power dissipation in the regulator. R6 and C20 are optional. They provide local decoupling as well as ESD protection.

4.3.3 Selection MOSFET Drive

The gate drive amplitude for the selection MOSFET Q1 is approximately equal to the voltage on the BPS rail (5 V). Consequently, logic level MOSFETs are used. Capacitor C18 is charged up to the level of the V_{CV1} from the CV1 via diode (D3) to the CDR1 pin. When the selection MOSFET needs to be gated on, CDR1 pin voltage is raised from GND to BPS, and the selection MOSFET gate voltage (the other terminal of the capacitor C18) is lifted to $V_{CV1} + V_{BPS}$.

The secondary control circuit in InnoMux2-EP IC needs access to the idle ring waveform in order to calculate the timing and facilitate valley switching. Such access is ensured through the FW pin by keeping Q1 on after the secondary conduction time has expired.

4.3.4 Output Control

Output rectification for the CV1 output is provided by the diode (D8) and the CV1 selection MOSFET (Q1). A Π – type LC filter (C13, C14, C26, C15 and L3) ensures low output ripple voltage. The first stage filter capacitors C13, C14, C26 have low ESR to minimize the switching noise. A small multilayer ceramic (MLCC) capacitor C16 is connected across the CV1 output terminals and provides low impedance bypass for any high frequency noise components.

Output rectification for the LED output is provided by diodes (D8 and D1). Capacitors C5 and C6 are used to provide energy storage and filtering at the LED output.

The RC snubber network R1, R2 and C1 damps high-frequency ringing across the rectifier diode D1.

The RC snubber network R9 and C19 damps high-frequency ringing across the rectifier diode D8.

Zener diode D6 is used as a voltage clamp for the transformer CV1 winding.

Zener diodes VR7, VR8 and R37 can be used to limit the maximum LED voltage which can be predominantly caused by the leakage in the transformer. Zener diodes VR7, VR8 and R37 are optional and not populated in this DER.

When the selection MOSFET (Q1) is turned off and the SR diode (D8) is conducting, the voltage on the anode of D1 rises until it is forward biased. In this condition, all the transformer energy is directed to the LED output.

When the selection MOSFET (Q1) is on, the transformer secondary windings are designed such that the voltage on the anode of D1 is below the lowest working LED string voltage. Therefore, D1 will remain reverse biased and all the transformer energy is directed to the CV1 output via Q1.

The set point for the CV1 output is determined by the internal code settings, CV1 voltage is monitored via a feedback signal to the VCV1 pin of InnoMux2-EP IC.

LED+ output maximum voltage is set by the internal code. In this design it has been set to the default value 80 V. Note that the actual LED+ voltage is not set by the code and it varies depending on the LED stack voltage and the drain voltage (VSENSE) on the LED driver MOSFET (Q3).

4.3.5 LED Current Control and Dimming

The maximum LED current is set by the resistor values of R17 and R18. The application is configured for 2-wire filtered PWM dimming mode. The maximum current through the LED stack is 400 mA. It is achieved at 100% duty cycle on both DIM1 and DIM2.

Resistors R33, R34, R35, R36, R22, R27, VR5 and VR6 are DIM1 and DIM2 external circuitries.

Other dimming options are available, such as PWM, Analog and 1-wire dimming. For details, please see the latest data sheet for InnoMux2-EP IC on the Power Integrations website.

4.3.6 Output Power Limiting

A power limit is implemented individually for each output using the internal trim code in InnoMux2-EP IC (U1). The power delivered to any of the outputs is restricted by limiting

the maximum average frequency at which an output can receive. The frequency limit is set by the trim code bits PLIM1 and PLIM2. Namely, PLIM1 bits set the frequency limit for output CV1, and PLIM2 bits set the frequency limit for the LED output. If the frequency is exceeded for a predetermined time interval, the InnoMux2-EP controller will execute auto-restart.

4.3.7 Standby Mode

If the DIM2 input is held at 0 V the PSU enters "Standby Mode". The LED current is disabled and the internal LED driver circuit is powered down, reducing the controller's power consumption. Full rated power is still available at the CV1 output. The +V_LED output is maintained at a level of at least 8 V. The DIM2 input is a logic level type. If it is pulled up to above 3.3 V (5 V_{MAX}), the LED current will be enabled.

4.3.8 Start-Up Sequence

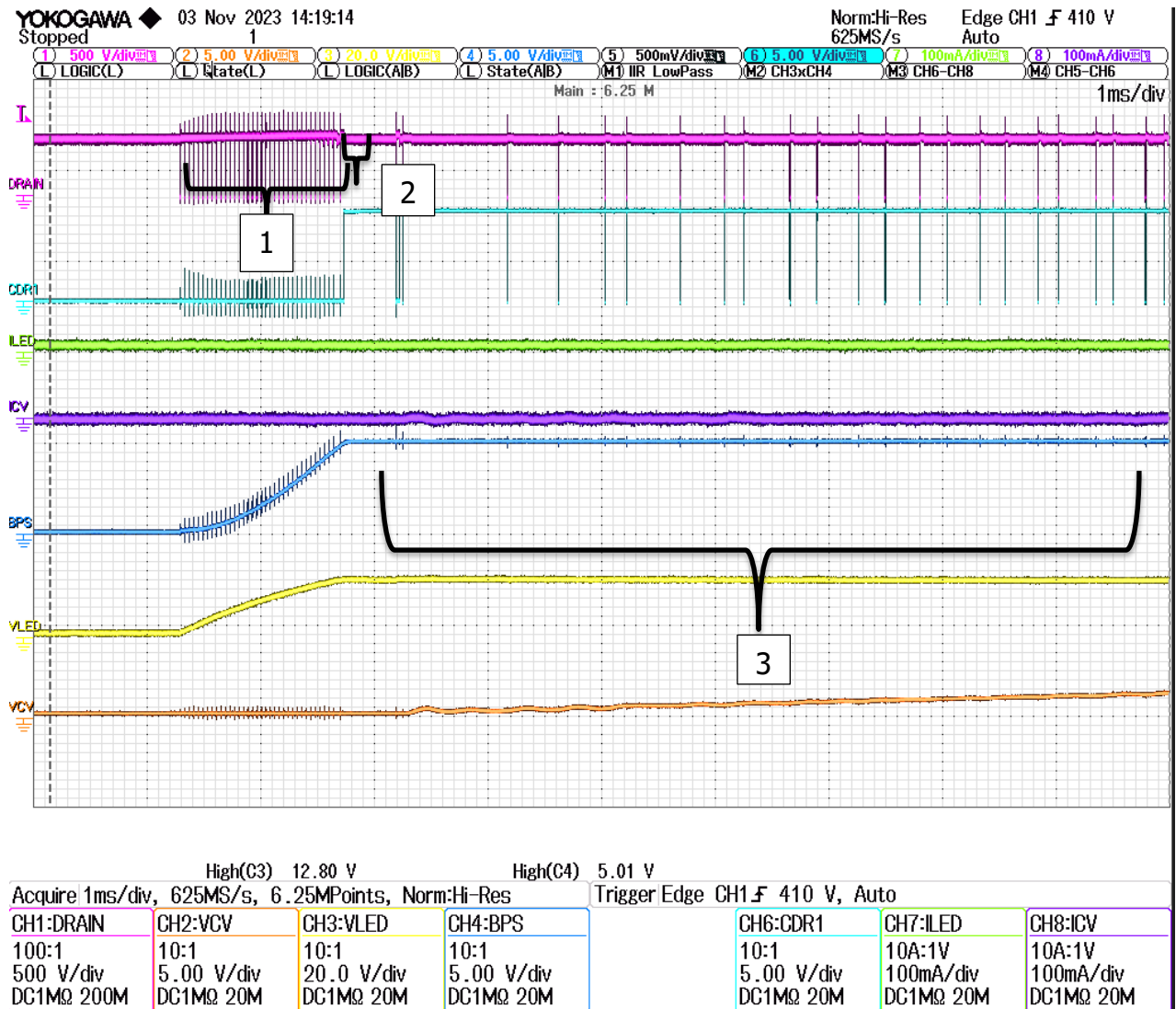


Figure 5 – First 10 ms of Start-Up.

1. Secondary-side controllers are powered-down (asleep). The primary-side controller operates open-loop at a fixed frequency of about 25 kHz. The peak current is set to approximately 75% of its maximum level. If the secondary-side does not wake up and respond, the primary-side will:
 - a. time out and shut down, or
 - b. the primary-side bias voltage will rise high enough to trigger a bias OVP shutdown.
2. The LED output is the only output to rise significantly during interval 1. It provides power to InnoMux2-EP (U1) internal secondary voltage regulator (BPS regulator), which generates the internal supply bus BPS (+5 V). Eventually the internal voltage regulator establishes 5 V at the BPS pin. IC U1 secondary-side controller then wakes up from its power-on-reset, and starts hand-shaking with the primary controller to take over the control of InnoMux2-EP. Hand-shaking pulse and SEL signals to indicate the handshake. Also need to point out what happens to secondary if handshake failed.
3. After handshaking, the fixed 25 kHz switching frequency is ended, and InnoMux2-EP IC (U1) switches according to the feedback and reference voltages on CV1 and LED. The CV1 voltage is linearly raised, while the LED voltage is maintained at the stay-alive voltage ($V_{\text{STAYALIVE}}$, ~8.0 V) to provide input to the internal BPS regulator. While the V_{CV1} is raised to the same reference percentage as the V_{LED} , InnoMux2-EP IC (U1) starts ramping up both two output voltages simultaneously (V_{CV1} and V_{LED}) to their references.
4. CV1 and LED output voltages can be seen to rise simultaneously. At some time during interval 4, the CV1 will reach a sufficient level to power the internal BPS regulator via the VCV1 pin (U1 pin 10). The input of the BPS regulator then switches automatically to the VCV1 pin, thus reducing the power dissipation on the BPS regulator.

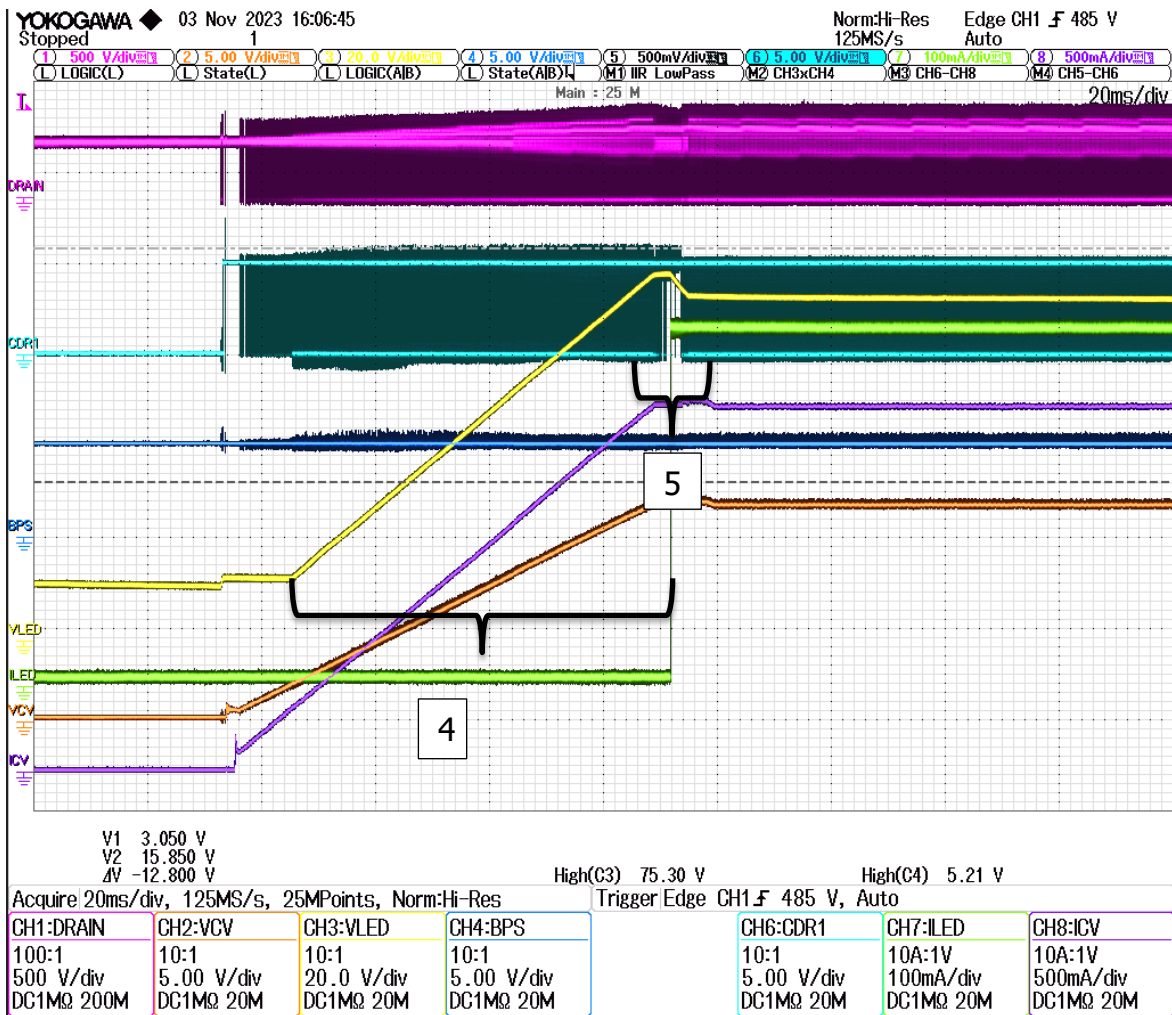


Figure 6 – Complete Start-Up Cycle Over Approximately 180 ms.

- The LED current is enabled. Its level depends on the dimming configuration and the signal on the dimming input(s) (DIM1, DIM2). The LED current is controlled by the internal regulator (U1 pins 1, 3 and 4) and the external LED driver MOSFET (Q3). To reduce the power dissipation on the LED driver MOSFET (Q3), the InnoMux2-EP controller (U1) maintains V_{LED} at a level with some minimum headroom of above the LED stack voltage. This keeps the voltage at the VSENSE pins to a minimum.

5 Connection Diagram

The connection diagram below shows a 2-wire filtered PWM dimming configuration. For other dimming configurations, please refer to the product datasheets.

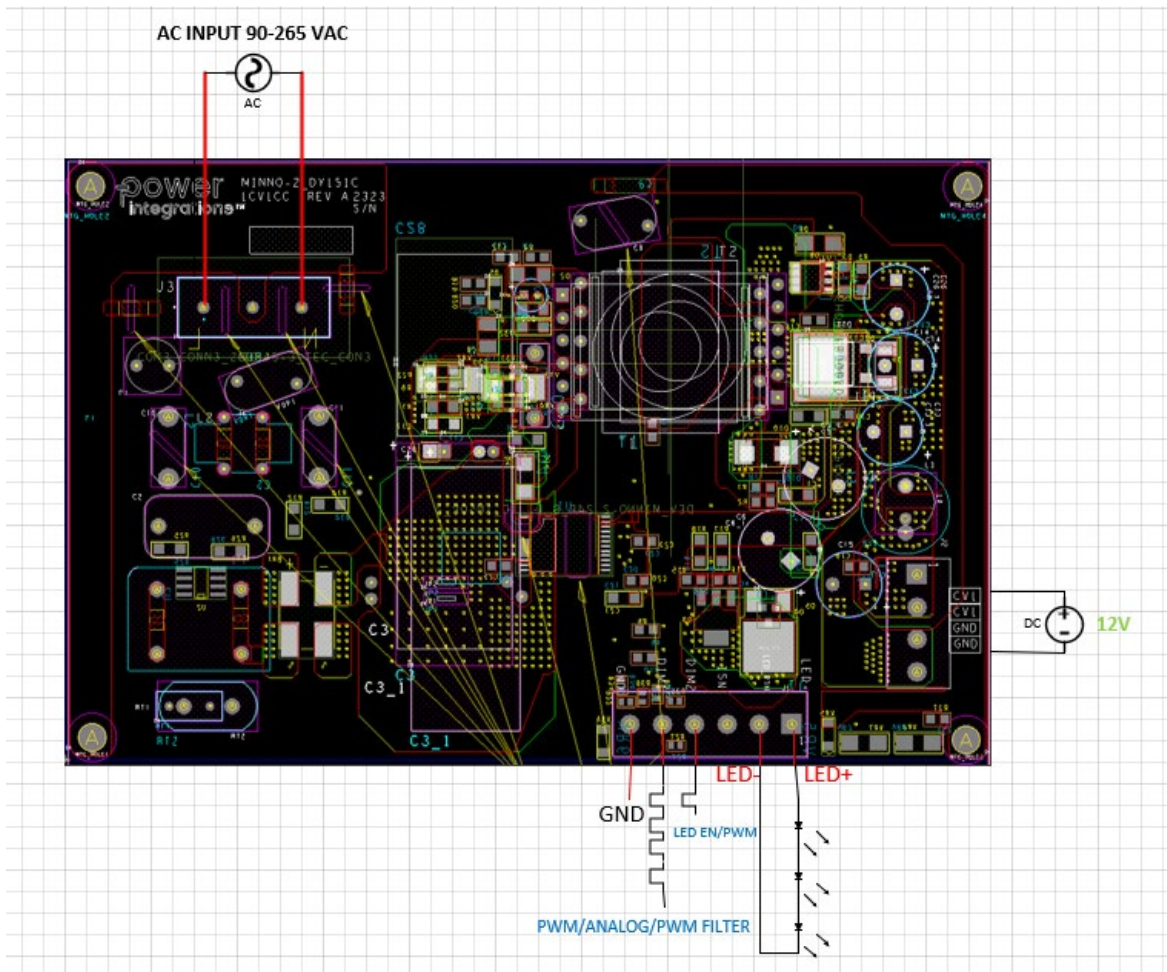


Figure 7 – Connection Diagram

6 PCB Layout

The converter PCB layout is illustrated below in Figures 8, 9, 10. PCB copper thickness is 2 oz (2.8 mils / 70 μm) was used for the PCB.

- (1) FWD pin: FWD signal has large dv/dt , which can be one of the major noise sources on the secondary circuit. Its PCB route should be kept away from the other signals.
- (2) Ground plane: The impedance from InnoMux2-EP controller's ground to ANODE terminal of secondary rectifier diode (D1) should be minimized or separated from the power return ground. Star connection ground can be used here, to prevent the large secondary discharge current from affecting the ground level of the InnoMux2-EP controller.
- (3) Thermal: The primary switch in InnoMux2-EP IC (U1) is cooled through the exposed pad and SOURCE pin of the IC. Care should be taken that their thermal impedance to the cooling copper of the PCB is kept to a minimum.).

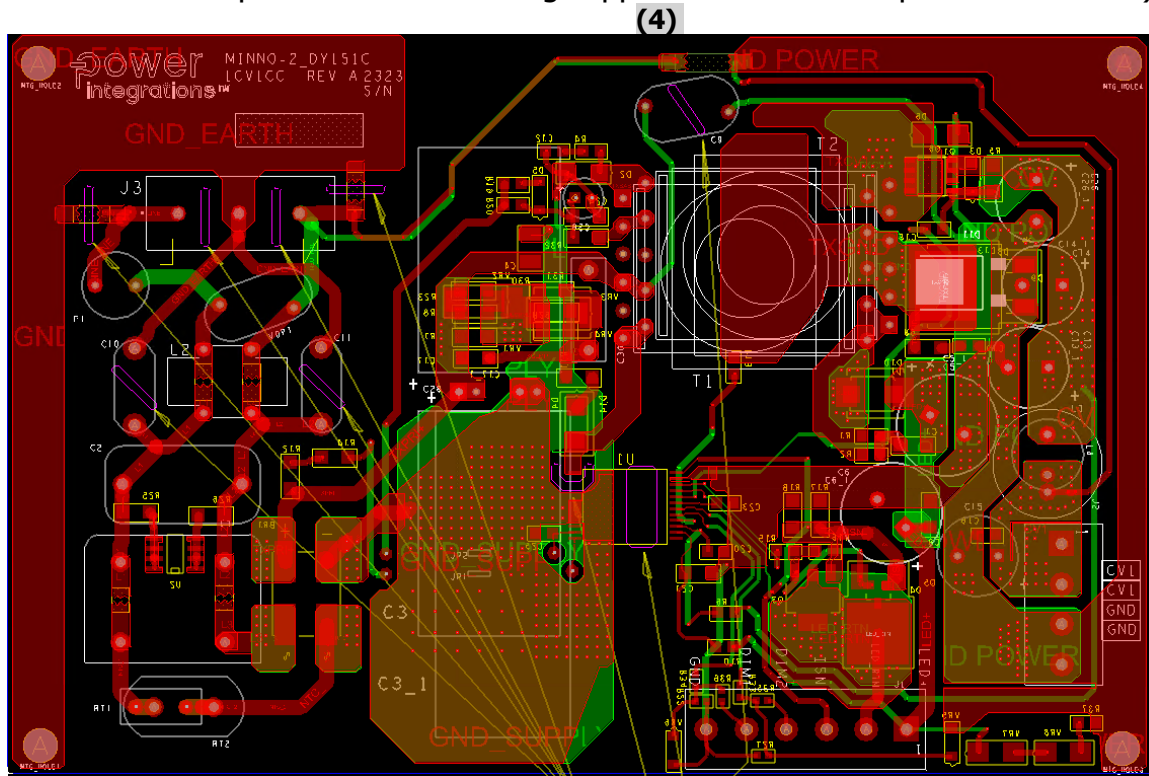


Figure 8 – Printed Circuit Layout.

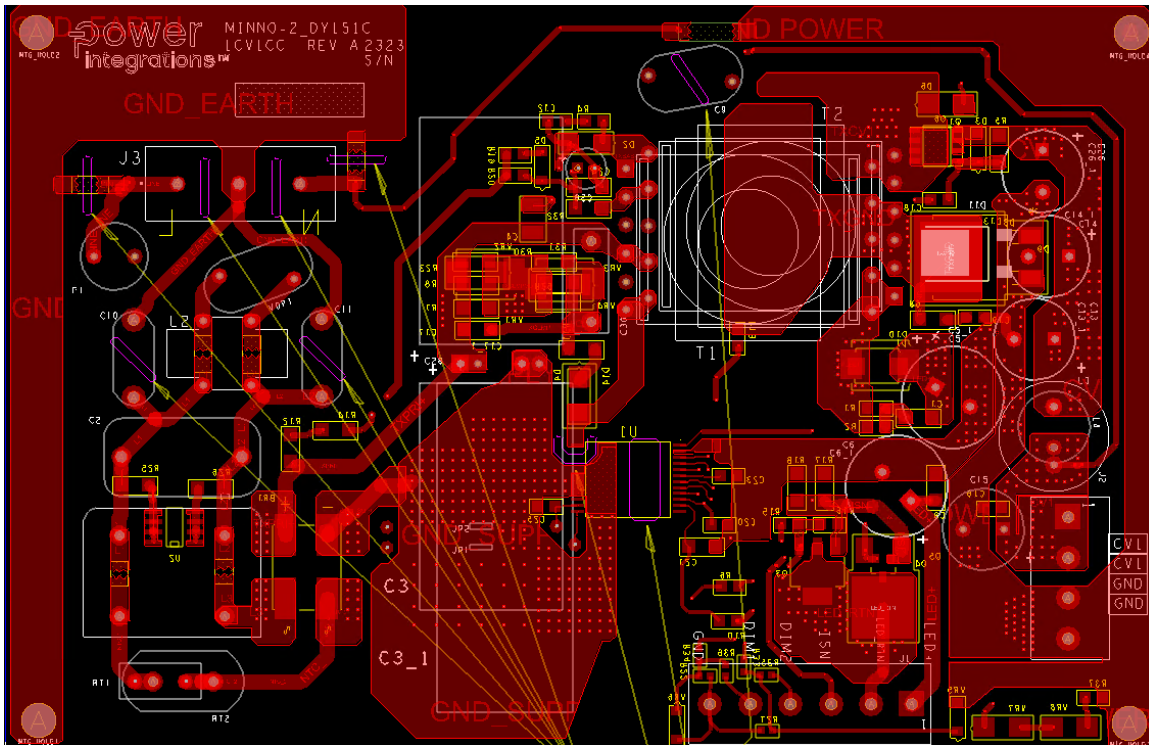


Figure 9 – Printed Circuit Layout, Bottom.

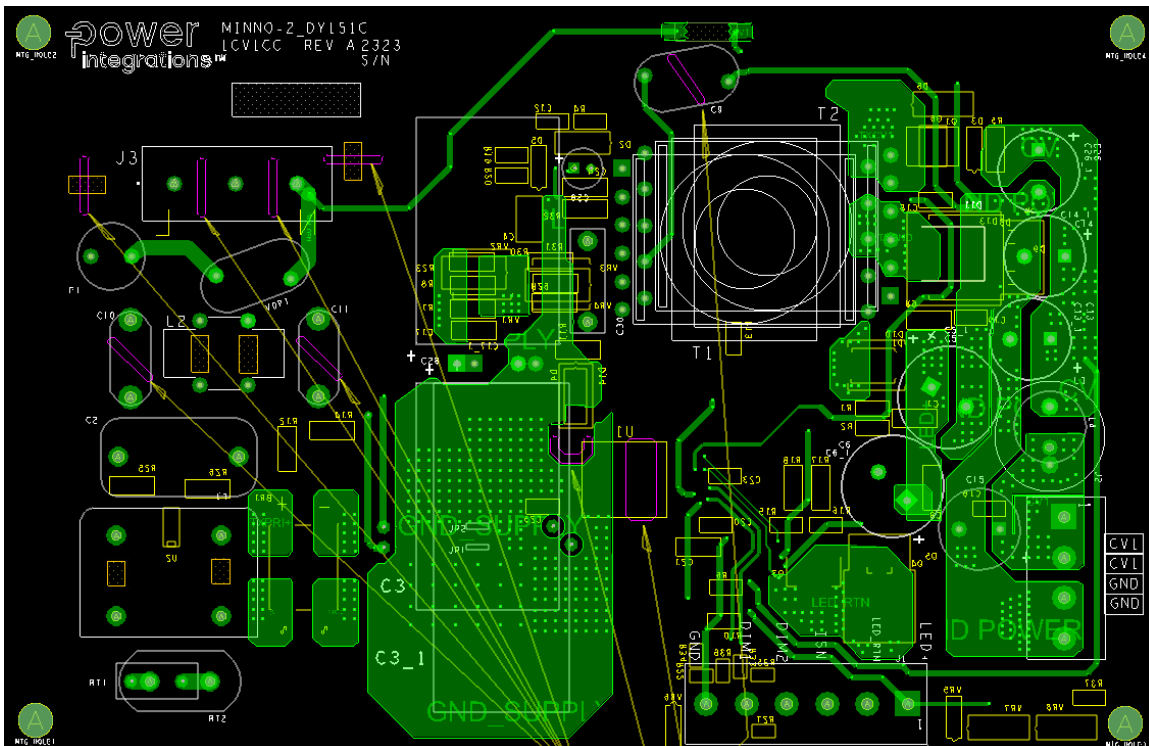


Figure 10 – Printed Circuit Layout, Top.

7 Bill of Materials


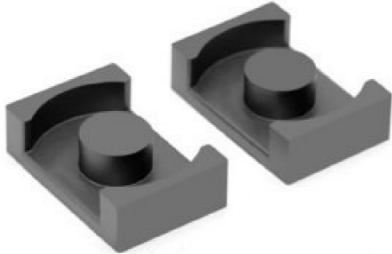
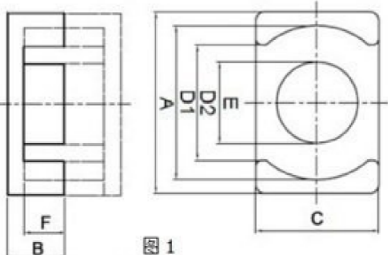
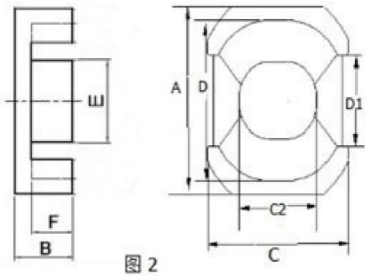
| Item | Qty | Ref Des | Description | Mfg Part Number | Mfg |
|------|-----|-------------|---|---------------------|--------------------|
| 1 | 1 | BR1 | RECT BRIDGE, GP, 800V, 4A, Z4-D | Z4DGP408L-HF | Comchip |
| 2 | 1 | C1 | 56 pF, ±5%, 1000 V (1 kV), Ceramic Capacitor C0G, NPO, 1206 | C1206C560JGDGAC7800 | Kemet |
| 3 | 1 | C2 | 470 nF, 275 VAC, Film, X2 | PX474K31D5 | Carli Electronics |
| 4 | 1 | C3 | 150 µF, 400 V, Electrolytic, (18 x 45) | UPT2G151MHD | Nichicon |
| 5 | 2 | C5 C6 | 120 µF, 100 V, Electrolytic, Gen. Purpose, (12.5 x 20) | UHE2A121MHD6 | Nichicon |
| 6 | 1 | C8 | 100 nF, 200 V, Ceramic, X7R, 1206 | C1206C104K2RACTU | Kemet |
| 7 | 1 | C9 | 2200 PF, ±20%, 500 VAC (Y1), 760 VAC (X1), Ceramic, Y5U | 440LD22-R | Vishay |
| 8 | 1 | C12 | 100 pF, 200 V, Ceramic, COG, 0805 | 08052A101JAT2A | AVX |
| 9 | 3 | C13 C14 C26 | 560 µF, 25 V, ±20%, Al Organic Polymer, Gen. Purpose | A750MS567M1EAAE015 | KEMET |
| 10 | 1 | C15 | 1000 µF, 25 V, Electrolytic, Gen. Purpose, (10 x 20) | EKMG250ELL102MJ20S | Nippon Chemi-Con |
| 11 | 1 | C16 | 1 µF, 25 V, Ceramic, X5R, 0805 | C2012X5R1E105K | TDK |
| 12 | 1 | C17 | 2.2 nF, 630 V, Ceramic, X7R, 1206 | C3216X7R2J222K115AA | TDK |
| 13 | 1 | C18 | 100 nF, 25 V, Ceramic, X7R, 0805 | 08053C104KAT2A | AVX |
| 14 | 1 | C19 | 220pF, ±5%, 500V, Ceramic Capacitor, X7R, 0805 | C0805C221JCRAC7800 | Kemet |
| 15 | 1 | C21 | 0.1 µF, 250V, ±10%, Ceramic, X7R, 1206 | C3216X7R2E104K160AA | TDK |
| 16 | 1 | C23 | 10 µF, ±10%, 16 V, X7R, Ceramic Capacitor, MLCC 0805 | CL21B106KOQNNNE | Samsung |
| 17 | 1 | C25 | 4.7 µF, ±10%, 16 V, Ceramic, X7R, 0805 | GRM21BR71C475KE51L | Murata |
| 18 | 1 | C29 | 22 µF, 50 V, Electrolytic, (5 x 11) | UPW1H220MDD | Nichicon |
| 19 | 1 | D1 | Diode 600 V 3 A Surface Mount SMB | STTH3L06U | ST Micro |
| 20 | 1 | D2 | Diode, 150 V, 1 A, SMT DO-214AC, SMA | STPS1150A | ST Micro |
| 21 | 1 | D3 | Diode, SCHOTKY, 100 V, 0.075A, SOD123 | BAT46W-TP | Micro Commercial |
| 22 | 1 | D4 | Diode, Avalanche, 1000 V, 1.5A, (SMA) | US1M-13-F | Diode Inc. |
| 23 | 1 | D5 | Diode ZENER 30 V 500 mW SOD123 | MMSZ5256B-7-F | Diodes, Inc. |
| 24 | 1 | D6 | Zener Diode, 24 V, 1 W, ±5%, (SMA) | SMAZ24-13-F | Diodes, Inc. |
| 25 | 1 | D8 | Diode 150 V 6 A DPak (2 Leads + Tab) | DSS6-015AS-TRL | IXYS |
| 26 | 1 | F1 | 2 A, 250V, Slow, TR5 | 37212000411 | Wickman |
| 27 | 1 | J1 | 6 Position (1 x 6) header, 5 mm (0.196) pitch, Vertical, Screw | 1715190 | Phoenix Contact |
| 28 | 1 | J2 | 4 Position (1 x 4) header, 5 mm (0.196) pitch, Vertical, Screw | 1715048 | Phoenix Contact |
| 29 | 1 | J3 | 3 Position Wire to Board Terminal Block 0.300" (7.62mm) | 282845-3 | TE Connectivity |
| 30 | 2 | JP1 JP2 | Wire Jumper, Non-insulated, #20 AWG, 0.2 in | 8020 000100 | Belden |
| 31 | 1 | L1 | CMC 10.3 mH 2.0 A 0.15 Ω WIDE IMP | SSR21NVS-M20103 | KEMET |
| 32 | 1 | L2 | 200 µH @ 100 kHz, Common Mode Choke | 30-00512-00 | Power Integrations |
| 33 | 1 | L3 | FIXED IND, 3.3 µH, ±20%, 5.2 A, 16 MΩ, TH | ELC10D3R3E | PANASONIC |
| 34 | | MTG_HOLE S | Mounting Hole M 4 | | |
| 35 | 1 | Q1 | MOSFET, N-Channel, 40 V, 36 A (Tc), 3.5 W (Ta), 7.8W (Tc), 8-SO | SI4154DY-T1-GE3 | Vishay |
| 36 | 1 | Q3 | MOSFET, N-Channel, 100 V, 1.8 A (Ta), 1.8 W (Ta), SOT223 | BSP372NH6327XTSA1 | Infineon |
| 37 | 2 | R1 R2 | RES, 22 Ω, 5%, 1/8 W, Thick Film, 0805 | ERJ-6GEYJ220V | Panasonic |
| 38 | 1 | R4 | RES, 10 Ω, 1%, 1/8 W, Thick Film, 0805 | ERJ-6ENF10R0V | Panasonic |
| 39 | 3 | R5 R12 R14 | RES, 2.00 MΩ, 1%, 1/4 W, Thick Film, 1206 | ERJ-8ENF2004V | Panasonic |
| 40 | 1 | R6 | RES, 3.3 Ω, 5%, 1/8 W, Thick Film, 0805 | ERJ-6GEYJ3R3V | Panasonic |
| 41 | 1 | R9 | RES, 22.1 Ω, 1%, 1/4 W, Thick Film, 1206 | ERJ-8ENF22R1V | Panasonic |
| 42 | 1 | R10 | RES, 0 Ω, 5%, 1/8 W, Thick Film, 0805 | RMCF0805ZT0R00 | Stackpole |
| 43 | 2 | R11 R32 | RES, 4.7 Ω, 1%, 1/4 W, Thick Film, 1206 | ERJ-8RQF4R7V | Panasonic |

| | | | | | |
|----|---|--------------------|--|------------------|--------------------|
| 44 | 1 | R13 | RES, 47 Ω , 5%, 1/8 W, Thick Film, 0805 | ERJ-6GEYJ470V | Panasonic |
| 45 | 1 | R15 | RES, 18 Ω , 5%, 1/8 W, Thick Film, 0805 | ERJ-6GEYJ180V | Panasonic |
| 46 | 1 | R16 | RES, 100 k Ω , 5%, 1/8 W, Thick Film, 0805 | ERJ-6GEYJ104V | Panasonic |
| 47 | 2 | R17 R18 | RES, 0.5 Ω , 1%, 1/2 W, Thick Film, -55°C ~ 155°C, 1206 | RL1206FR-7W0R5L | YAGEO |
| 48 | 1 | R19 | RES, 47 Ω , 5%, 1/8 W, Thick Film, 0805 | ERJ-6GEYJ470V | Panasonic |
| 49 | 1 | R20 | RES, 5.1 k Ω , 5%, 1/8 W, Thick Film, 0805 | ERJ-6GEYJ512V | Panasonic |
| 50 | 2 | R22 R27 | RES, 100 k Ω \pm 1%, 1/10 W Chip Resistor 0603 | RC0603FR-07100KL | Yageo |
| 51 | 3 | R29 R30 R31 | RES, 7.5 k Ω , 1%, 1/4 W, Thick Film, 1206 | ERJ-8ENF7501V | Panasonic |
| 52 | 4 | R33 R34 R35 R36 | RES, 100 Ω \pm 5%, 1/10 W Chip Resistor 0603 | RC0603JR-07100RL | Yageo |
| 53 | 1 | RT2 | NTC Thermistor, 1.3 Ω , 7 A | MF72-001.3D13 | Cantherm |
| 54 | 1 | T1 | Bobbin, EQ27/14, 11 pins, 6pri, 5sec | YT-2701 | www.dgytdz.com |
| 55 | 1 | U1 | InnoMux2-EP controller IC | IMX2268C | Power Integrations |
| 56 | 1 | VDR1 | 275 VAC, 45 J, 10 mm, RADIAL | V275LA10P | Littelfuse |
| 57 | 1 | VR2 | 137 V Clamp, 4.4A Ipp, Unidirectional TVS Diode (SMBJ) | SMBJ85A | Littelfuse |
| 58 | 2 | VR5 VR6 | Diode ZENER 5.6 V 500 mW SOD123 | MMSZ5232B-7-F | Diodes, Inc. |

8 Transformer (T1) and CMC (L2) Specification

8.1 Core Information

Core EQ27/14, Guangzhou Tongyang Electronics Part No. 066260270718044

| | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
|--|---|-----------------|-----------------|----------|---------|----------------------|---|--------------|---|-------------|---|-------------|----|---|---|---|----|----------|----|----------|---|--------------|---|-------------|-----|-------------|-----------|---|------------------------------|--|---|------|---------------------------------------|-------|---|-------|--|------|------------------------|--|---------------------------------------|------|--|------|------|------|--|-------------------|------|--|------|--|------|--|
|  <p>广州市通洋电子有限公司 Guangzhou Tongyang Electronics Co.,Ltd</p> <p>地址: 中国广东省广州市白云区松北工业区社前路56号1栋 Add: 1st Building, No. 56 Sheqian Road, Songbe Industrial Zone, Baiyun District, Guangzhou, China Tel: +86 020-81786686 Web: http://www.gztydz.com E-mail: ywb@gztydz.com</p> | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
|    | <table border="1"> <tr> <td>代 码 Code</td> <td>066260270718044</td> </tr> <tr> <td>型 号 Type</td> <td>EQ27/14</td> </tr> <tr> <td rowspan="9">尺寸 (mm) Dimension</td> <td>A</td> <td>26.70 ± 0.40</td> </tr> <tr> <td>B</td> <td>6.85 ± 0.20</td> </tr> <tr> <td>C</td> <td>18.1 ± 0.30</td> </tr> <tr> <td>C2</td> <td>*</td> </tr> <tr> <td>D</td> <td>*</td> </tr> <tr> <td>D1</td> <td>23.10min</td> </tr> <tr> <td>D2</td> <td>18.90min</td> </tr> <tr> <td>E</td> <td>11.10 ± 0.20</td> </tr> <tr> <td>F</td> <td>4.45 ± 0.20</td> </tr> <tr> <td>B-F</td> <td>2.40 ± 0.20</td> </tr> <tr> <td>图 drawing</td> <td>1</td> </tr> <tr> <td>可调尺寸 adjustable dimension</td> <td></td> </tr> <tr> <td>磁芯常数C1 (mm⁻¹) Core Factor</td> <td>0.45</td> </tr> <tr> <td>有效磁路长度 Le (mm) Effective length Le</td> <td>39.16</td> </tr> <tr> <td>有效截面积 Ae (mm²) Effective Area</td> <td>85.88</td> </tr> <tr> <td>有效体积 Ve (mm³) Effective Volume</td> <td>3363</td> </tr> <tr> <td>重量 W (g/set) Weight</td> <td></td> </tr> <tr> <td rowspan="3">电感系数 AL (nH/N²) ± 25%</td> <td>TY40</td> <td></td> </tr> <tr> <td>TY44</td> <td>5000</td> </tr> <tr> <td>TY95</td> <td></td> </tr> <tr> <td rowspan="3">功率损耗 Core loss</td> <td>TY40</td> <td></td> </tr> <tr> <td>TY44</td> <td></td> </tr> <tr> <td>TY95</td> <td></td> </tr> </table> | 代 码 Code | 066260270718044 | 型 号 Type | EQ27/14 | 尺寸 (mm) Dimension | A | 26.70 ± 0.40 | B | 6.85 ± 0.20 | C | 18.1 ± 0.30 | C2 | * | D | * | D1 | 23.10min | D2 | 18.90min | E | 11.10 ± 0.20 | F | 4.45 ± 0.20 | B-F | 2.40 ± 0.20 | 图 drawing | 1 | 可调尺寸 adjustable dimension | | 磁芯常数C1 (mm ⁻¹) Core Factor | 0.45 | 有效磁路长度 Le (mm) Effective length Le | 39.16 | 有效截面积 Ae (mm ²) Effective Area | 85.88 | 有效体积 Ve (mm ³) Effective Volume | 3363 | 重量 W (g/set) Weight | | 电感系数 AL (nH/N ²) ± 25% | TY40 | | TY44 | 5000 | TY95 | | 功率损耗 Core loss | TY40 | | TY44 | | TY95 | |
| | 代 码 Code | 066260270718044 | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| | 型 号 Type | EQ27/14 | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| | 尺寸 (mm) Dimension | A | 26.70 ± 0.40 | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| | | B | 6.85 ± 0.20 | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| | | C | 18.1 ± 0.30 | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| | | C2 | * | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| | | D | * | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| | | D1 | 23.10min | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| | | D2 | 18.90min | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| | | E | 11.10 ± 0.20 | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| | | F | 4.45 ± 0.20 | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| | B-F | 2.40 ± 0.20 | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| | 图 drawing | 1 | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| 可调尺寸 adjustable dimension | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| 磁芯常数C1 (mm ⁻¹) Core Factor | 0.45 | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| 有效磁路长度 Le (mm) Effective length Le | 39.16 | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| 有效截面积 Ae (mm ²) Effective Area | 85.88 | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| 有效体积 Ve (mm ³) Effective Volume | 3363 | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| 重量 W (g/set) Weight | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| 电感系数 AL (nH/N ²) ± 25% | TY40 | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| | TY44 | 5000 | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| | TY95 | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| 功率损耗 Core loss | TY40 | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| | TY44 | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| | TY95 | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |

磁芯可按客户尺寸开模，可以开气隙。

We can open the mould or grind air gap for the ferrite core as per customer's requirement and size.

Figure 11 – EQ27/14 Core.

8.2 Bobbin Information

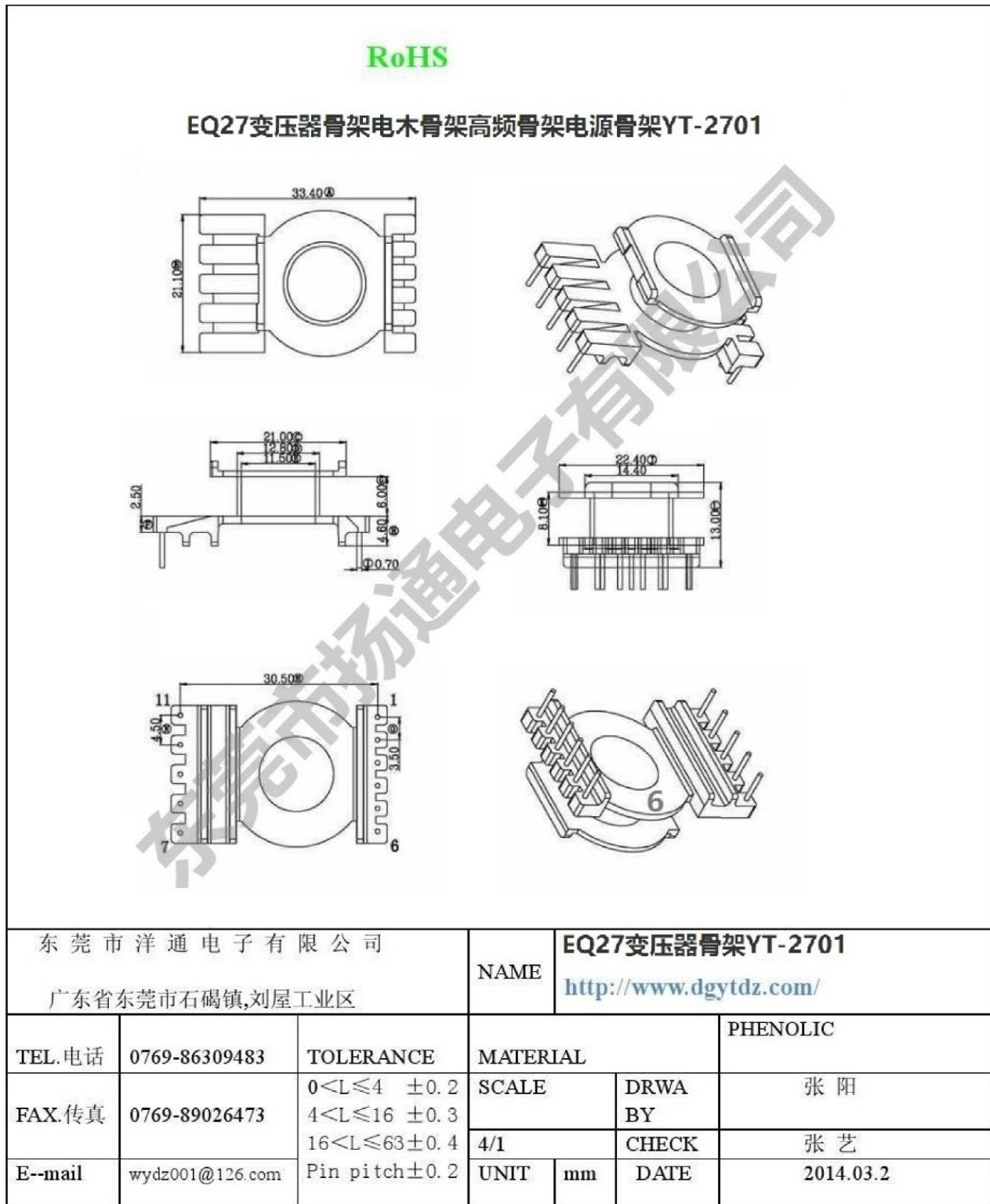


Figure 12 – Guangzhou Tongyang Electronics - 11 Pin Bobbin – YT-2701.

8.3 Electrical Diagram (T1)

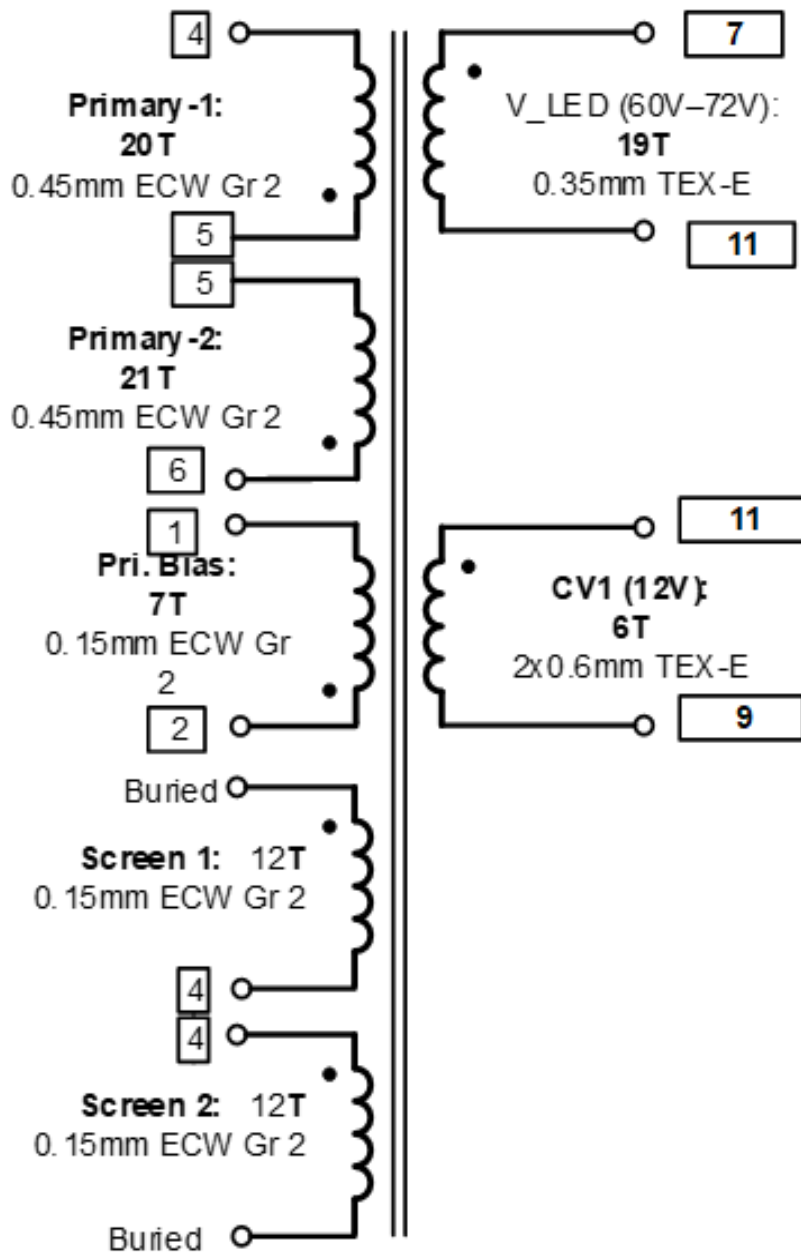


Figure 13 – Transformer Electrical Diagram.

8.4 Winding Stack Diagram

Note:
 Unless stated otherwise **bobbin**
tums anti-clock-wise looked from
 the pins' end.

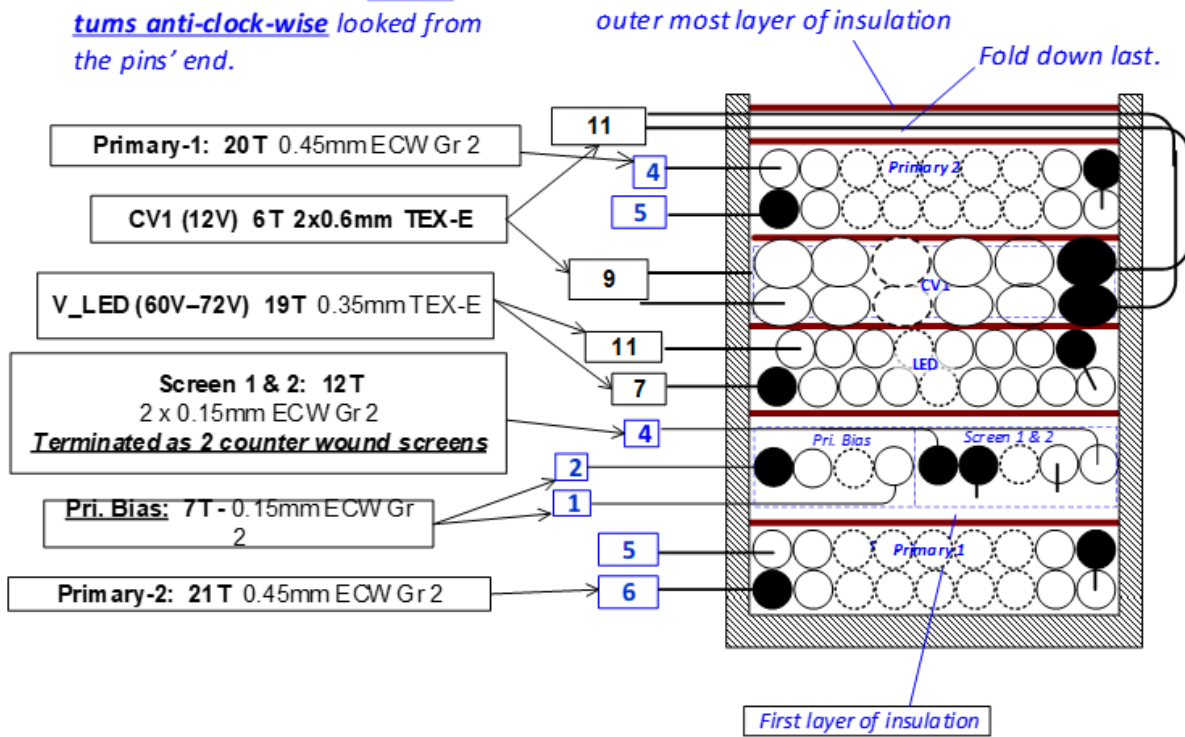


Figure 14 – Transformer Build Diagram.

8.5 Transformer Electrical Specification

| Parameter | Condition | Spec. |
|-----------------------------------|--|------------------|
| Electrical Strength | 1 second, 60 Hz from pins 1-6 to 7-13. | 3000 VAC |
| Nominal Primary Inductance | Measured at 1 V _{PK-PK} , 100 kHz switching frequency, between pin 5 and 6, with all other windings open. | 377 μH ±3% |
| Resonant Frequency | Between pin 5 and 6, other windings open. | 1,100 kHz (Min.) |
| Primary Leakage Inductance | Between pin 5 and 6, with all secondary 7, 9, 11 and 13 shorted. | 10 μH (Max.) |

8.7 Materials List

| Item | Description |
|------|--|
| [1] | Core: Ferroxcube Part No. EQ27/14 TY44. |
| [2] | Bobbin: EQ27 YT-2701 |
| [3] | Magnet Wire: 0.45 mm ECW Gr 2. |
| [4] | Magnet Wire: 0.15 mm ECW Gr 2. |
| [5] | Magnet Wire: 0.35 mm, Triple Insulated Wire. |
| [6] | Magnet Wire: 0.6 mm, Triple Insulated Wire. |
| [8] | Barrier Tape: Polyester Film, 2.5±0.5 mil Thickness, 6 mm Wide. |
| [9] | Varnish: MR8008B - Varnish, Insulating, Polyurethane, Transparent/Amber EMR8008B250ML Or BC-359 |

8.8 Transformer Construction

| | |
|------------------------------------|--|
| Layer 1&2 Primary-1 | Start at pin 6, wind 21 turns of 1 wire Item [3] in 2 layers with tight tension. Terminate at pin 5. |
| Insulation | Place 1 layers of tape Item [8] for insulation. |
| Layer 3 Primary Bias | Start at pin 2, wind 7 turns of wire Item [4] with tight tension and terminate at pin 1. |
| Layer 3 Screen: 1&2 | Start at pin 4 for screen 1 and start from a dummy pin for screen2. #wind 12T of wire Item [4] from end of bias wind with tight tension. Cut screen1 winding and bury , cut screen2 winding at the end and connect it to pin4.Take off the winding from dummy pin and bury inside the layer. Cover the buried windings with 1 layer of Item [8]. |
| Insulation | Place 1 layer of tape Item [8] for insulation. Cut end of screen wind to leave the end buried under the tape. |
| Layer 4&5 LED | Start at pin 7, wind 19 turns of wire Item [5] in 2 layers with tight tension and terminate at pin 11. |
| Insulation | Place 1 layer of tape Item [8] for insulation. |
| Layer 6 CV | Start at pin 9, wind 6 turns of Item [6] in 1 layer with tight tension. Cut to leave about 5cm and tape to mandrel bobbin |
| Layer 7 CV | Start at pin 9, wind 6 turns of Item [6] in 1 layer with tight tension. Cut to leave about 5cm and tape to mandrel bobbin |
| Layer 8&9 Primary-2 | Start at pin 5, wind 20 turns of 1 wire Item [3] in 2 layers with tight tension. Terminate at pin 4. |
| Insulation | Place 2 layers of tape Item [8] for insulation. |
| Finish Assembly | Gap core halves to 377 μ H \pm 3% inductance. Insert cores and tape tightly together item [8]. Label "XXX.X μ H" (XXX.X = measured primary inductance value in μ H) Varnish – Item [11]. |

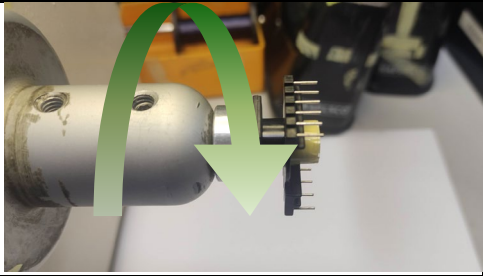
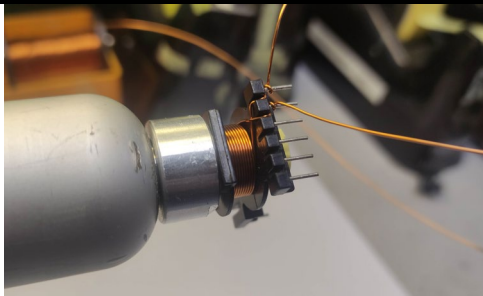
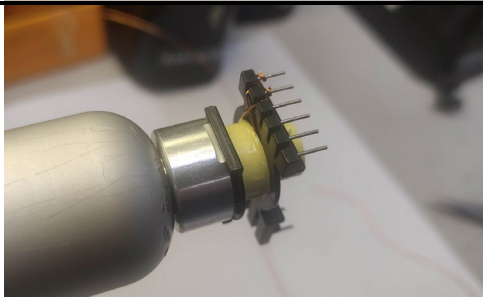
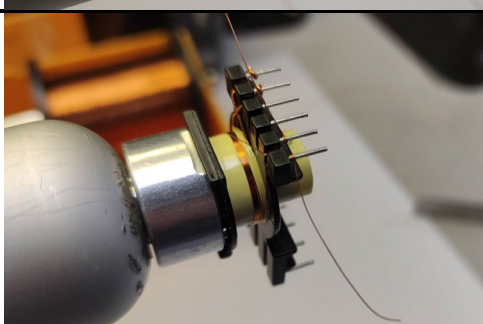
8.9 Transformer Test

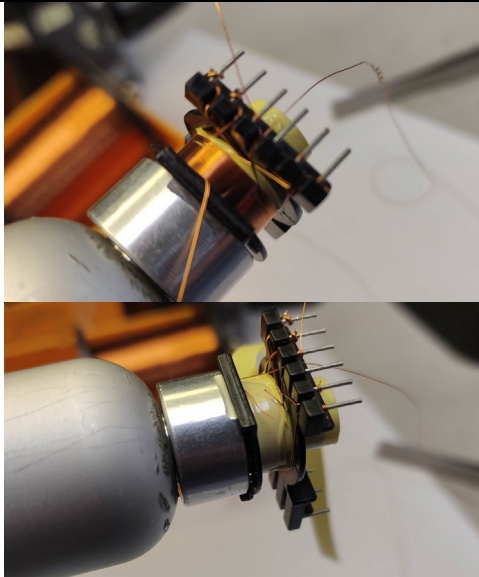
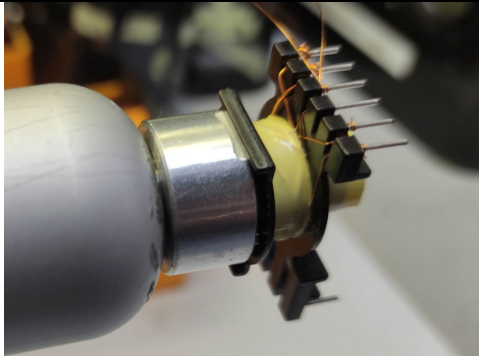
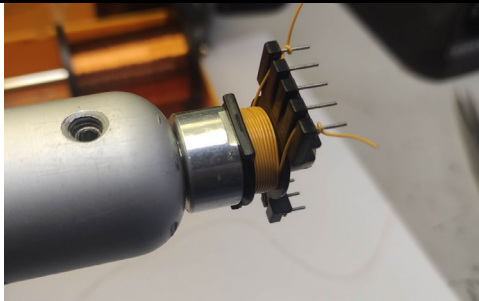
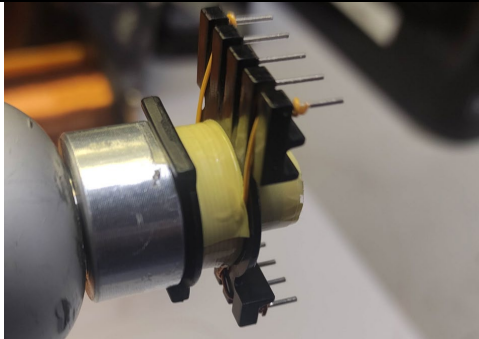
The winding measured inductance of the individual windings as well as the primary leakage inductance of the transformer are shown in the table below:

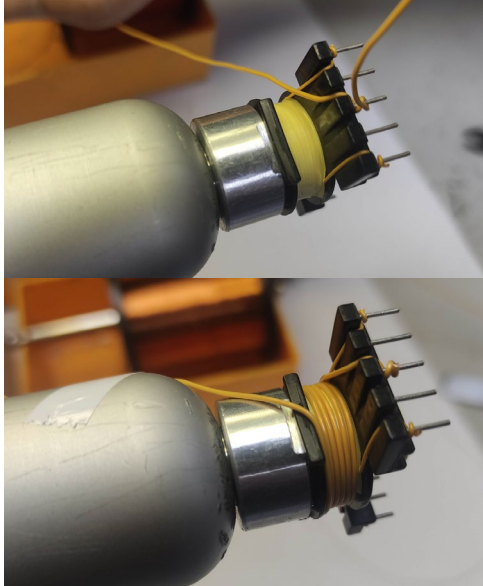
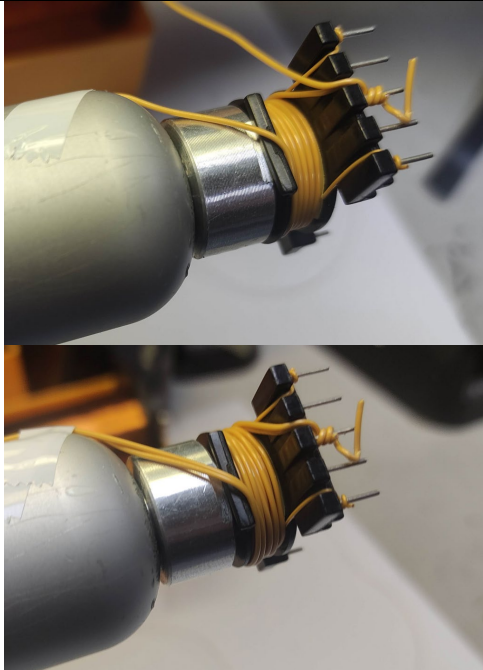
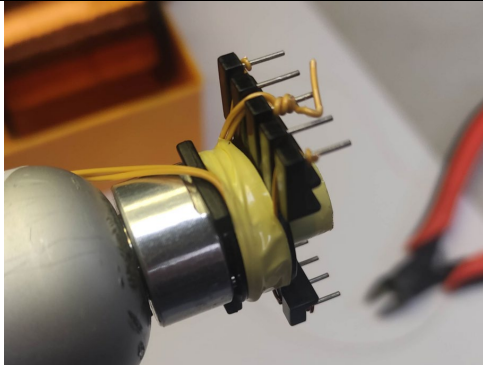
| | | Between Pins | Pins Shorted |
|------------------------------|------|---------------------|---------------------|
| L _{pri} [μ H] | 376 | 4 - 6 | |
| L _{CV} [μ H] | 8.6 | 11 - 9 | |
| L _{LED} [μ H] | 82 | 11 - 7 | |
| L _{1aux} [μ H] | 11.6 | 1 - 2 | |
| L _{lk1} [μ H] | 9.4 | 5 - 6 | 7 and 11 |
| L _{lk2} [μ H] | 12.2 | 5 - 6 | 9 and 11 |

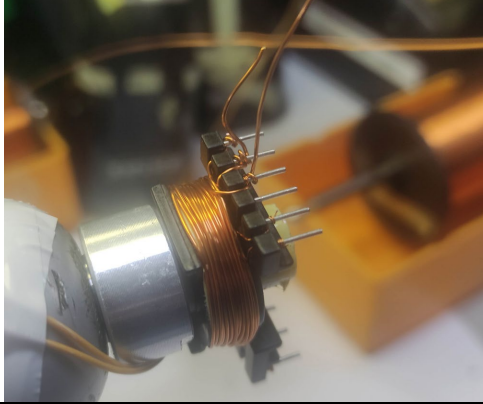
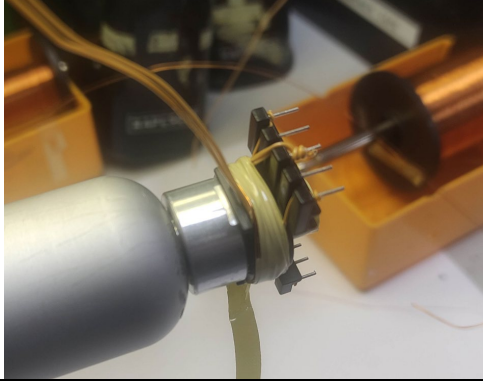
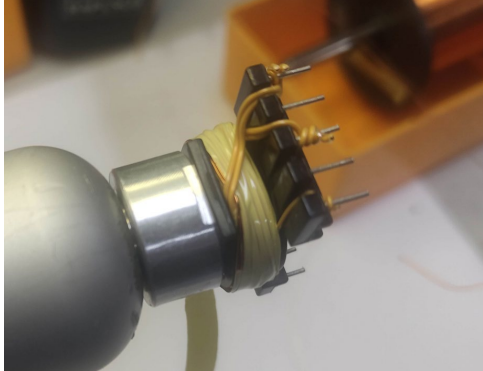
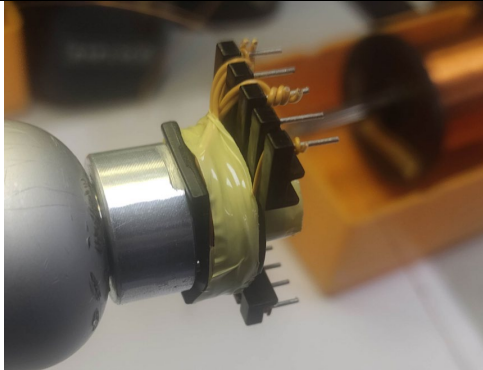
Table 1– Winding Inductance. All Measurements are Done in 100 kHz at 1 V_{RMS}.

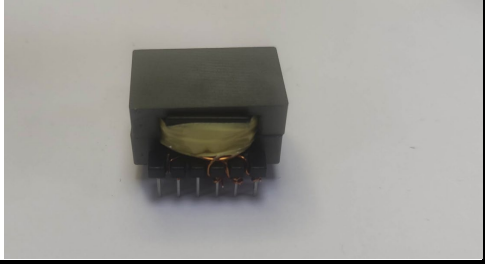
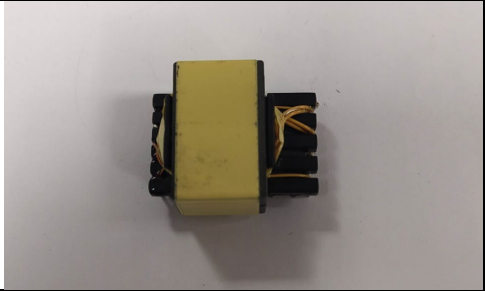
8.10 Winding Illustration

| | | |
|--|---|---|
| |  | <p>Place the bobbin on the mandrel with the pin side to the right. Winding direction is in the clockwise direction i.e. top side moving away from operator.</p> |
| <p>Wind 1 Primary 1 ½ Primary</p> |  | <p>Start at pin 6, wind 21 turns of 1 wire Item [3] in 2 layers with tight tension. Terminate at pin 5.</p> |
| <p>Insulation layer</p> |  | <p>Place 1 layers of tape Item [8] for insulation.</p> |
| <p>Wind 2 Primary Bias</p> |  | <p>Start at pin 2, wind 7 turns of wire Item [4] with tight tension and terminate at pin 1.</p> |

| | | |
|---|---|---|
| <p>Wind 3 Screen 1&2</p> |  | <p>Start at pin 4 for screen 1 and start from a dummy pin for screen2. #wind 12T of wire Item [4] from end of bias wind with tight tension. Cut screen1 winding and bury, cut screen2 winding at the end and connect it to pin4. Take off the winding from dummy pin and bury inside the layer. Cover the buried windings with 1 layer of Item [8].</p> |
| <p>Insulation layer</p> |  | <p>Place 1 layer of tape Item [8] for insulation. Cut end of screen wind to leave the end buried under the tape.</p> |
| <p>Wind 4 LED</p> |  | <p>Start at pin 7, wind 19 turns of wire Item [5] in 2 layers with tight tension and terminate at pin 11.</p> |
| <p>Insulation</p> |  | <p>Place 1 layer of tape Item [8] for insulation.</p> |

| | | |
|-----------------------------|---|---|
| <p>Wind 5 CV</p> |  | <p>Start at pin 9, wind 6 turns of Item [6] in 1 layer with tight tension in anticlockwise direction.</p> <p>Cut to leave about 5cm and tape to mandrel bobbin.</p> |
| <p>Wind 5 CV</p> |  | <p>Start at pin 9. Wind 6 turns of Item[6] in 1 layer with tight tension in anticlockwise direction.</p> <p>Cut to leave 5 cm of free wire and secure it to the mandrel chuck with tape</p> |
| <p>Insulation</p> |  | <p>Place 1 layer of tape Item [8] for insulation.</p> |

| | | |
|--|---|---|
| <p>Wind 6 Primary 2 ½ Primary winding</p> |  | <p>Start at pin 5, wind 20 turns of 1 wire Item [3] in 2 layers with tight tension. Terminate at pin 4.</p> |
| <p>Insulation</p> |  | <p>Place 1 layer of tape Item [8] for insulation.</p> |
| <p>Terminate CV winding</p> |  | <p>Bend wire end down and take through the slot between pins 9 & 10 and terminate to pin 11.</p> |
| <p>Insulation</p> |  | <p>Place 1 layer of tape Item [8] for insulation.</p> |

| | | |
|---------------------------|---|---|
| <p>Insert core</p> |  | <p>Gap core to achieve 377 μH. Tape core tightly together.</p> |
| |  | <p>Cover with 1 layer of tape item [8]. Varnish dip and cure item [11]</p> |

8.11 CMC Specification (L1)

8.11.1 Electrical Diagram

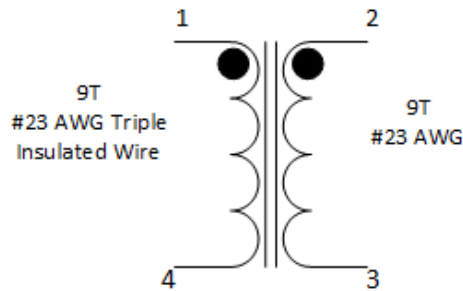


Figure 15 – Inductor Electrical Diagram.

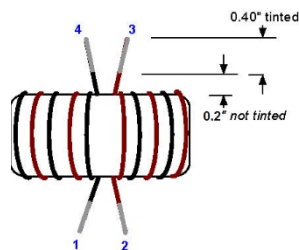
8.11.2 Electrical Specifications

| | | |
|-----------------------------------|--|-----------------------|
| Inductance | Pins 1-4 measured at 100 kHz, 0.4 RMS. | 200 μ H \pm 10% |
| Primary Leakage Inductance | Pins 1-4, with 2-3 shorted. | 1 μ H |

8.11.3 List of Materials

| Item | Description |
|------|---|
| [1] | Core: GL50 T 12X6X4-C, PI Part # 32-00315-00 BIPOLAR ELECTRONIC CO., LTD. |
| [2] | Magnet Wire: #23 AWG. |
| [3] | Triple Insulated wire #23 AWG. |

8.11.4 Illustration



Note: Add Teflon sleeving for terminations.

8.11.5 CMC Winding Illustration

| | |
|--|---|
| | <p>Start as pin 1 for Item [3] and pin 2 for Item [2] .</p> <p>Wind together 9 turns on core Item [1].</p> <p>Mark end of Item [3] as pin 4 and end of Item [2] as pin 3.</p> |
|--|---|

10 Performance

10.1 The Current Limit Characteristic

The Current Limit Characteristic curve is verified in specific load points by calculating primary peak current at measured switching frequency points.

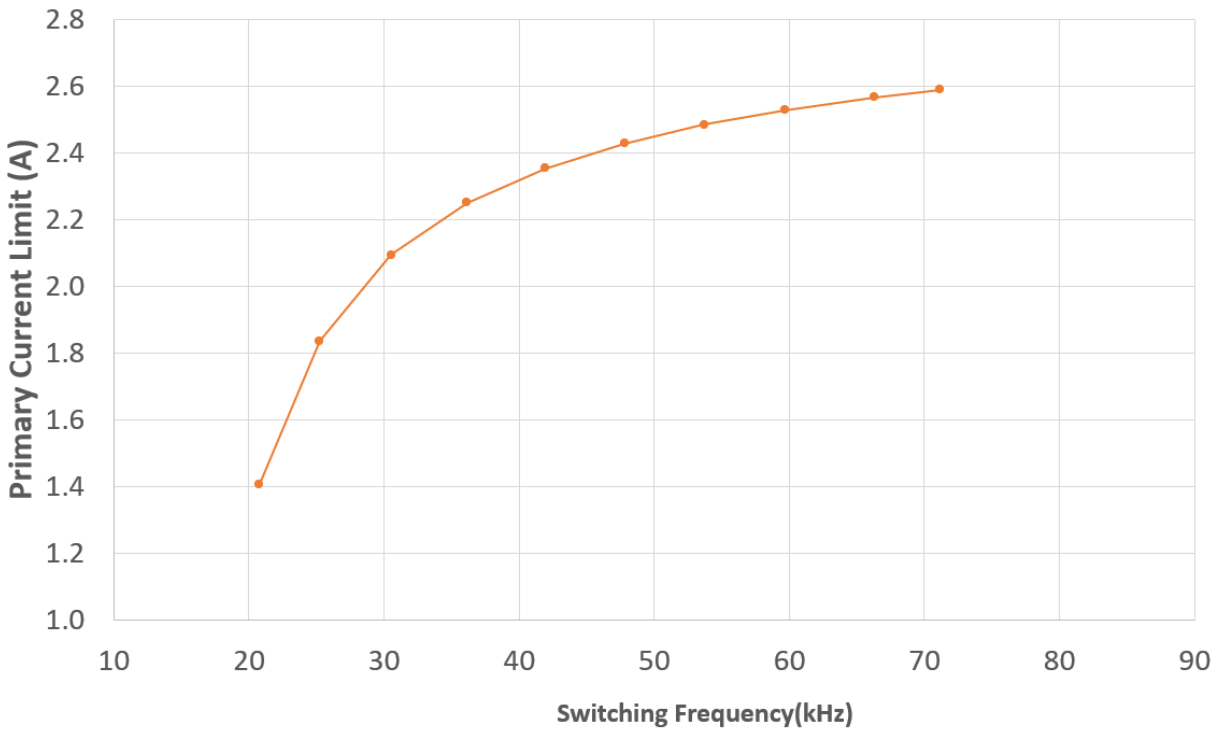


Figure 16 – Primary Current(A) vs. SW frequency at Room Temperature.

10.2 Full Load Efficiency vs. Line

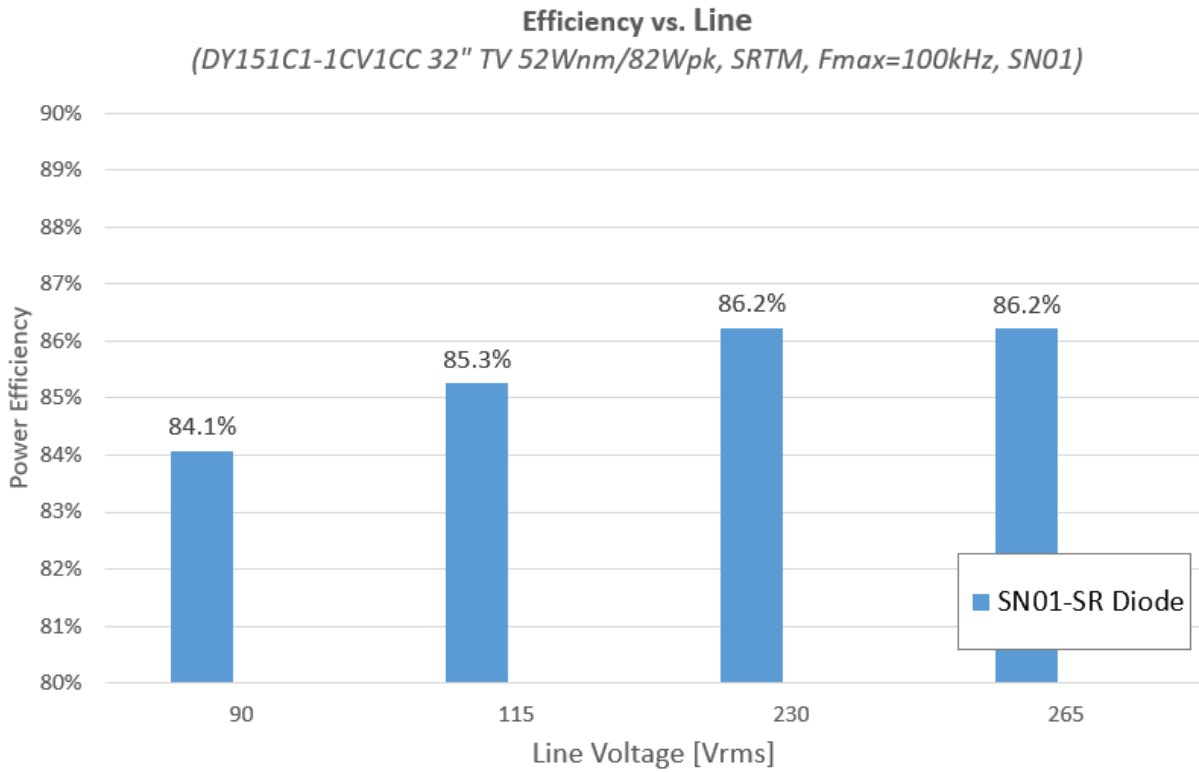


Figure 16 – Full Power Efficiency vs. Line Voltage at Room Temperature.

8.12 Efficiency vs. Load

The efficiency vs. load measurements is shown below. These were obtained for all combinations of:

- All (nominal) line voltages (90 V, 115 V, 230 V, 265 V);
- LED full current of 380 mA with 11 steps for each line voltage
- CV1 full current of 2 A with 11 steps for each line voltage

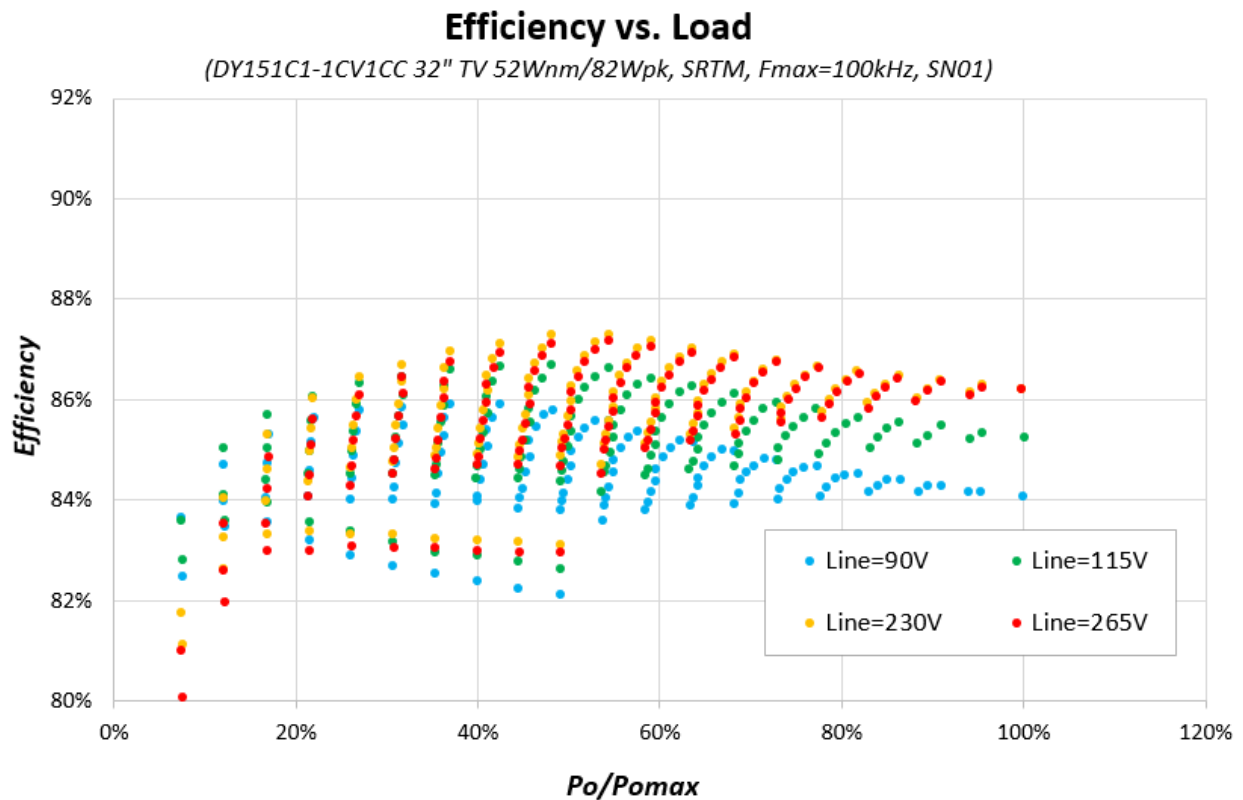


Figure 17 – Efficiency vs. Load for all line and V_{LED} variations, Room Temperature.

8.13 Output Load Regulation

The output-voltage regulation error was measured for both CV output. The current at the CV output was increased from 1% to 100% of its rating in 10 steps. The current at the LED output was increased from 5% to 100% of its rating in 10 steps.

- all (nominal) line voltages

The load regulation error for the CV output is shown on Figure 18.

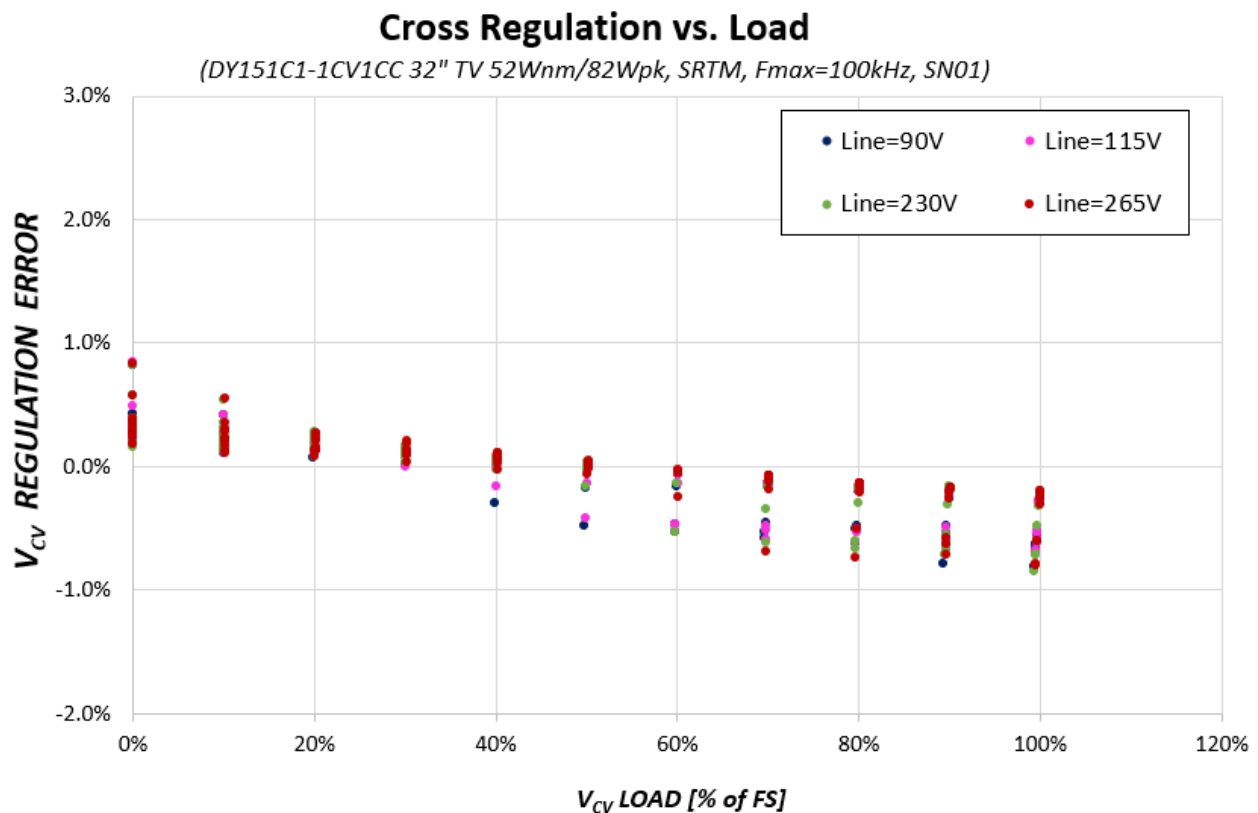


Figure 18 – V_{CV} Output Error vs. Percentage Load, at Room Temperature.

The load regulation error for the LED output is shown on Figure 19.

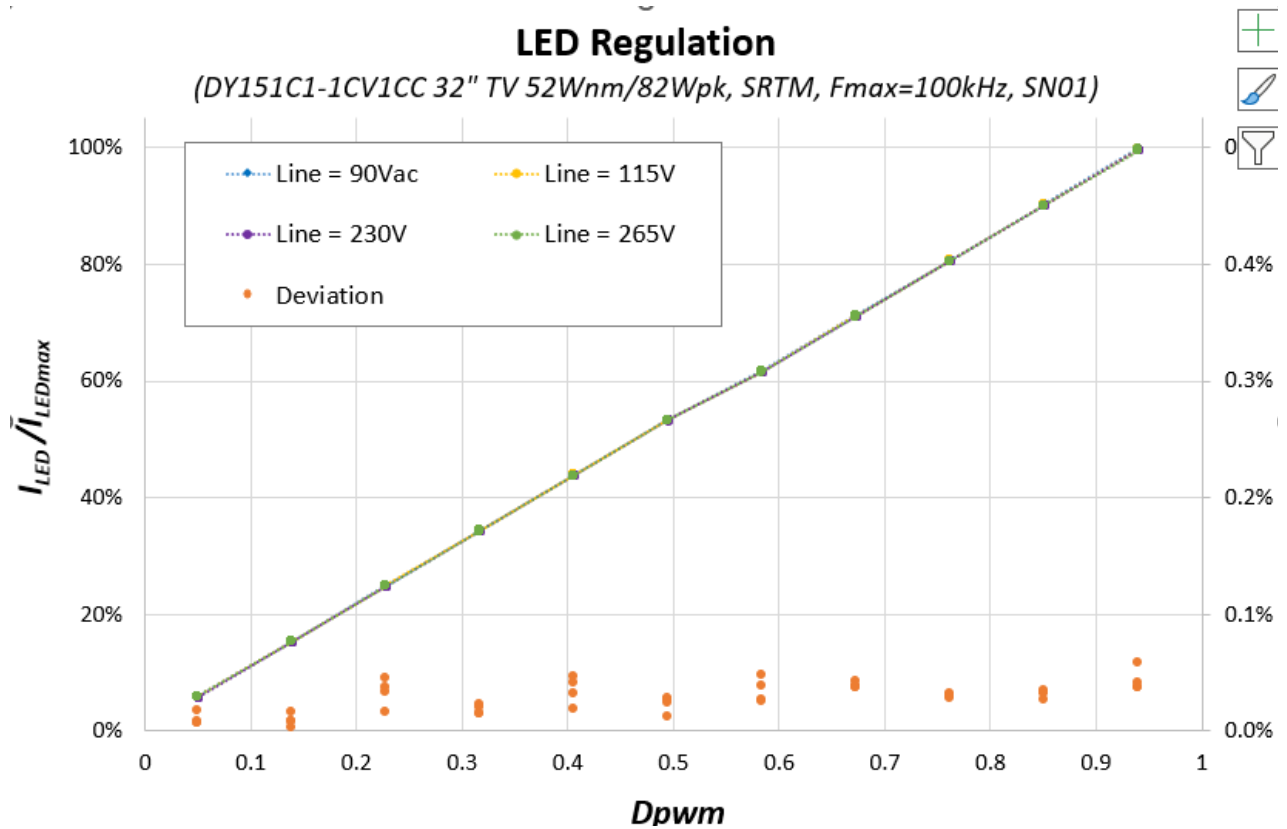


Figure 19 – I_{LED} Output Error vs. PWM Duty, at Room Temperature.

8.14 Standby Input Power ($I_{LED} = 0 A$)

The converter standby power was measured for all (nominal) line voltages; with the LED output disabled, and for 0 mW ~ 300 mW load on the CV output. The results are shown in Figure 20 below.

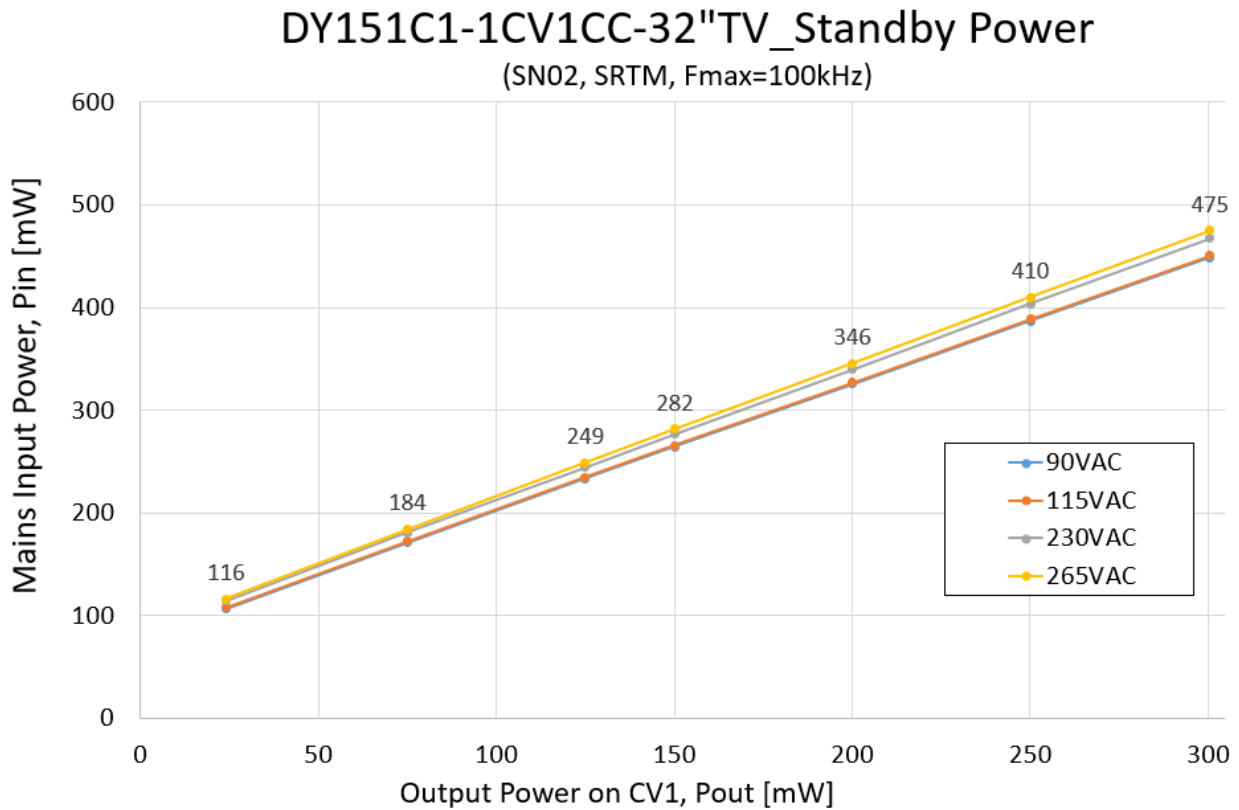


Figure 20 – Standby Power Consumption vs. Line Voltage, Room Temperature.

8.15 LED Dimming

The PSU was configured for filtered PWM dimming. The value of the LED current was measured as the duty of the PWM was increased from 10% to 100% in 10 steps. The measurements were taken at nominal LED stack voltage and repeated for:

- all line voltages
- no load or full load on CV output

The results are presented in Figure 21 and Figure 22.

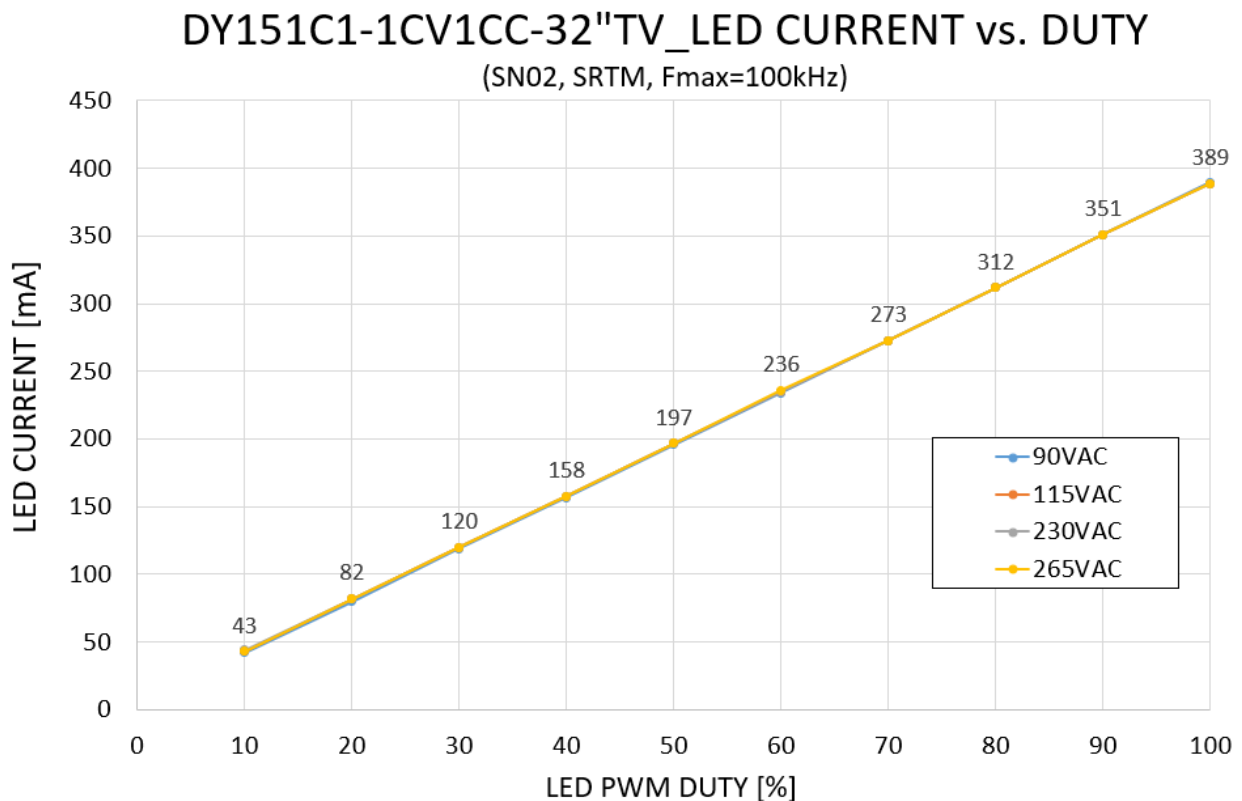


Figure 21 – Filtered PWM Dimming (CV = No-Load).

DY151C1-1CV1CC-32"TV_LED CURRENT vs. DUTY

(SN02, SRTM, F_{max}=100kHz)

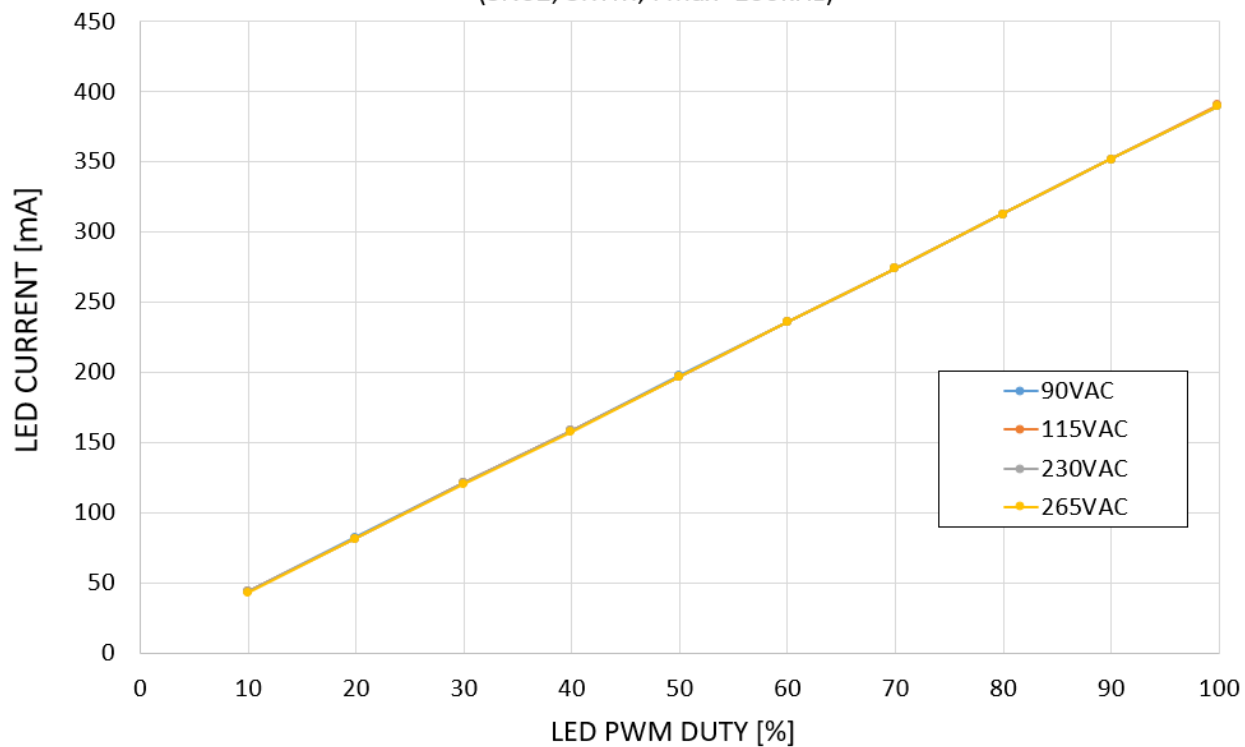


Figure 22 – Filtered PWM Dimming (CV = Nominal Load).

8.16 CV Load Transient Response

CV output voltage is measured at load transient from 0.5 A to 4.5 A. Measurement has been done at 90 VAC and 265 VAC with full LED load and 10% duty on LED load. In all cases less than 5% voltage drop observed on CV output.

Bandwidth of the channel is 20 MHz.

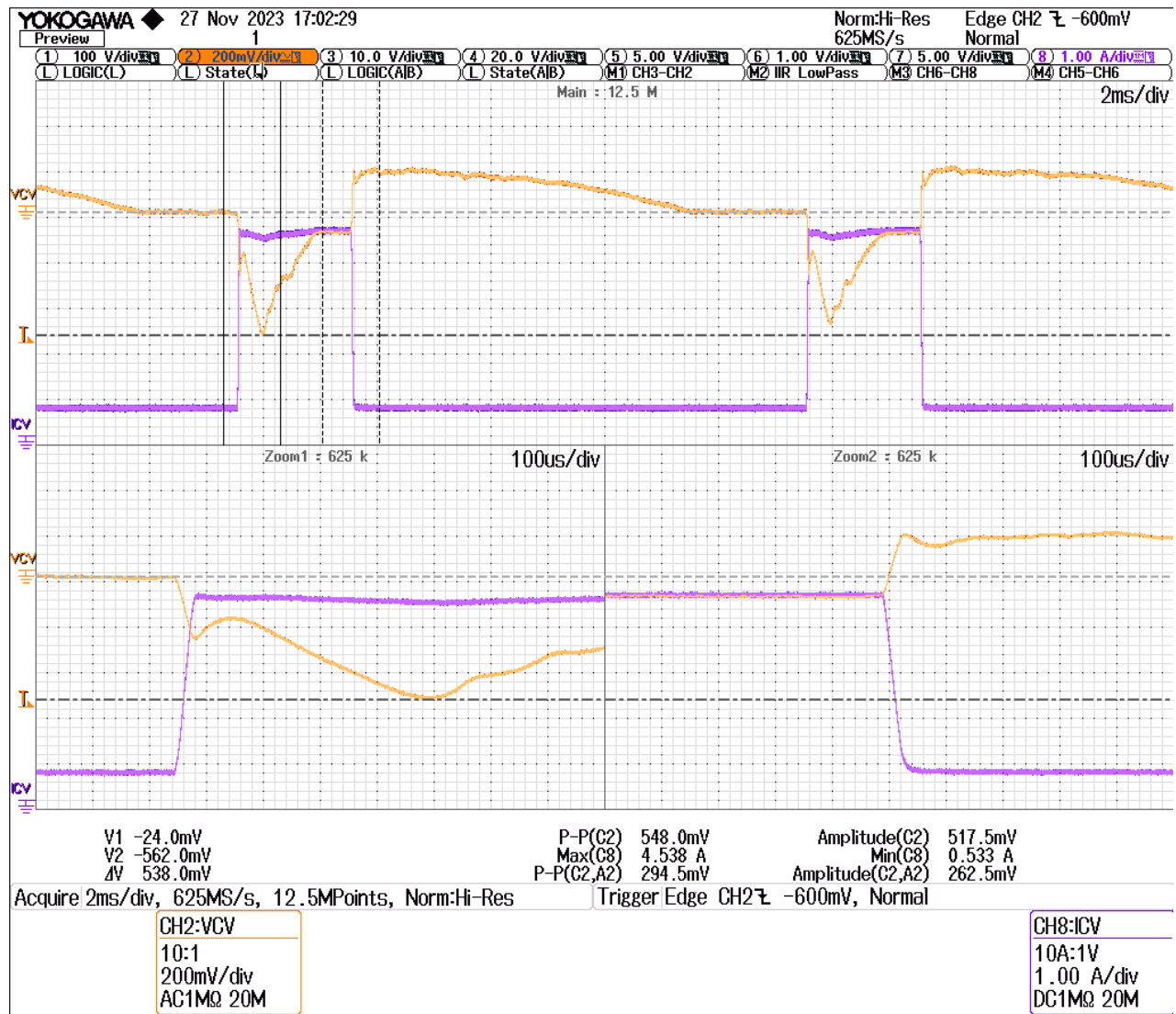


Figure 23 – CV (12 V) Output - Load Transient under Nominal LED Load at 90 VAC.
 I_{cv} = 0.5 A - 4.5 A; Undershoot 548 mV, 4.56%; Overshoot = 294.5 mV, 2.45%
 CH2: V_{cv}, CH8: I_{cv}

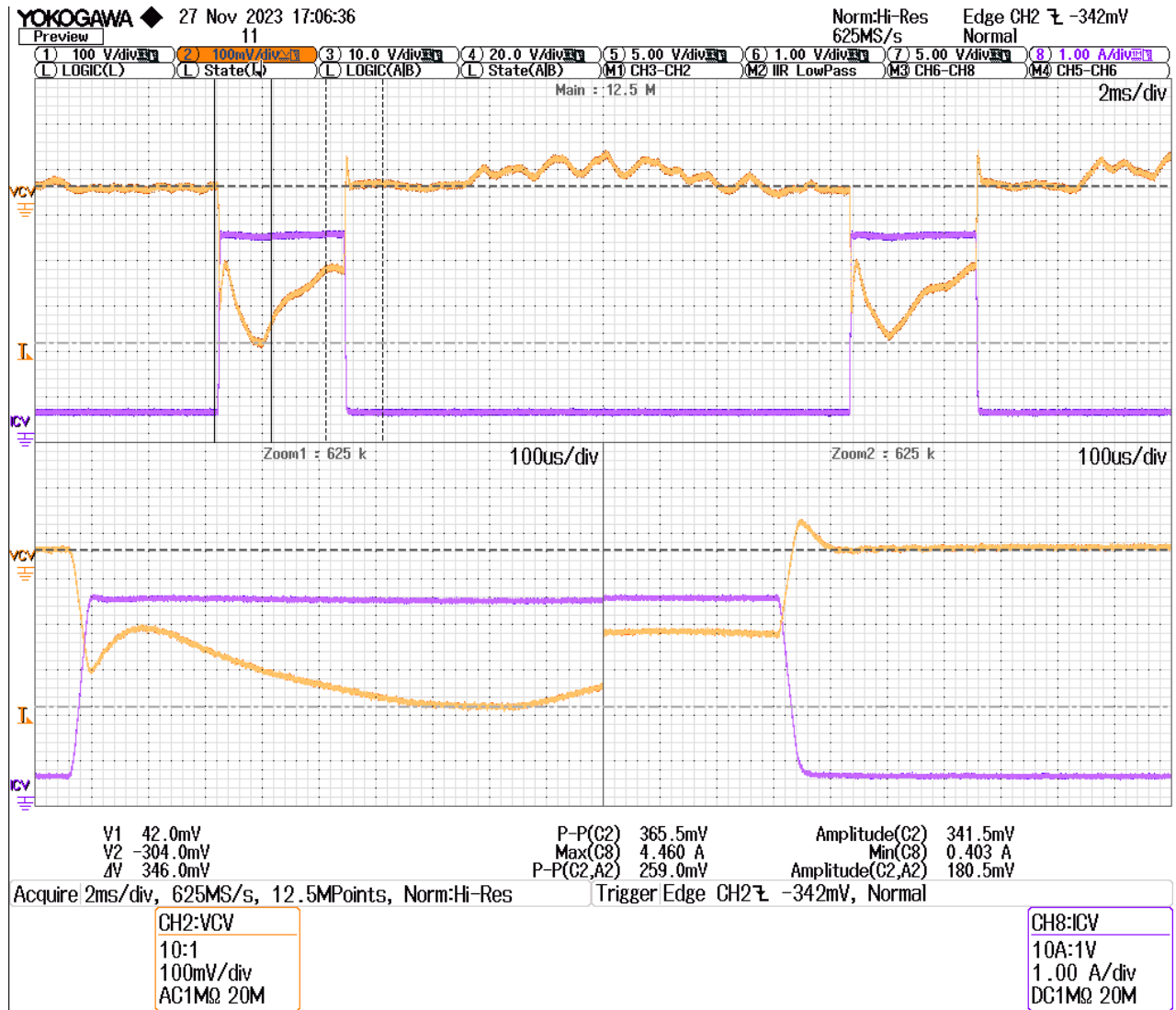


Figure 24 – CV (12 V) Output - Load Transient Under 10% Duty on LED at 90 VAC.
 I_{cv} = 0.5 A - 4.5 A; Undershoot 366 mV, 3.05%; Overshoot = 259 mV, 2.16%
 CH2: V_{cv}, CH8: I_{cv}

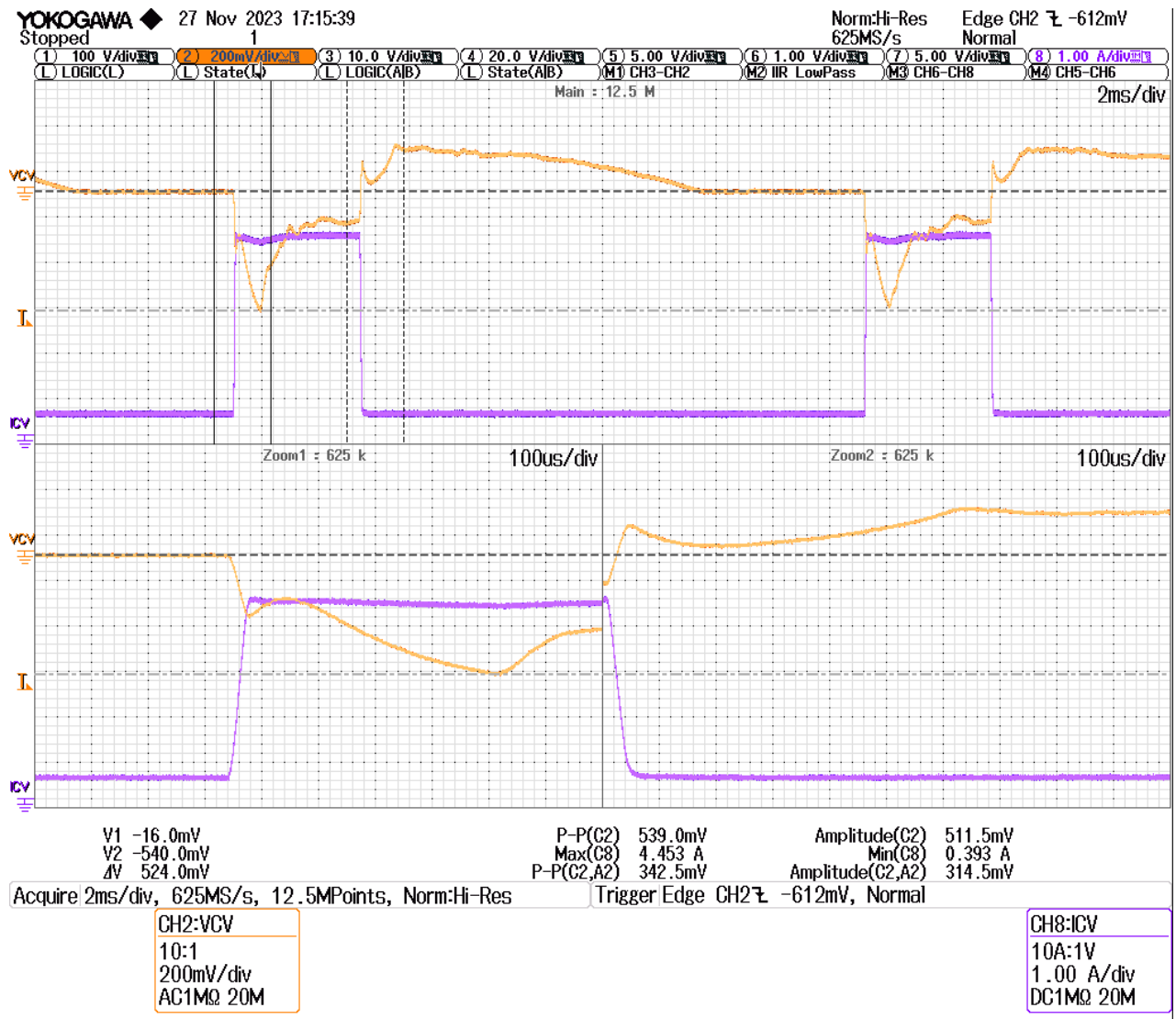


Figure 25 – CV (12 V) Output - Load Transient Under Nominal LED load at 265 VAC.
 ICV = 0.5 A - 4.5 A; Undershoot 539 mV, 4.49%; Overshoot = 342 mV, 2.85%
 CH2: V_{CV}, CH8: I_{CV}

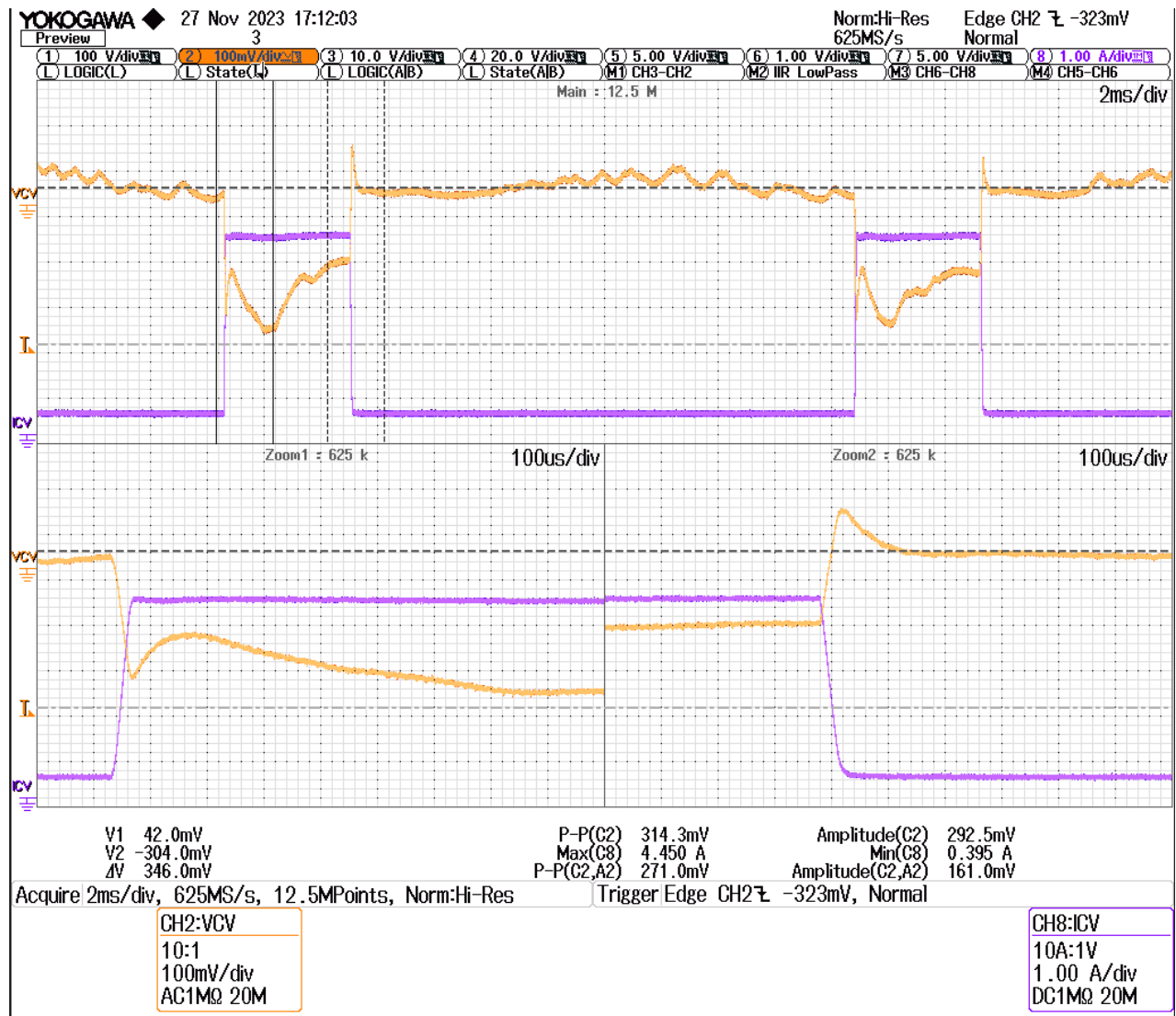


Figure 25 – CV (12 V) Output - Load Transient Under 10% Duty on LED Load at 265 VAC.
 ICV = 0.5 A - 4.5 A; Undershoot 314 mV, 2.61%; Overshoot = 271 mV, 2.25%
 CH2: V_{CV}, CH8: I_{CV}

8.17 Switching Waveforms

8.17.1 Primary Switch Maximum Voltage

Voltages on the primary FET has been measured at 265 VAC and 90 VAC under nominal and peak load.

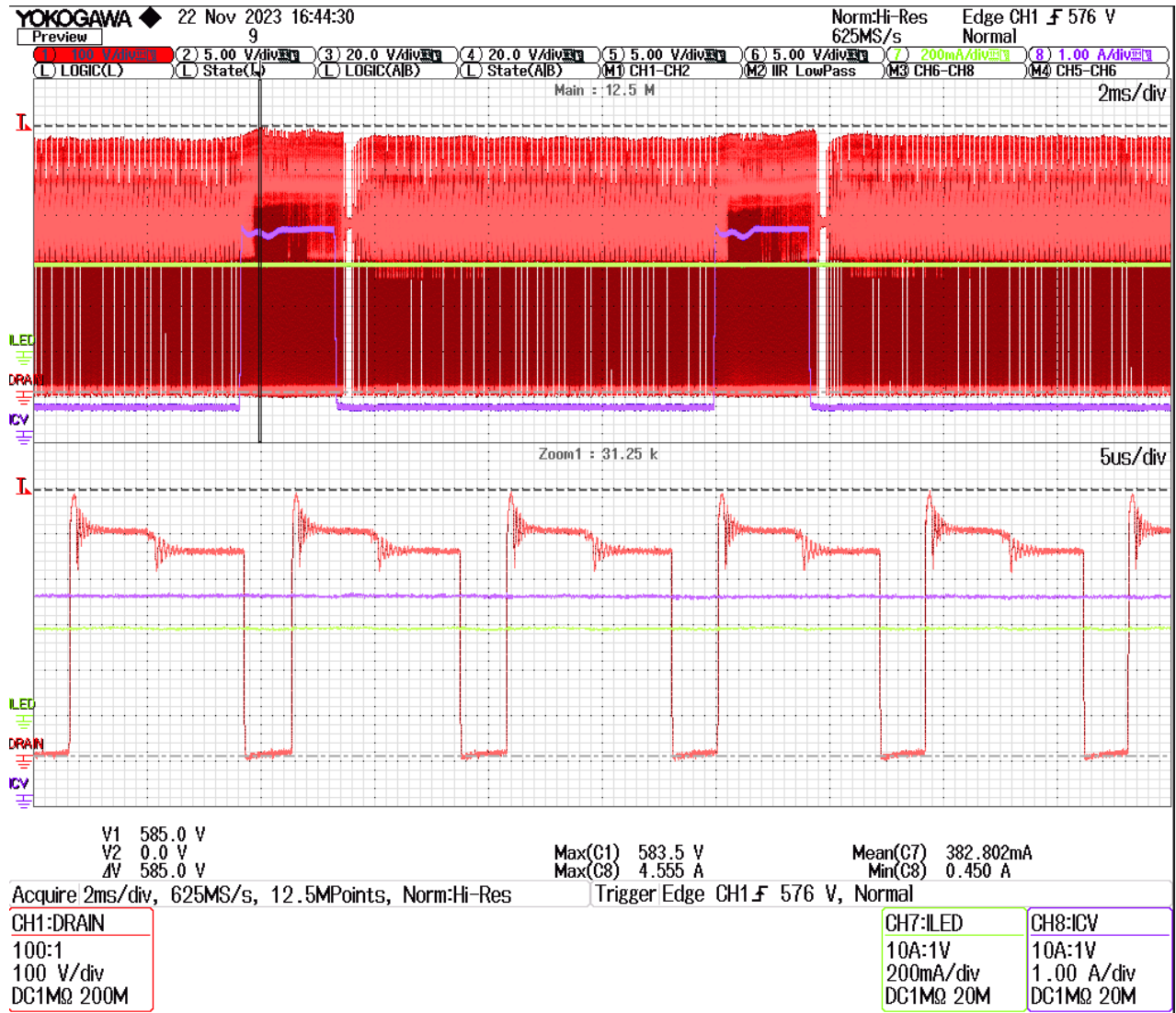


Figure 26 – Primary Switch Voltage Under Peak Load at 265 VAC.

CH1: V_{DRAIN}, CH7: I_{LED}, CH8: I_{CV}

Maximum D-S voltage across the primary switch is 585V.

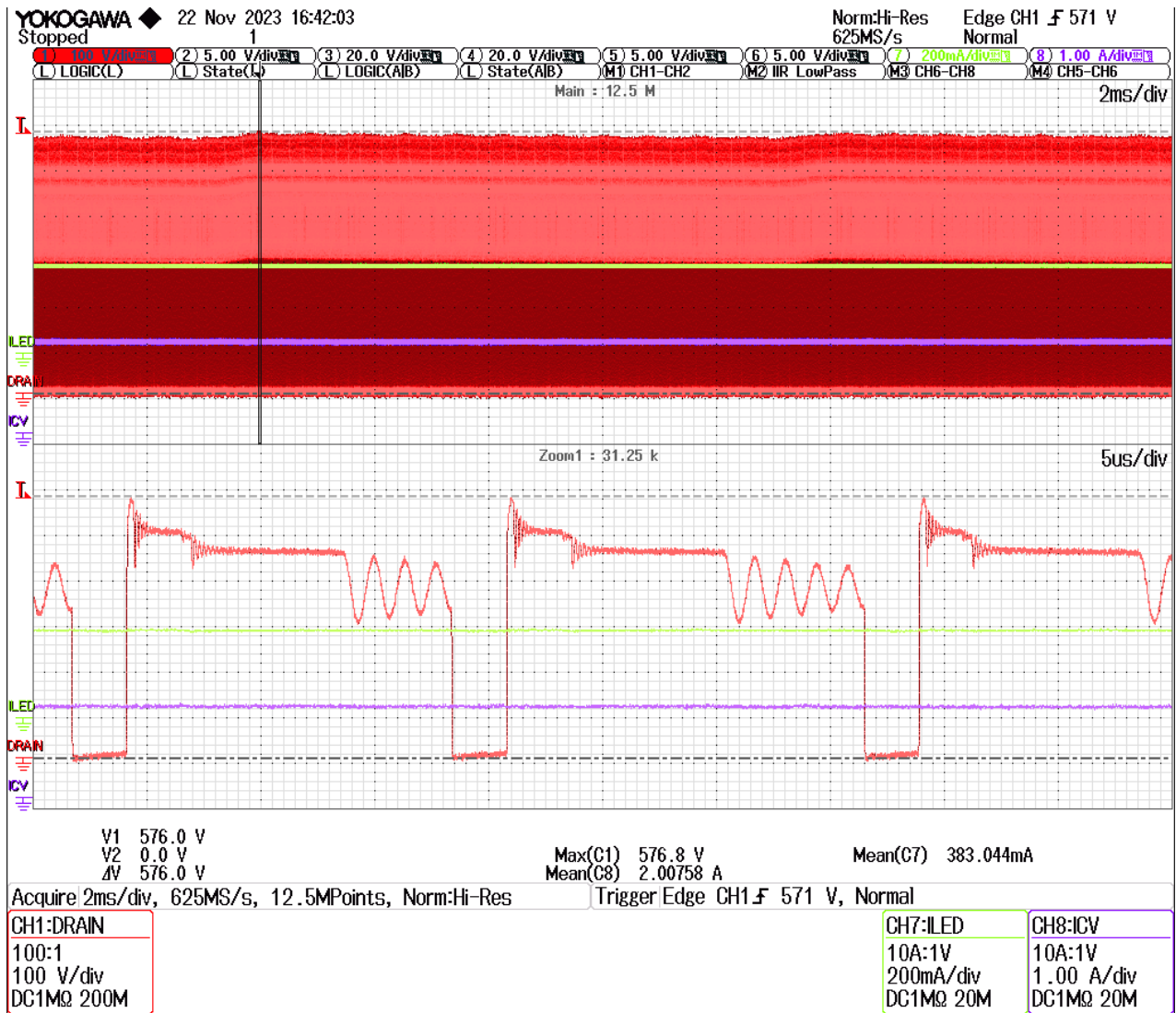


Figure 27 – Primary Switch Voltage Under Nominal Load at 265 VAC.

CH1: V_{DRAIN}, CH7: I_{LED}, CH8: I_{CV}

Maximum D-S voltage across the primary switch is 577 V.

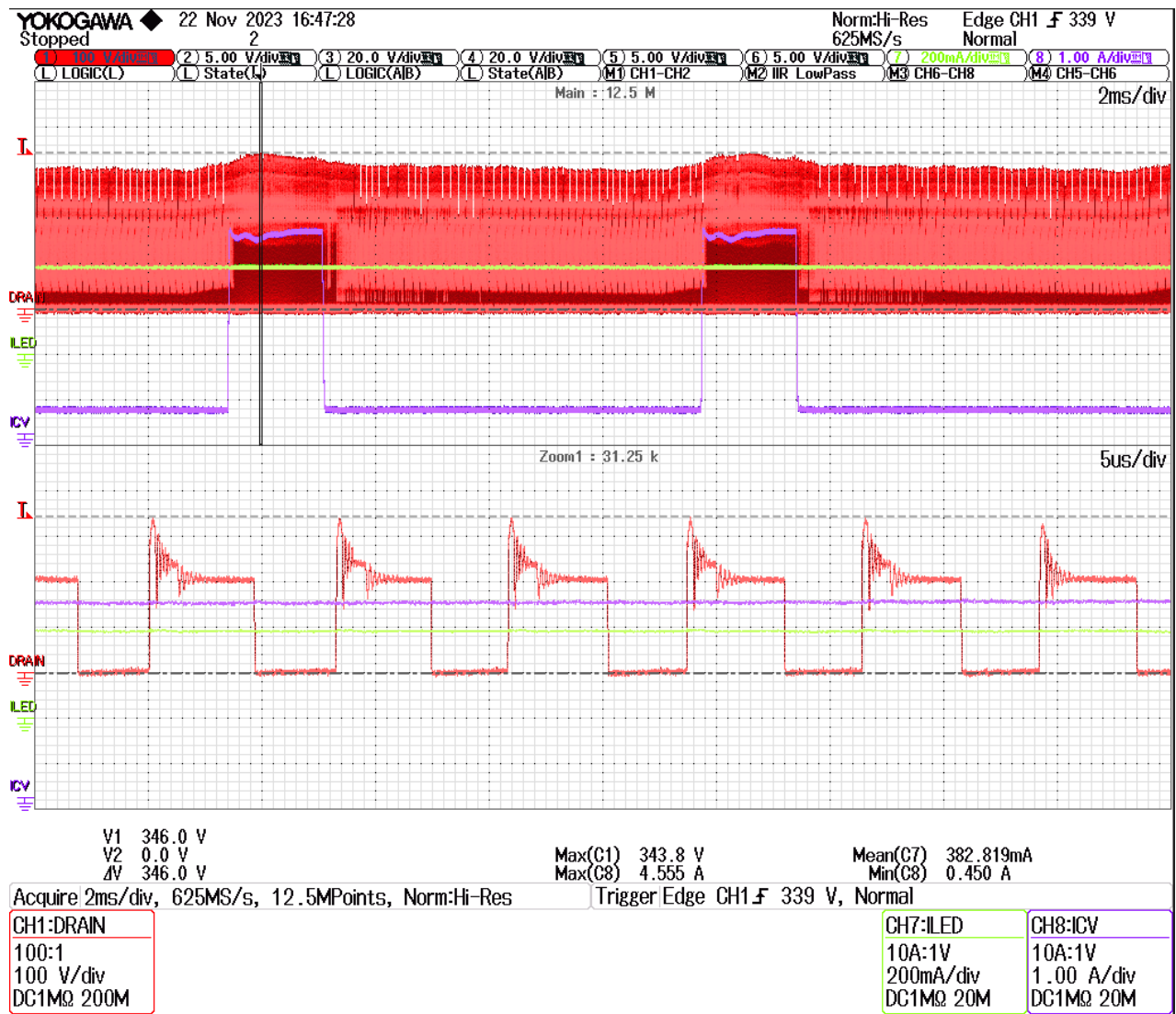


Figure 28 – Primary Switch Voltage Under Peak Load at 90 VAC.

CH1: V_{DRAIN}, CH7: I_{LED}, CH8: I_{CV}

Maximum D-S voltage across the primary switch is 344 V.

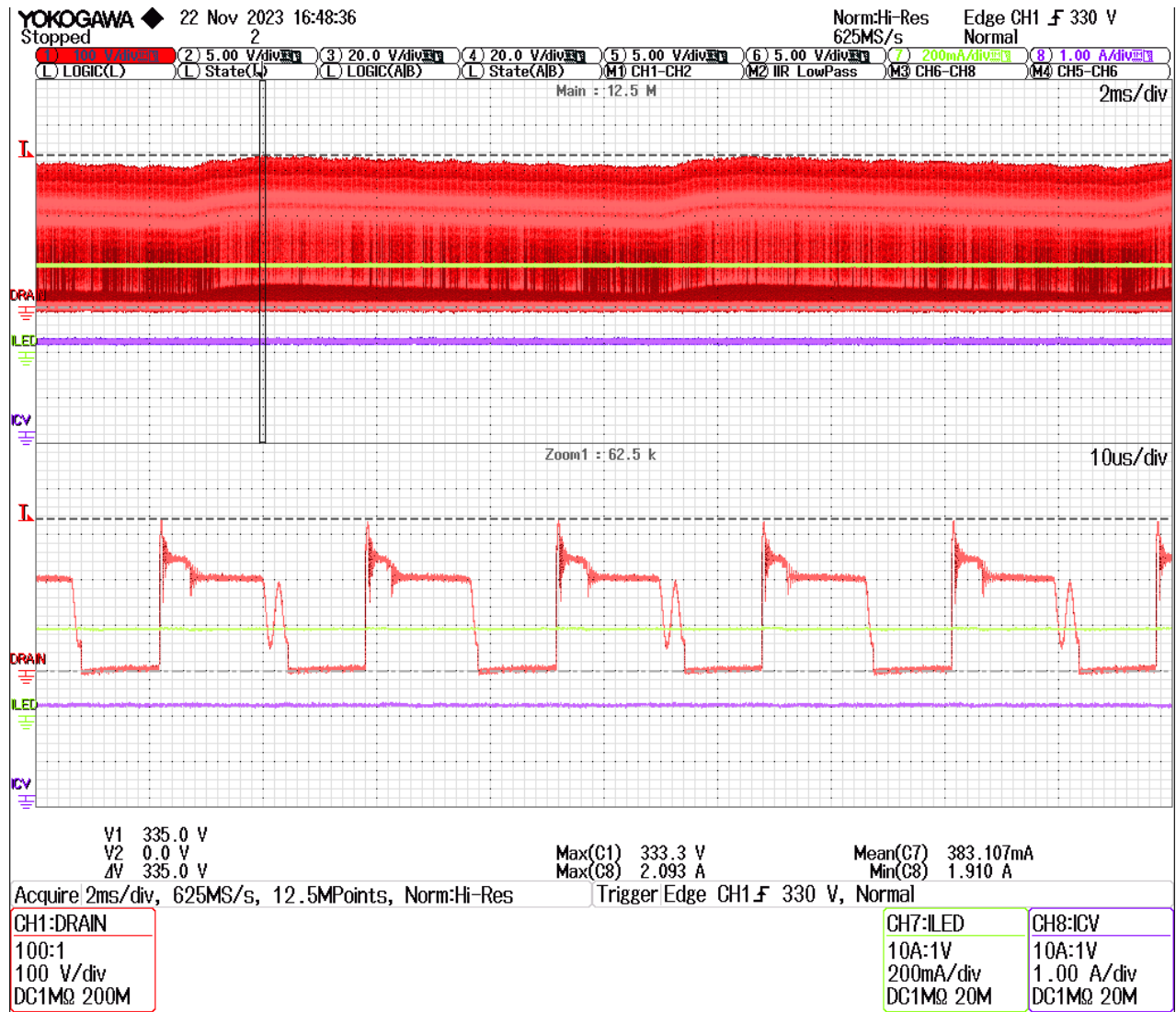


Figure 29 – Primary Switch Voltage Under Nominal Load at 90 VAC.

CH1: V_{DRAIN}, CH7: I_{LED}, CH8: I_{CV}

Maximum D-S voltage across the primary switch is 333 V.

8.17.2 Primary Switching Frequency

The primary switching frequency of the converter varies depending on the line and load conditions. It was measured under peak load at minimum line input of 90 VAC. The maximum switching frequency occurs at the minimum DC input (110 kHz). LED channel has its nominal current, 380 mA and CV channel has a peak current which is 4.5 A with a 40% duty and 100 Hz load step conditions.

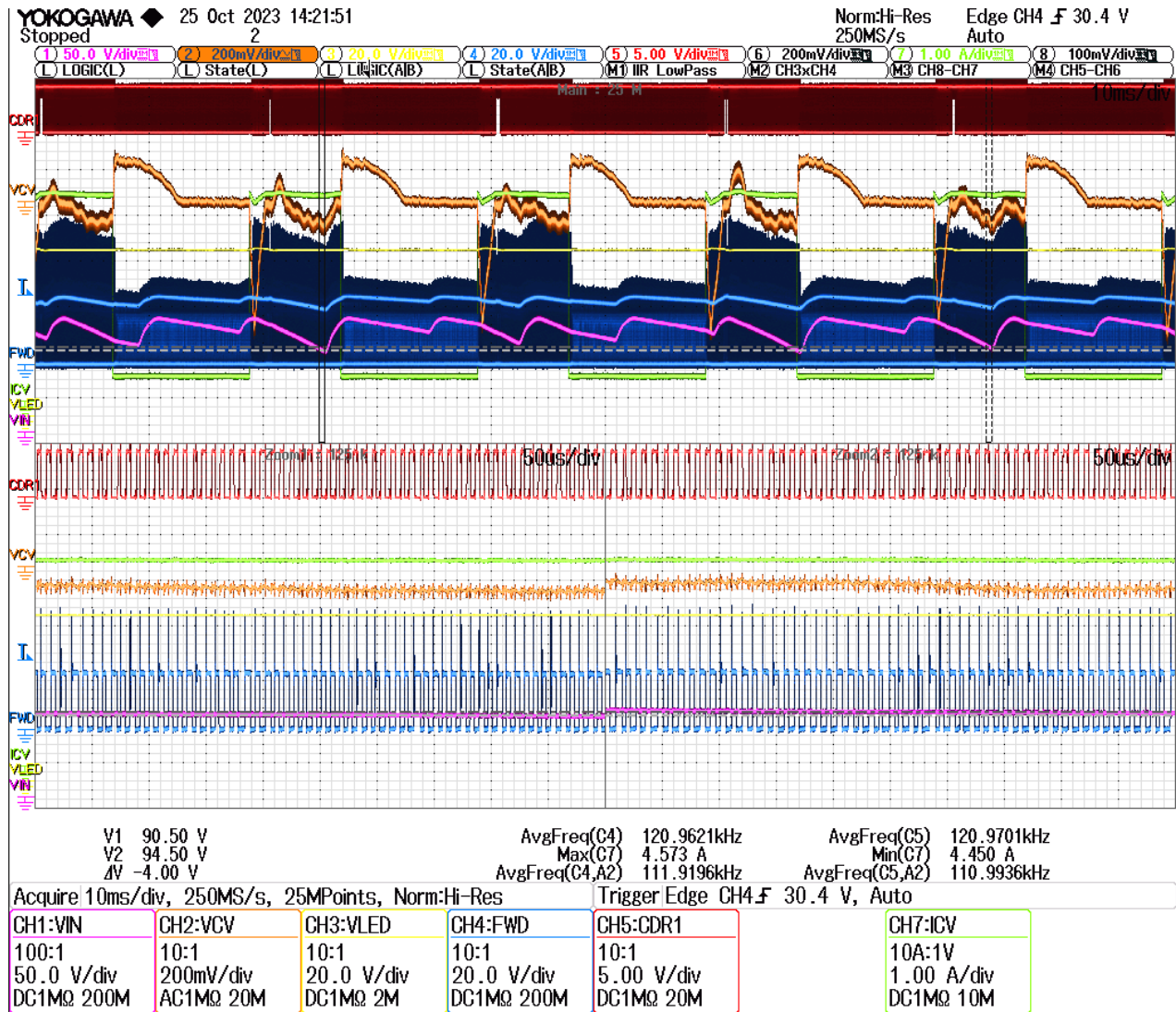


Figure 30 – Max Primary Switching Frequency (110 kHz).

8.17.3 Transformer Current Waveforms

| | |
|-----|-----------------|
| CH1 | SR Current |
| CH5 | Primary Current |
| CH7 | ICV1 |
| CH8 | ILED |

Table 2 – Scope Channel Allocation (This Section).

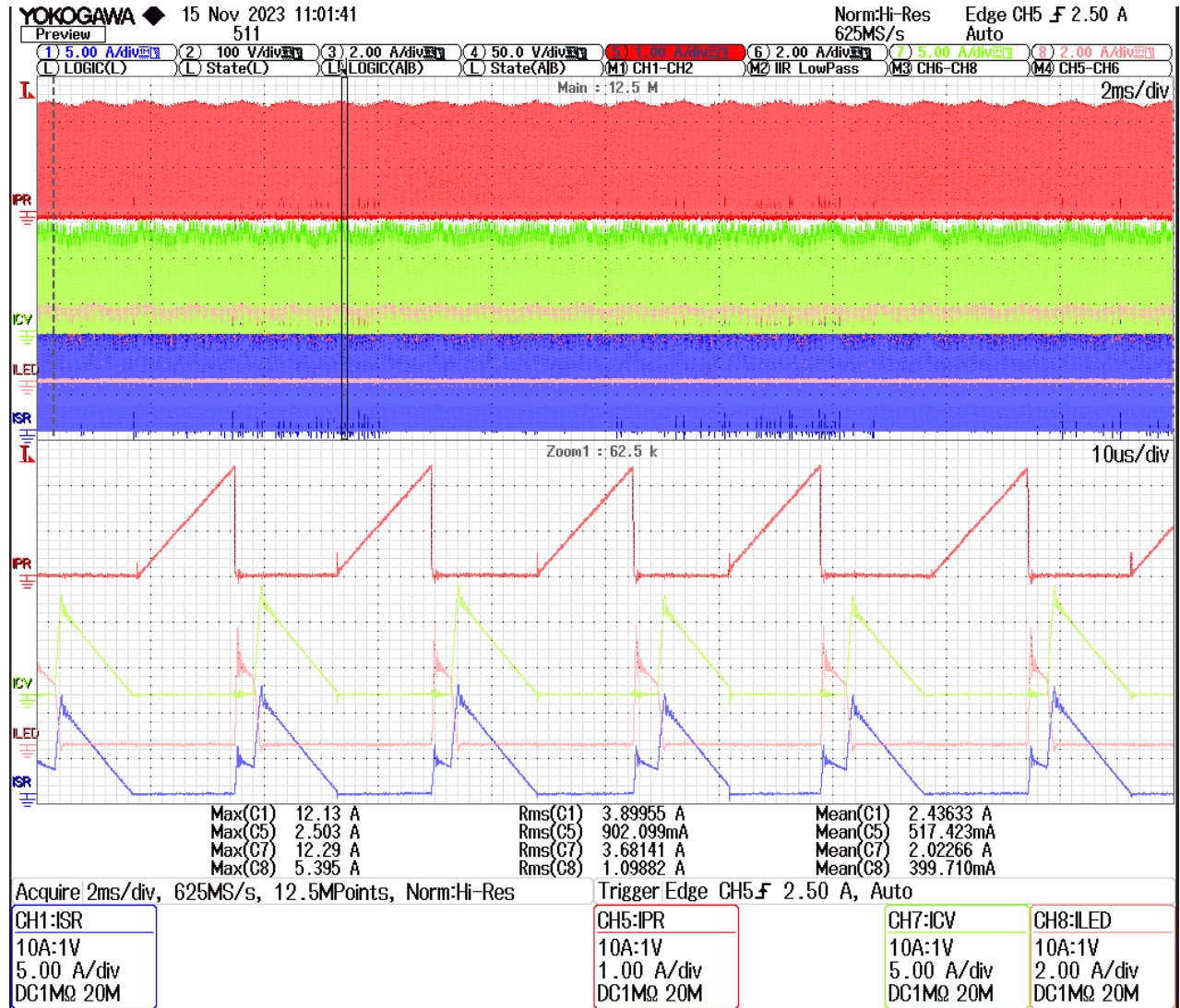


Figure 31 – Transformer Winding Currents at Minimum Input Voltage.

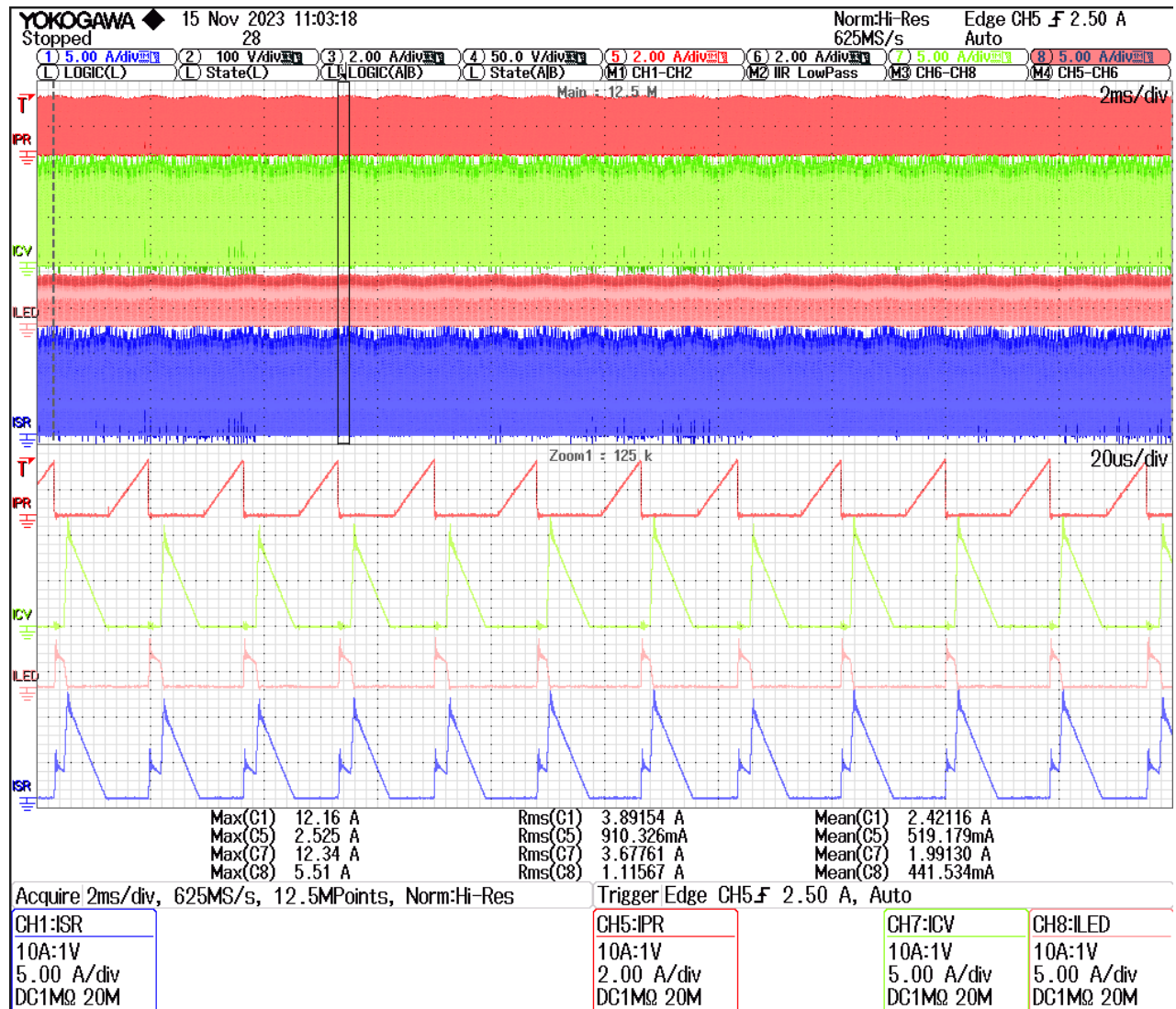


Figure 32 – Transformer Currents – Detailed View.

8.18 Start-Up

| | |
|-----|---------------|
| CH1 | Drain voltage |
| CH2 | CV voltage |
| CH3 | LED voltage |
| CH4 | BPS voltage |
| CH5 | SEL GATE |
| CH7 | LED current |
| CH8 | CV current |

Table 5 – Scope Channel Allocation (This Section).

8.18.1 Full Load Start-up

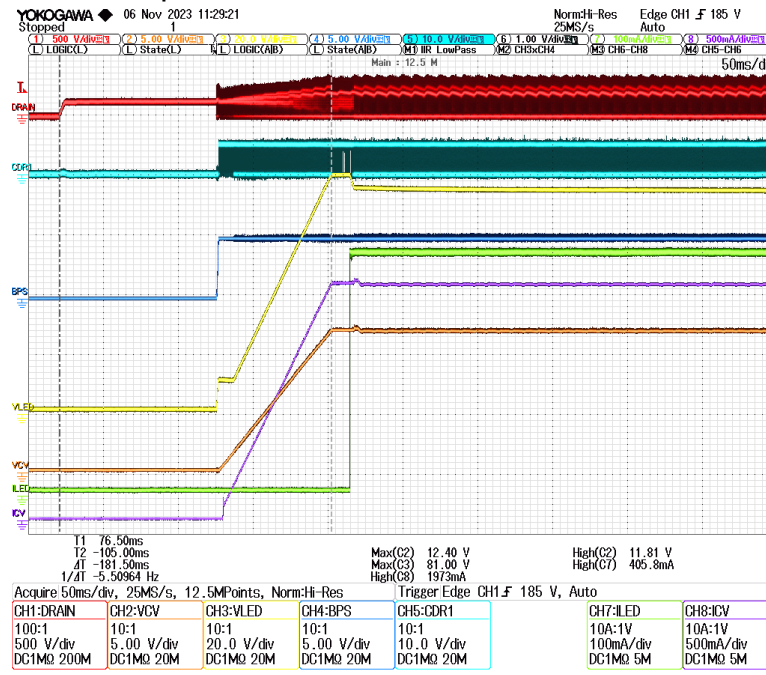


Figure 33 – Line input 90 VAC, Start-up Delay 105 ms, Start-Up Time 181 ms.

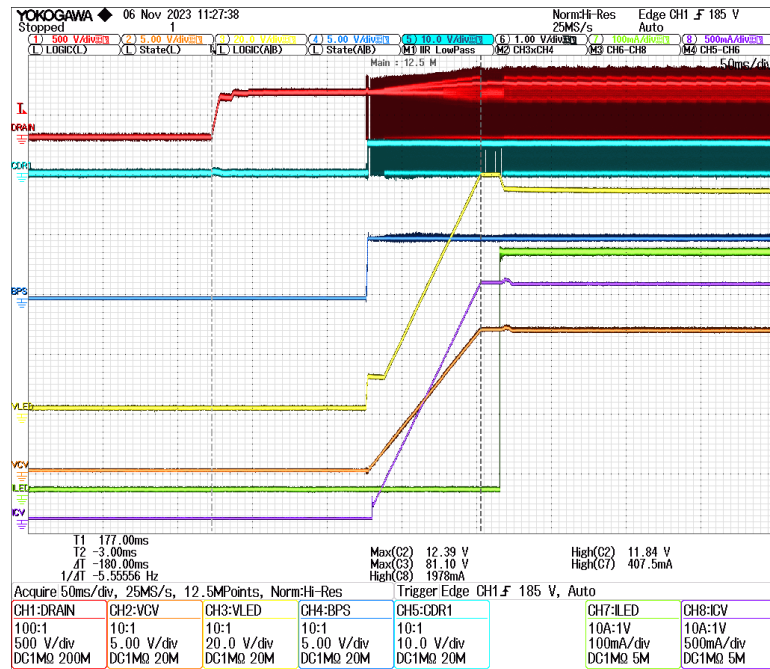


Figure 34 – Line Input 265 VAC, Start-up Delay 105 ms, Start-up Time 180 ms.

8.18.2 No-Load Start-up

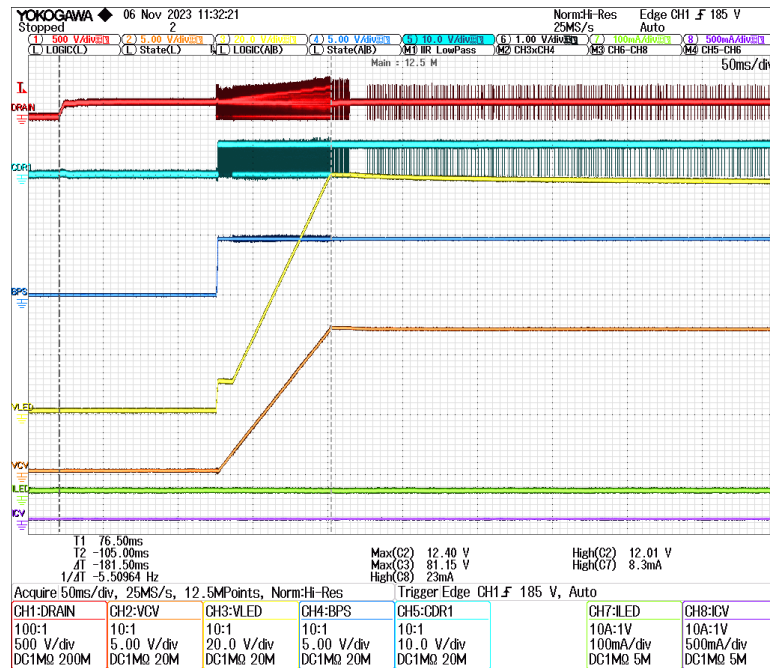


Figure 35 – Line Input 90 VAC, Start-up Delay 105 ms, Start-up Time 181 ms.

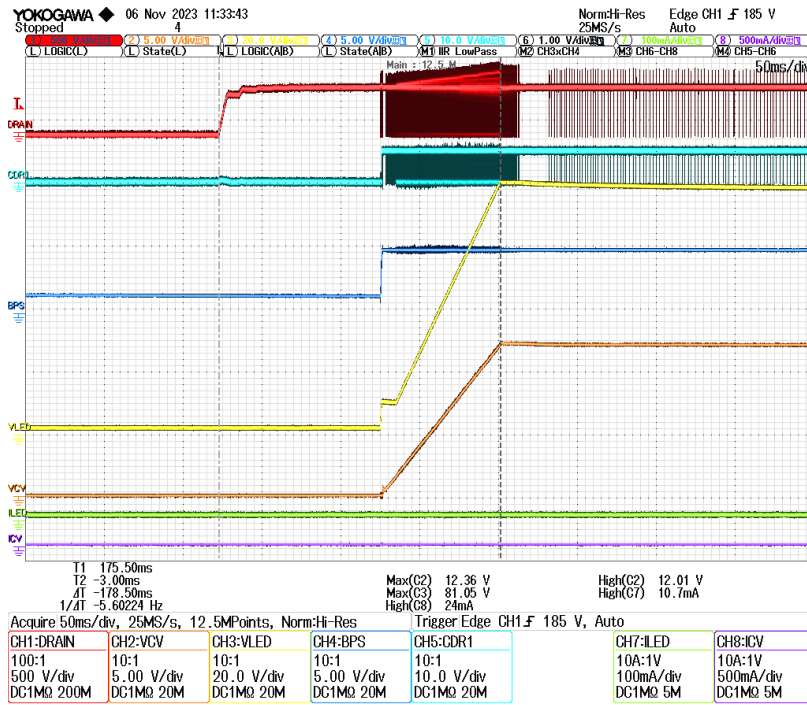


Figure 36 – Line Input 265 VAC, Start-up Delay 105 ms, Start-up Time 178 ms.

8.18.3 Start-up Under CV and LED Fault Conditions

| | |
|-----|------|
| CH2 | VCV |
| CH3 | VLED |
| CH4 | FWD |
| CH5 | CDR1 |
| CH8 | ILED |

Table 6 – Scope Channel Allocation (This Section).

The converter was tested for start-up under two types of single fault conditions, namely:

- Short-circuit to GND at CV output;
- Short-circuit to Vled- at Vled+ output;
- Open circuit of feedbacks;

In all cases, the converter protection prevented any permanent damage to its components. The line fuse F1 remained intact. The converter went into auto restart for the duration of the fault condition. It resumed normal operation after the fault condition was removed.

Details of the start-up behavior under those fault conditions are shown in Figure 36 to Figure 51.

| CV=0A | Faults Before Start-up | | | | | | | |
|---------------|-------------------------|-------------------------|-----------------------|-----------------------|-------------------------|-------------------------|-------------|-----------|
| LED=0A | CV short to GND | | VLED+ short to VLED- | | CV FB open | | LED FB open | |
| | 90 V | 265 V | 90 V | 265 V | 90 V | 265 V | 90 V | 265 V |
| Protect. Def. | PLIM/ Request Not Clear | PLIM/ Request Not Clear | LED Fault (LED=380mA) | LED Fault (LED=380mA) | PLIM/ Request Not Clear | PLIM/ Request Not Clear | LED Fault | LED Fault |

| CV=2A | Faults Before Start-up | | | | | | | |
|---------------|-------------------------|-------|----------------------|-----------|-------------------------|-------------------------|-------------|-----------|
| LED=380mA | CV short to GND | | VLED+ short to VLED- | | CV FB open | | LED FB open | |
| | 90 V | 265 V | 90 V | 265 V | 90 V | 265 V | 90 V | 265 V |
| Protect. Def. | PLIM/ Request Not Clear | OVP | LED Fault | LED Fault | PLIM/ Request Not Clear | PLIM/ Request Not Clear | LED Fault | LED Fault |

Table 7 – Protection Definitions Under Fault Conditions.

8.18.3.1 Start-up Under CV Fault Conditions

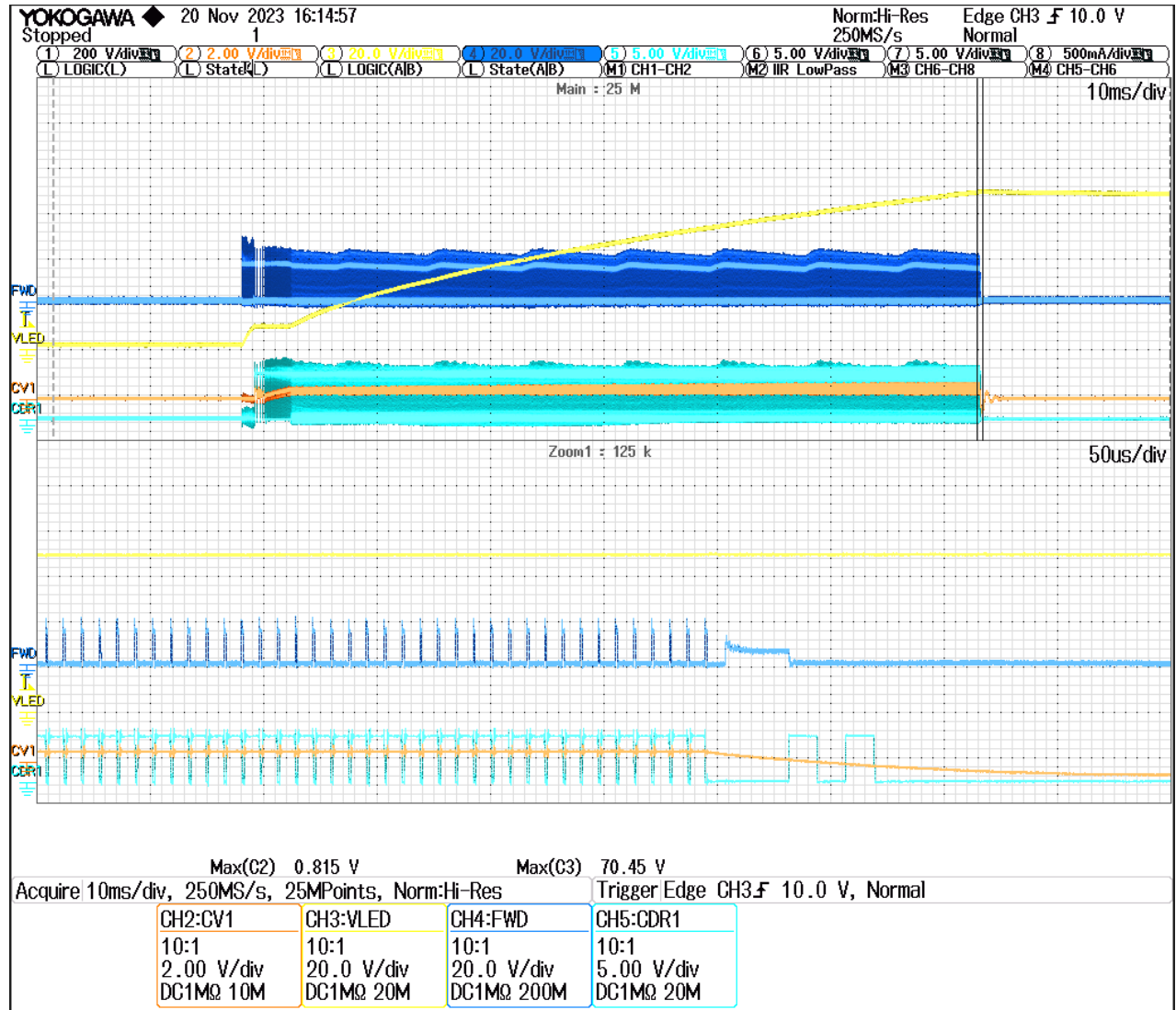


Figure 37 – Start-up With CV1 Shorted to GND. Line Input 90 V, CV and LED No-Load.

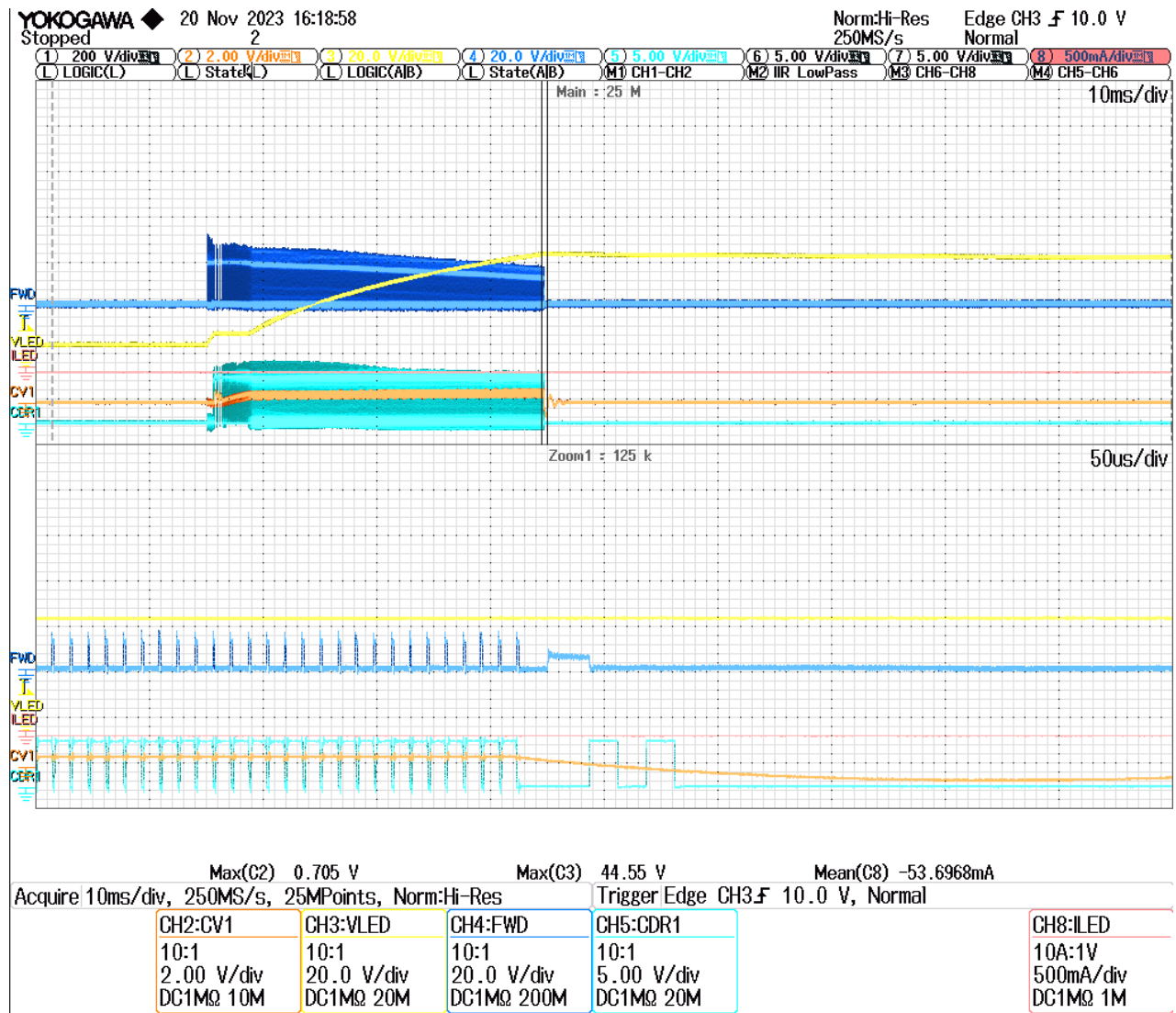


Figure 38 – Start-up With CV1 Shorted to GND. Line Input 265 V, CV and LED No-Load.

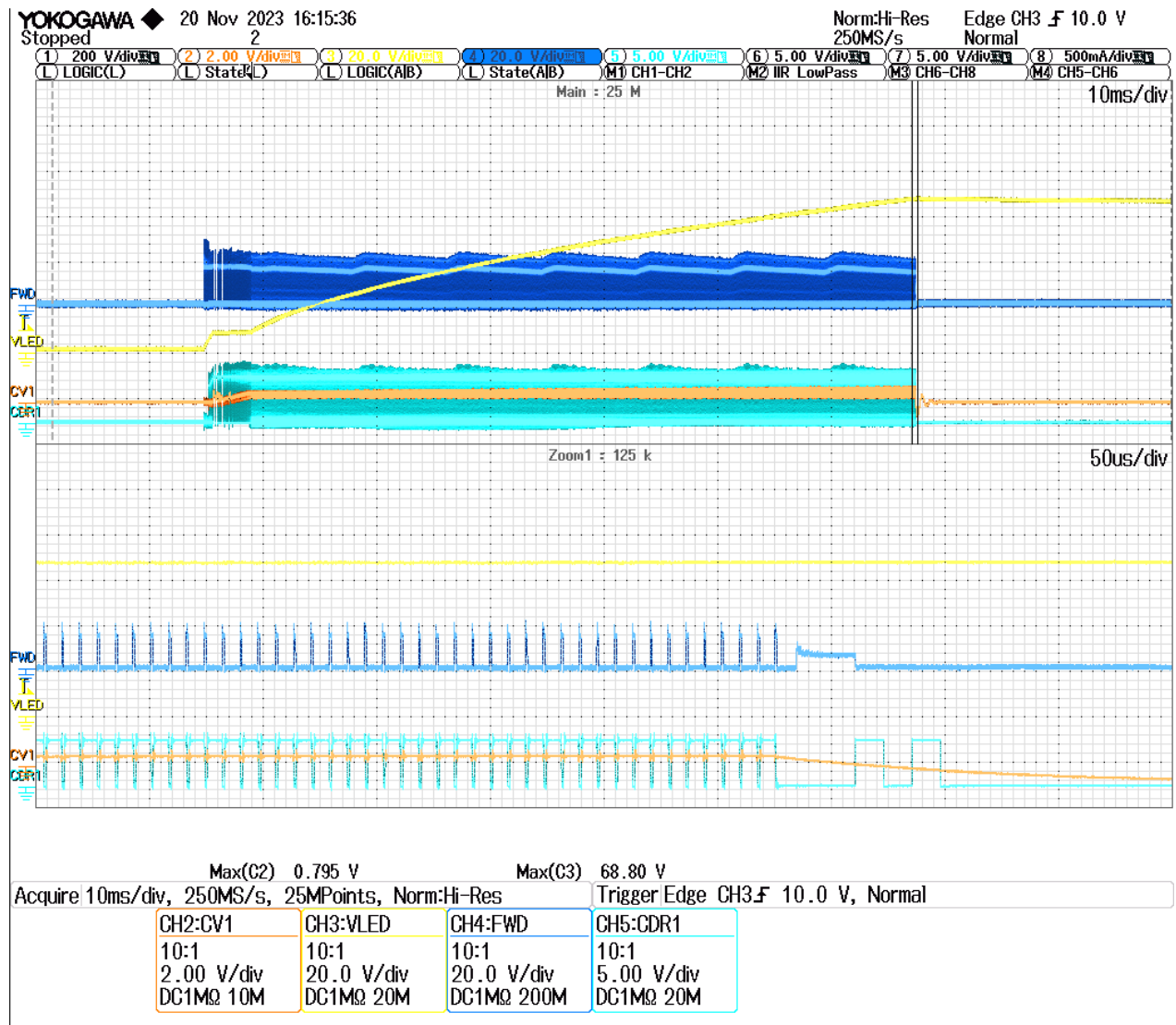


Figure 39 – Start-up With CV1 Shorted to GND. Line Input 90 V, CV and LED Nominal Load.

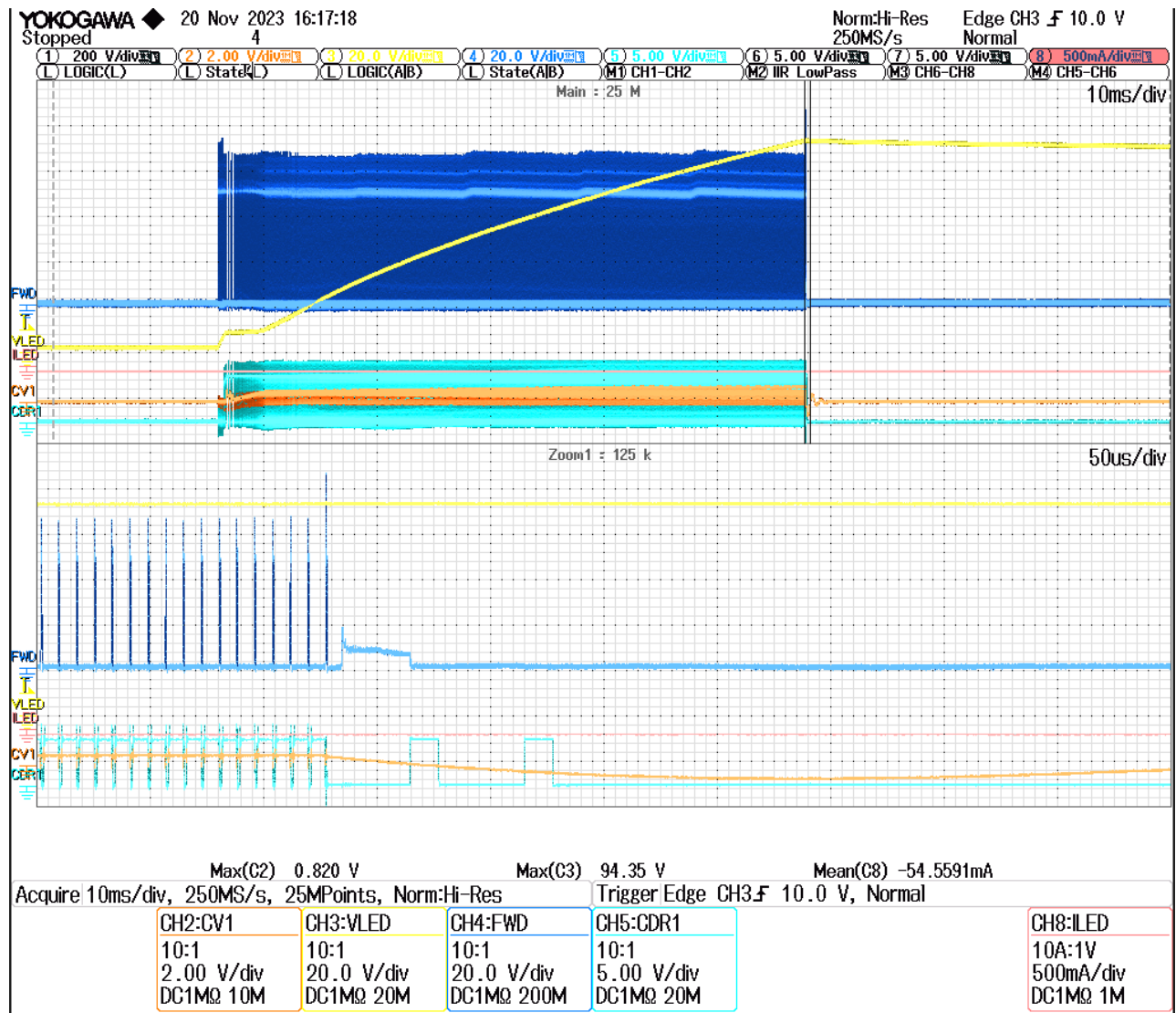


Figure 40 – Start-up With CV1 Shorted to GND. Line Input 265 V, CV and LED Nominal Load.

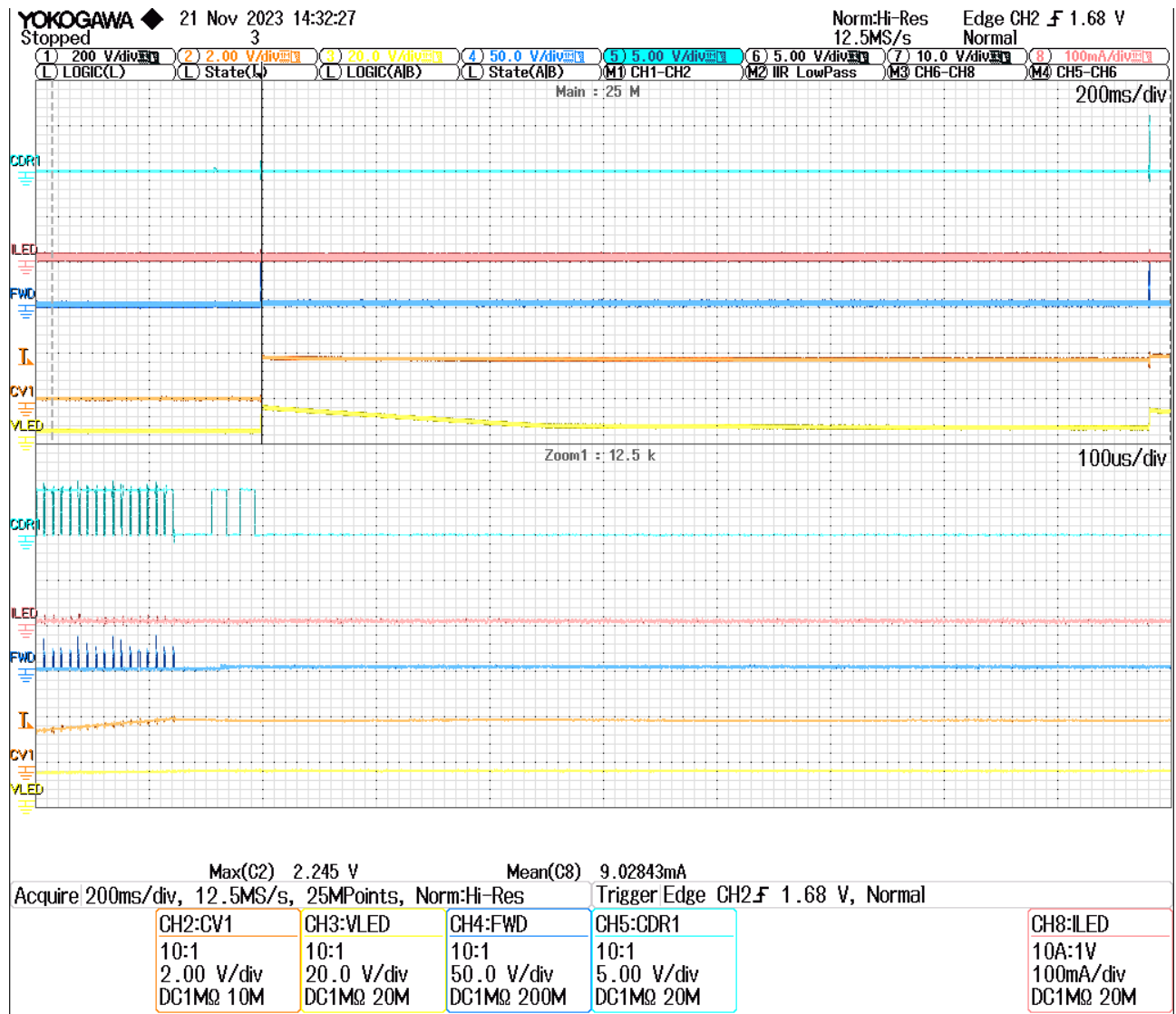
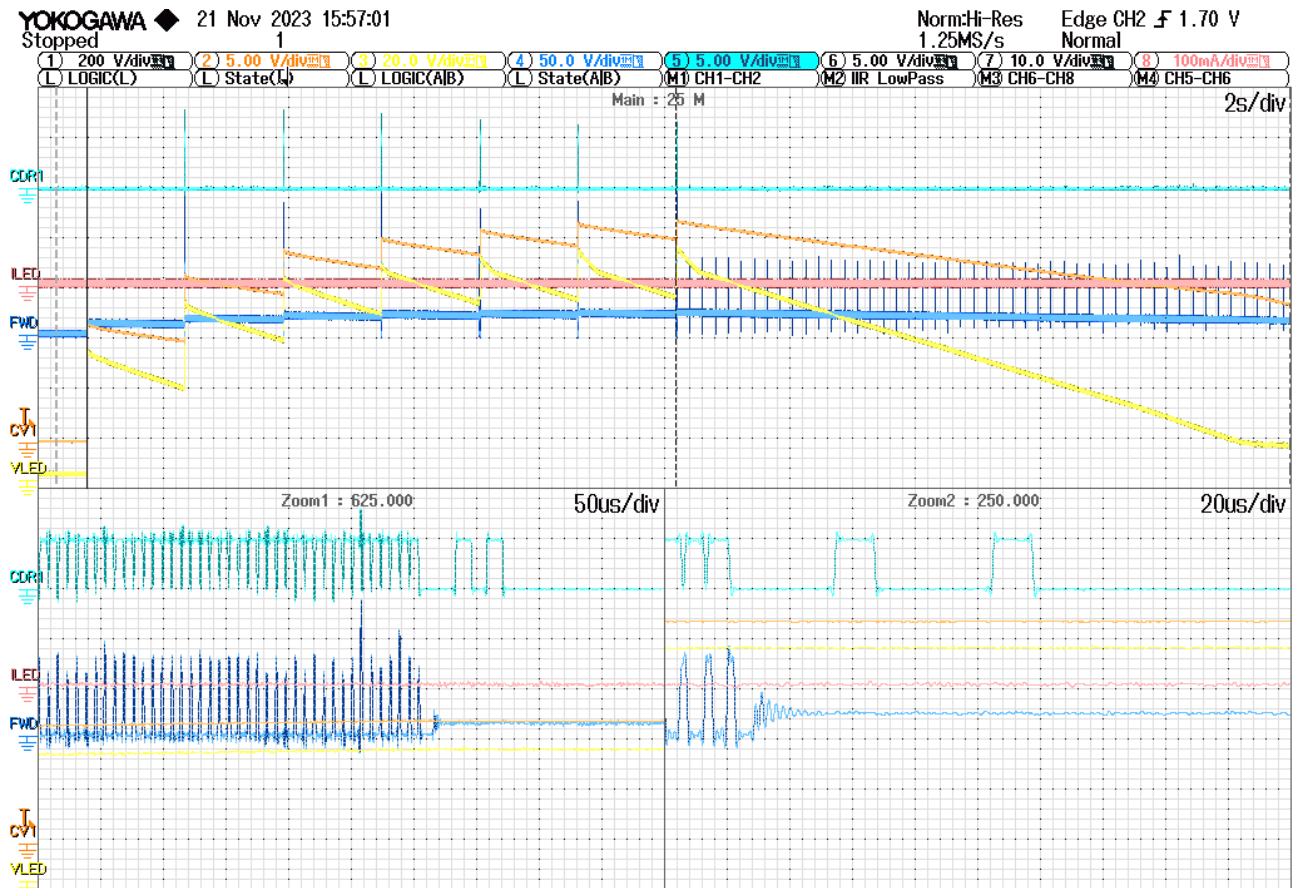


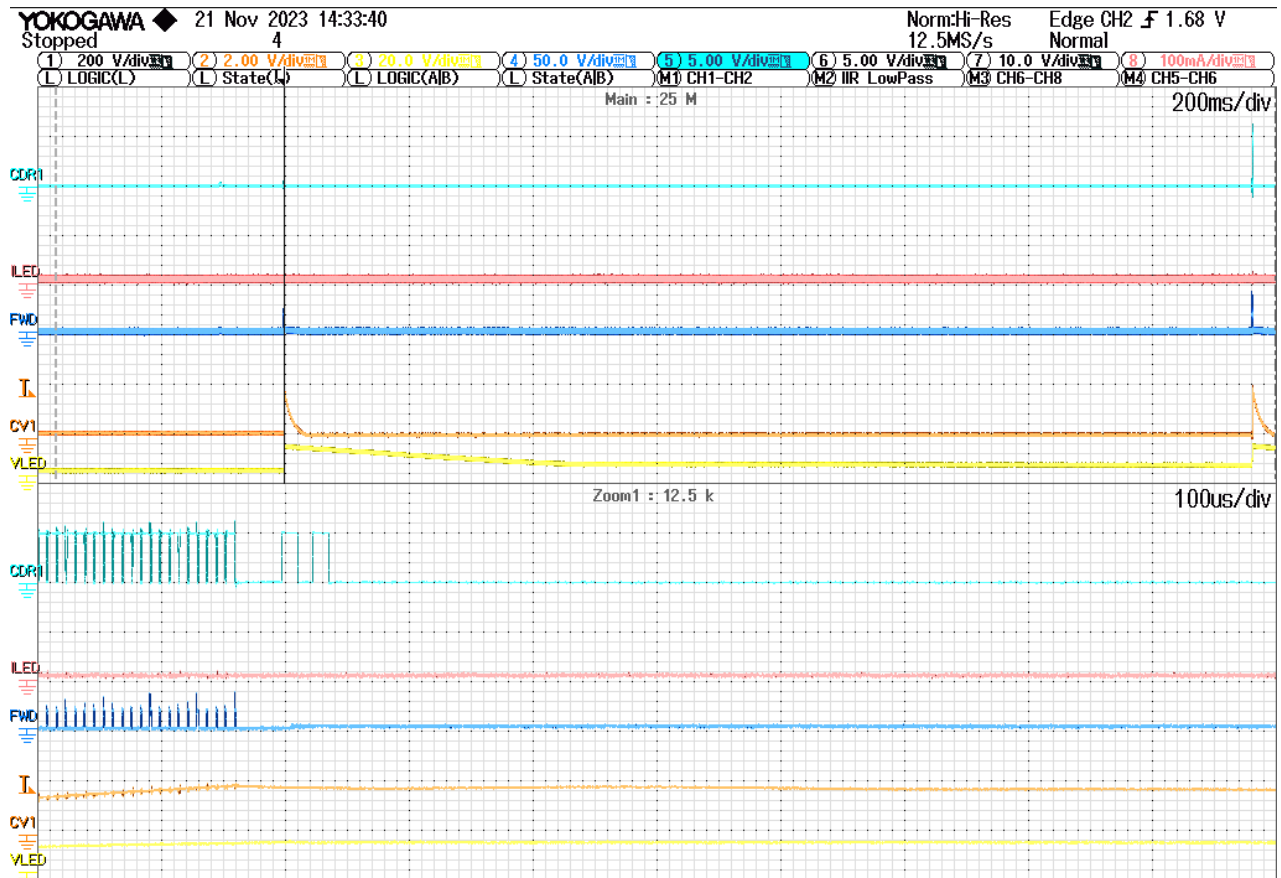
Figure 41 – Start-up With CV FB Open. Line Input 90 V, CV and LED No-Load.



Max(C3) 93.75 V
 Acquire 2s/div, 1.25MS/s, 25MPoints, Norm:Hi-Res Trigger Edge CH2F 1.70 V, Normal

| | | | | |
|--|---|---|---|--|
| CH2:CV1 10:1 5.00 V/div DC1MΩ 10M | CH3:VLED 10:1 20.0 V/div DC1MΩ 20M | CH4:FWD 10:1 50.0 V/div DC1MΩ 200M | CH5:CDR1 10:1 5.00 V/div DC1MΩ 20M | CH8:ILED 10A:1V 100mA/div DC1MΩ 20M |
|--|---|---|---|--|

Figure 42 – Start-up With CV FB Open. Line Input 265 V, CV and LED No-Load.



| | | | | | |
|---|------------|--------------------|------------|-----------------------------------|--|
| Max(C2) 2.135 V | | Mean(C8) 10.4558mA | | | |
| Acquire 200ms/div, 12.5MS/s, 25MPoints, Norm:Hi-Res | | | | Trigger Edge CH2 F 1.68 V, Normal | |
| CH2:CV1 | CH3:VLED | CH4:FWD | CH5:CDR1 | CH8:ILED | |
| 10:1 | 10:1 | 10:1 | 10:1 | 10A:1V | |
| 2.00 V/div | 20.0 V/div | 50.0 V/div | 5.00 V/div | 100mA/div | |
| DC1MΩ 10M | DC1MΩ 20M | DC1MΩ 200M | DC1MΩ 20M | DC1MΩ 20M | |

Figure 43 – Start-up With CV FB Open. Line Input 90 V, CV and LED Nominal Load.

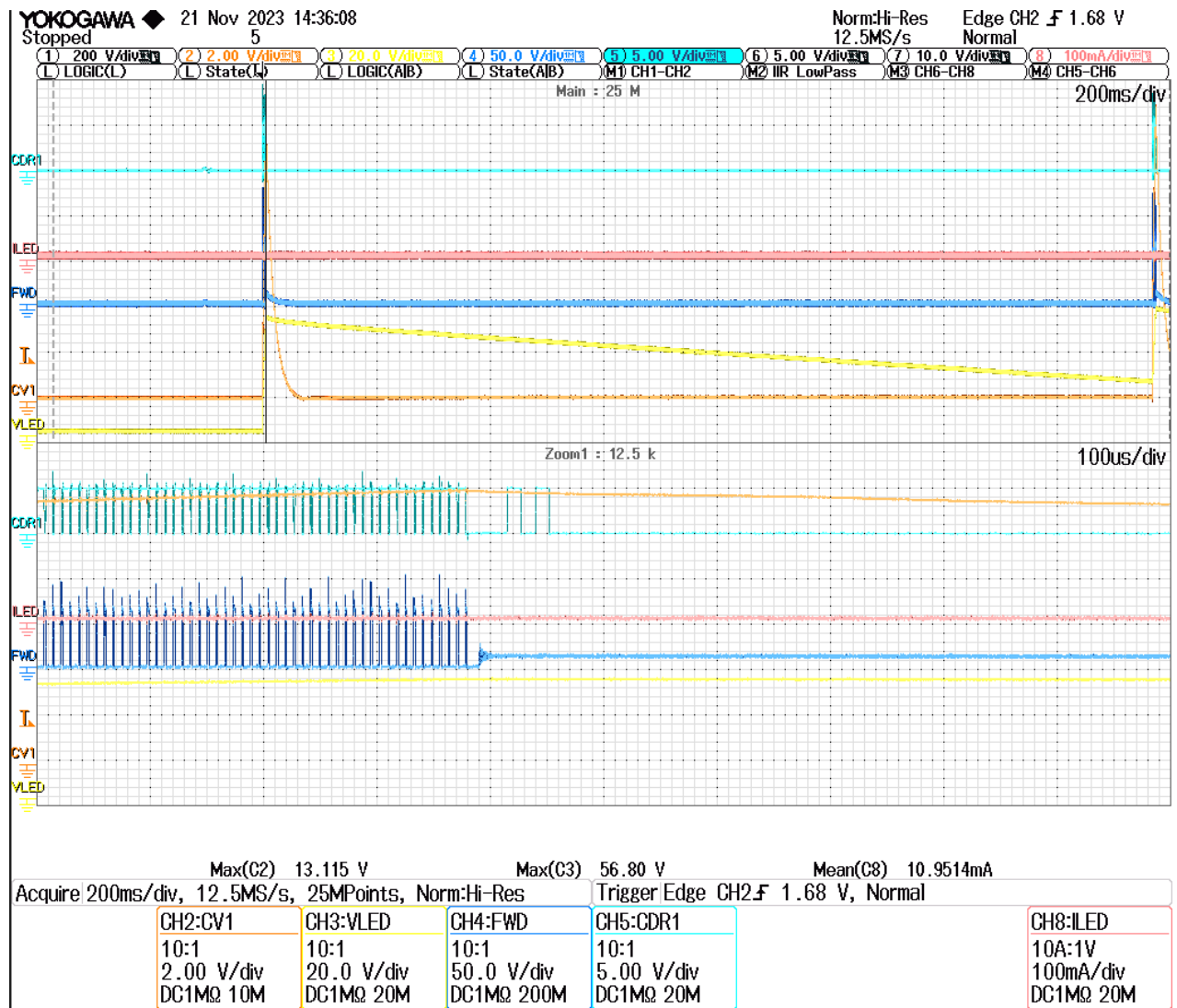


Figure 44 – Start-up With CV FB Open. Line Input 265 V, CV and LED Nominal Load.

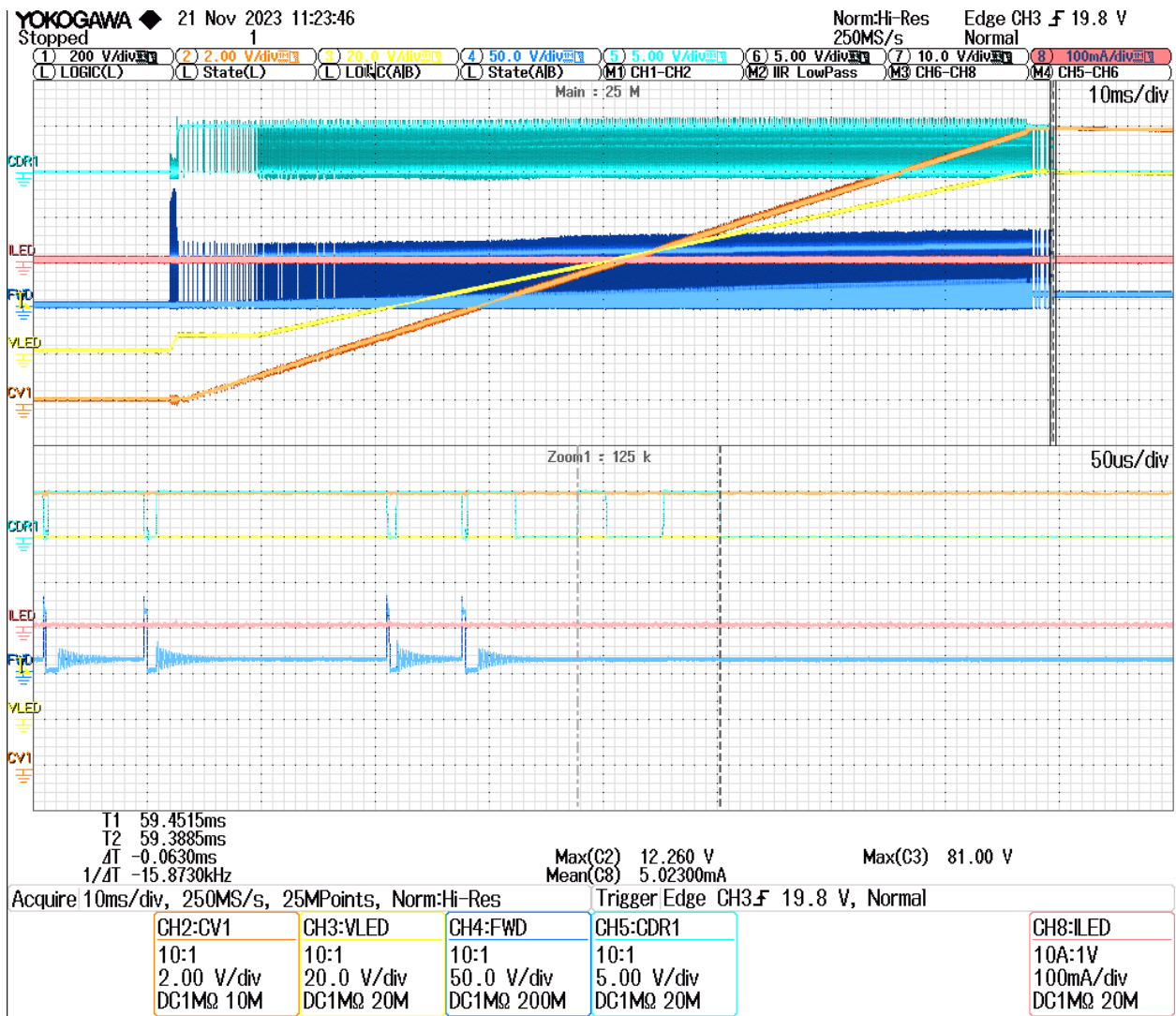


Figure 46 – Start-up With LED Output Shorted to LED Return. Line Input 265 V, CV 0 A, LED = 380 mA.

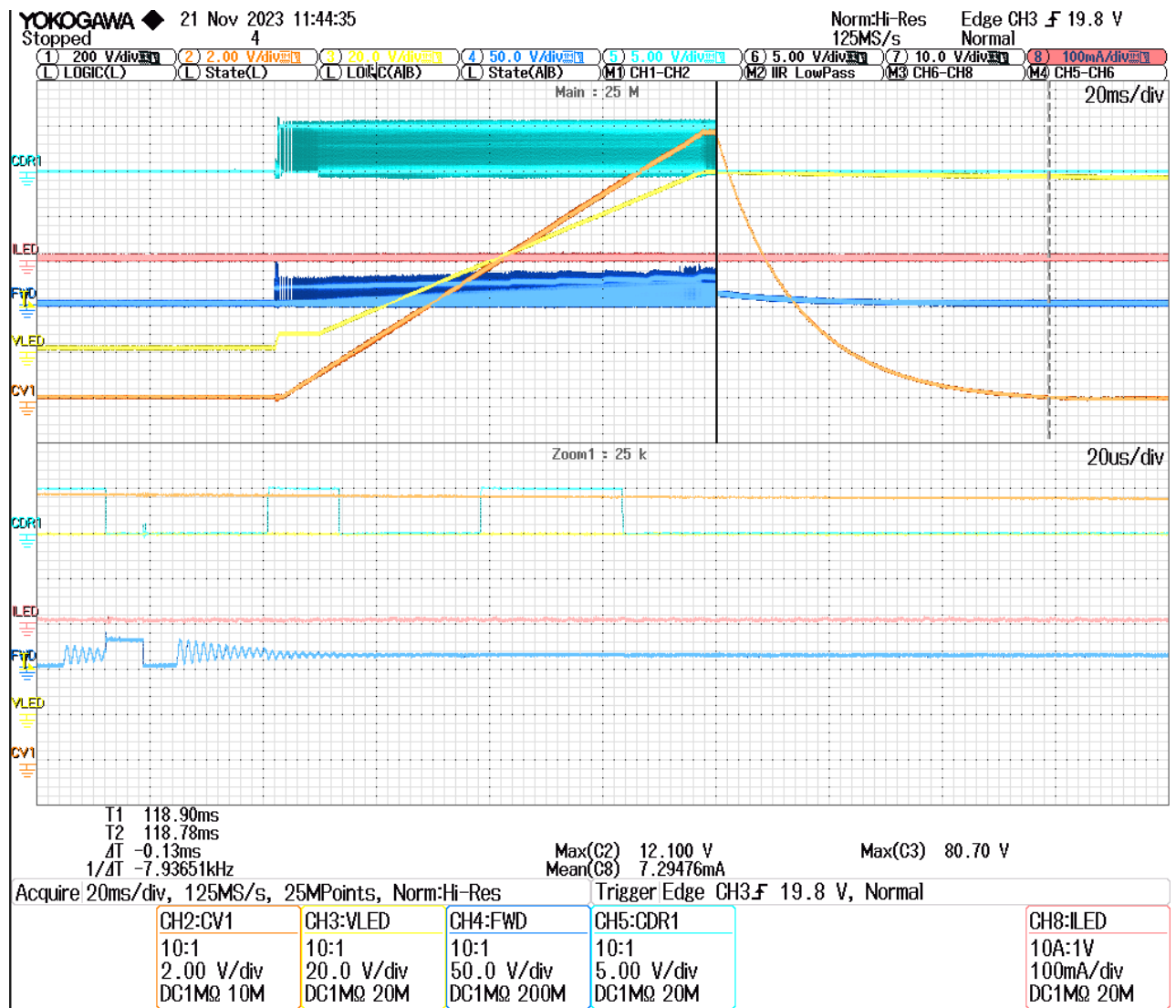


Figure 47 – Start-up With LED Output Shorted to LED Return. Line Input 90 V, CV 2A, LED = 380 mA.

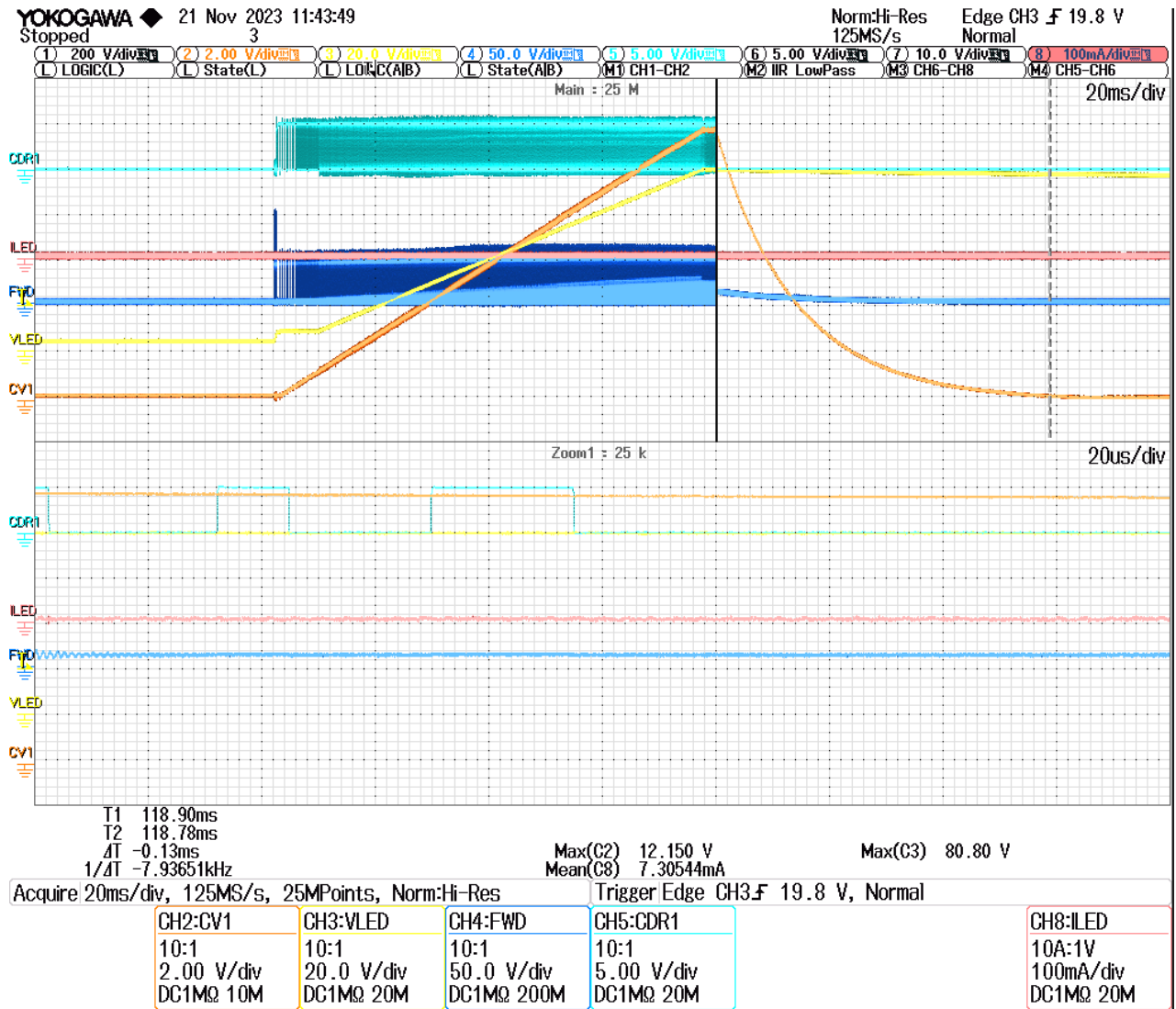


Figure 48 – Start-up With LED Output Shorted to LED Return. Line Input 265 V, CV 2 A, LED = 380 mA.

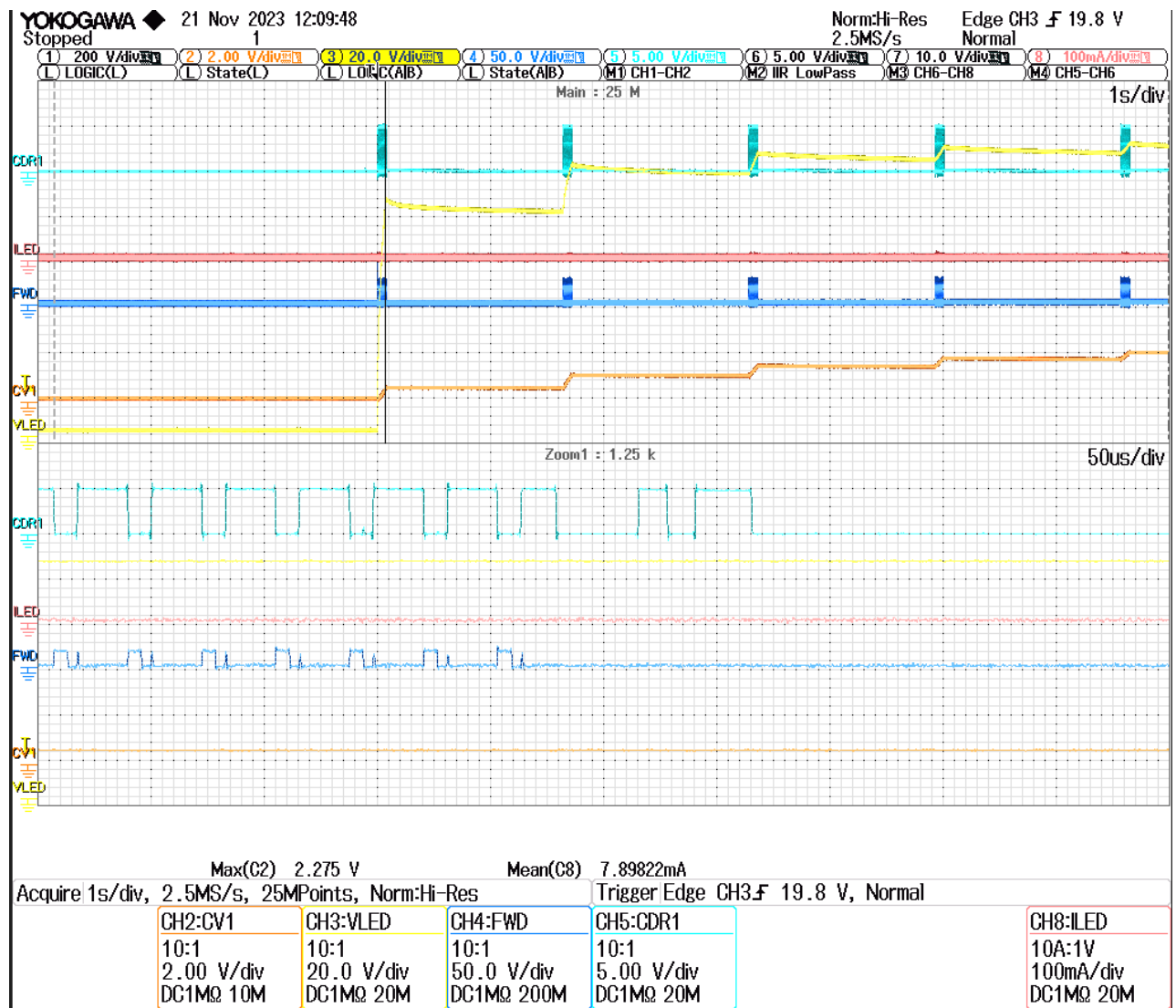


Figure 49 – Start-up With LED FB Open. Line Input 90 V, CV 0 A, LED = 0 mA.

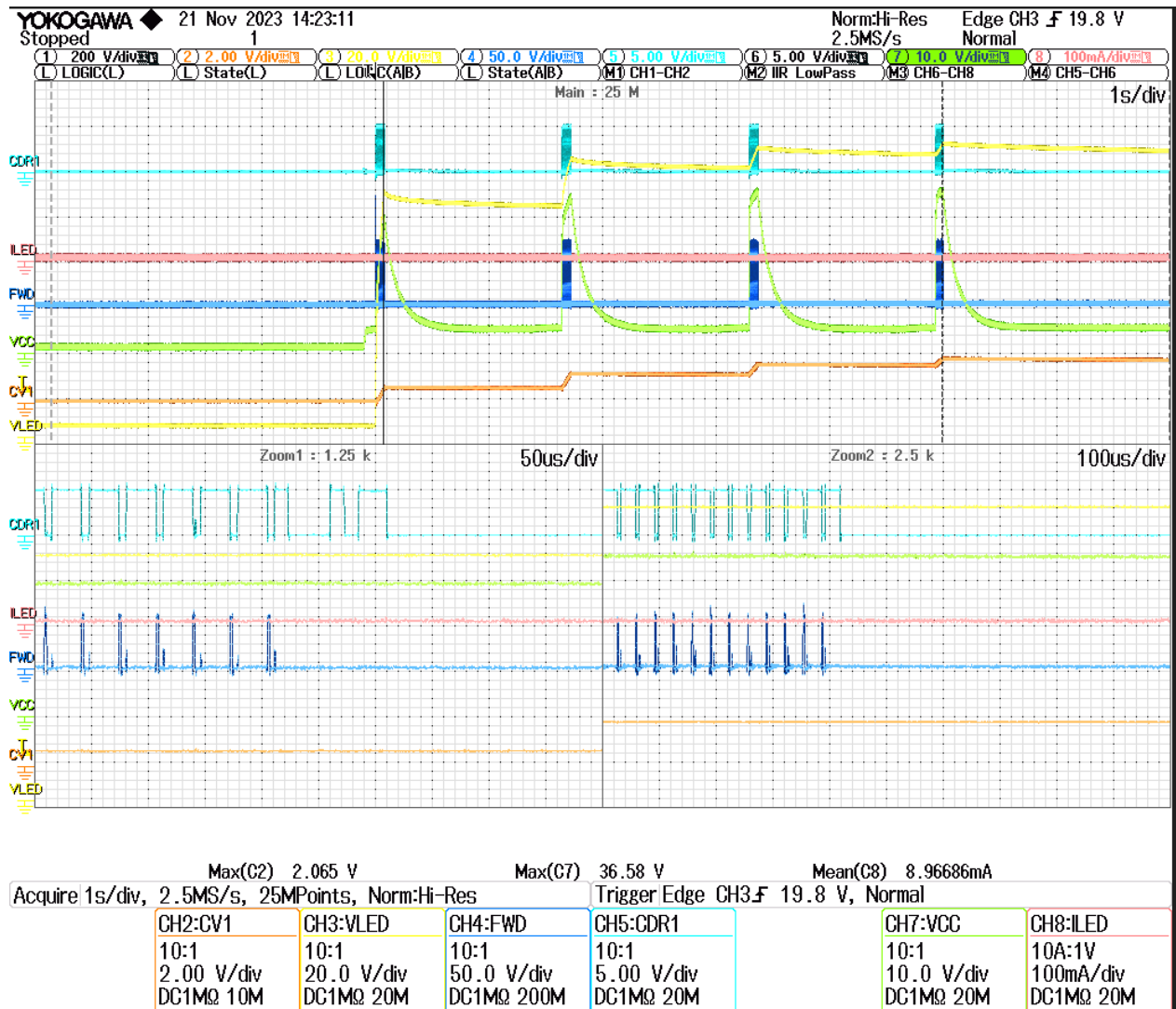


Figure 50 – Start-up With LED FB Open. Line Input 265 V, CV 0 A, LED = 0 mA.

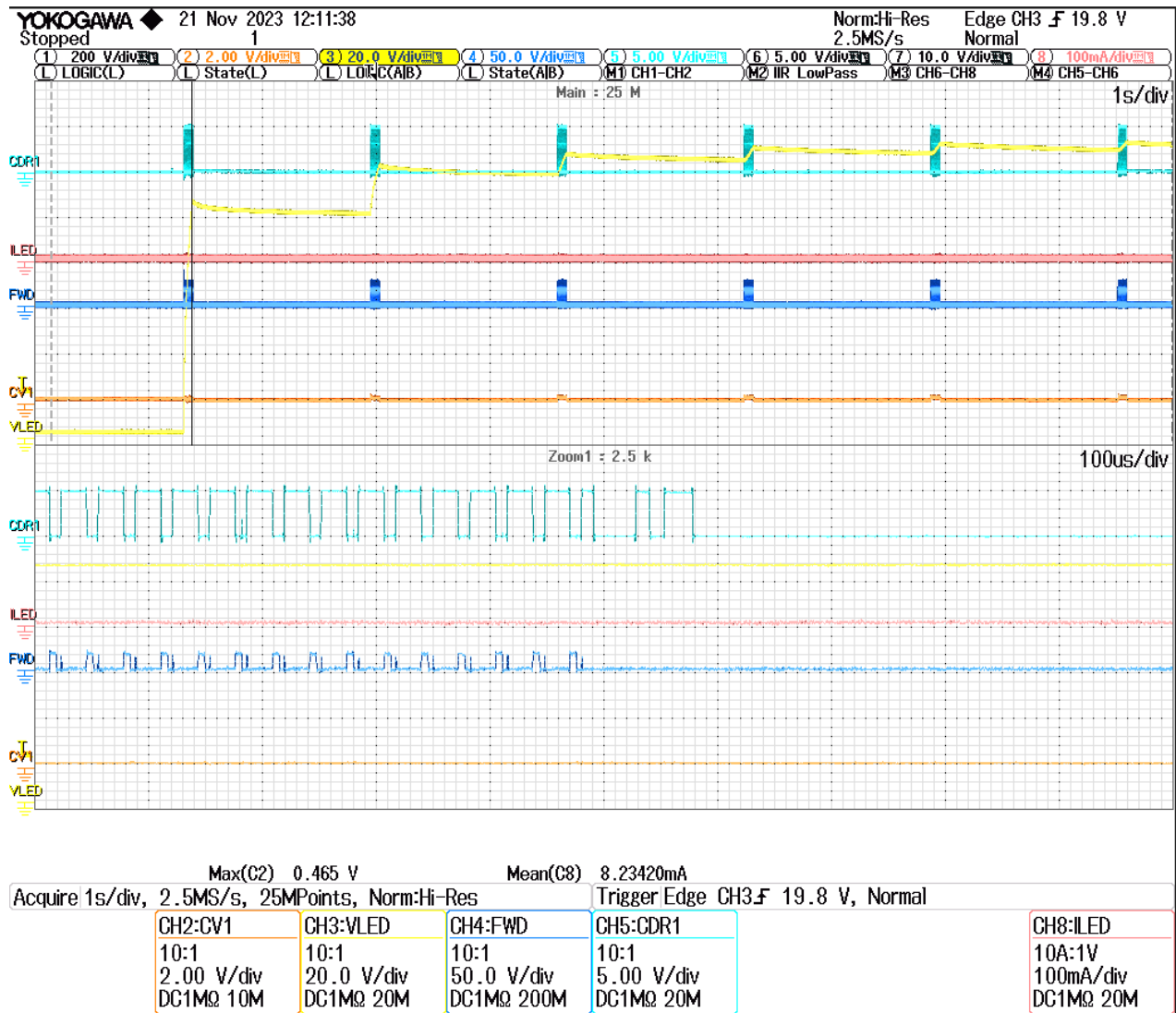


Figure 51 – Start-up With LED FB Open. Line Input 90 V, CV 2 A, LED = 380 mA.

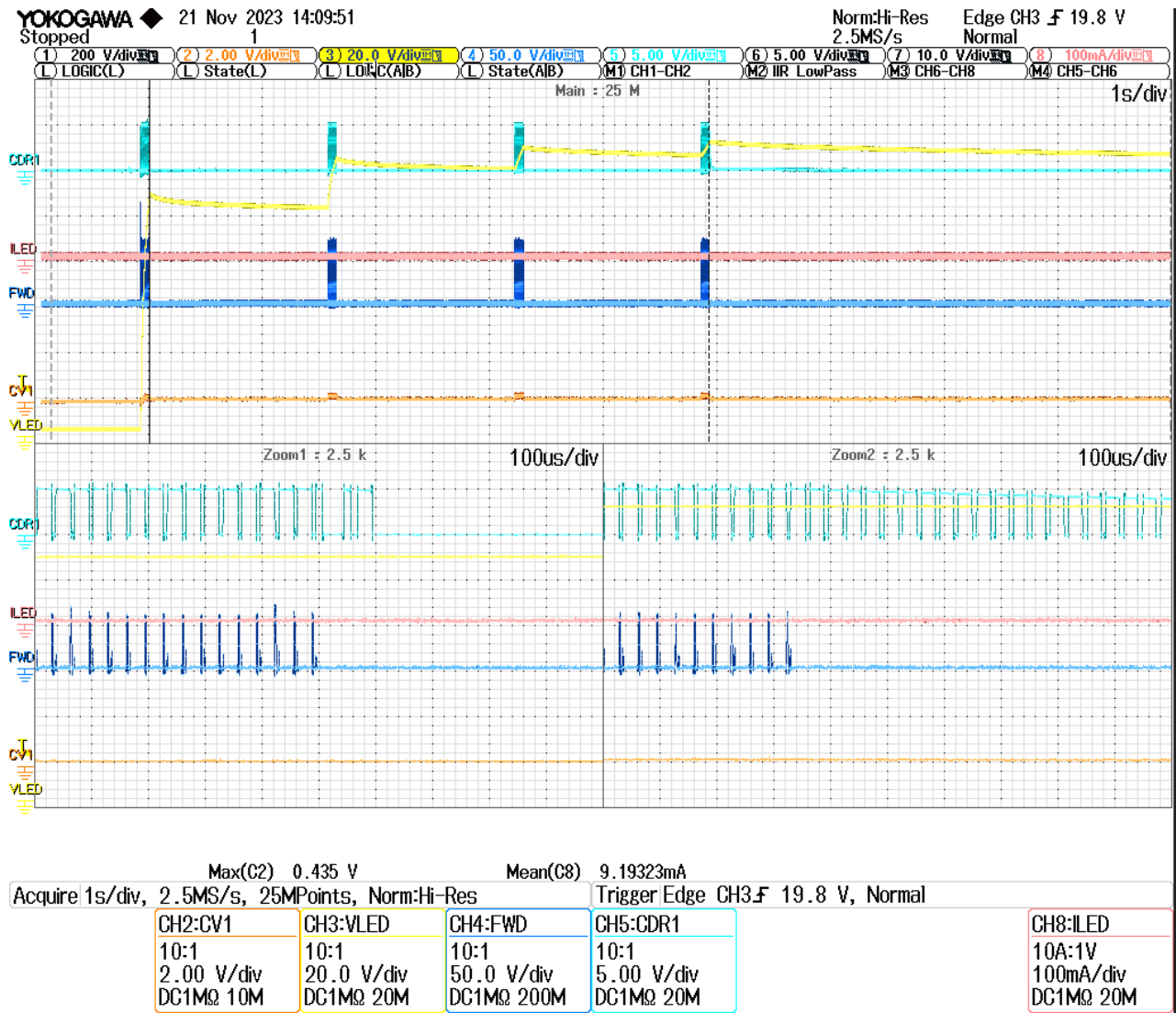


Figure 52 – Start-up With LED FB Open. Line Input 265 V, CV 2 A, LED = 380 mA.

8.19 Component Peak Voltages

8.19.1 SR Diode Reverse Voltage

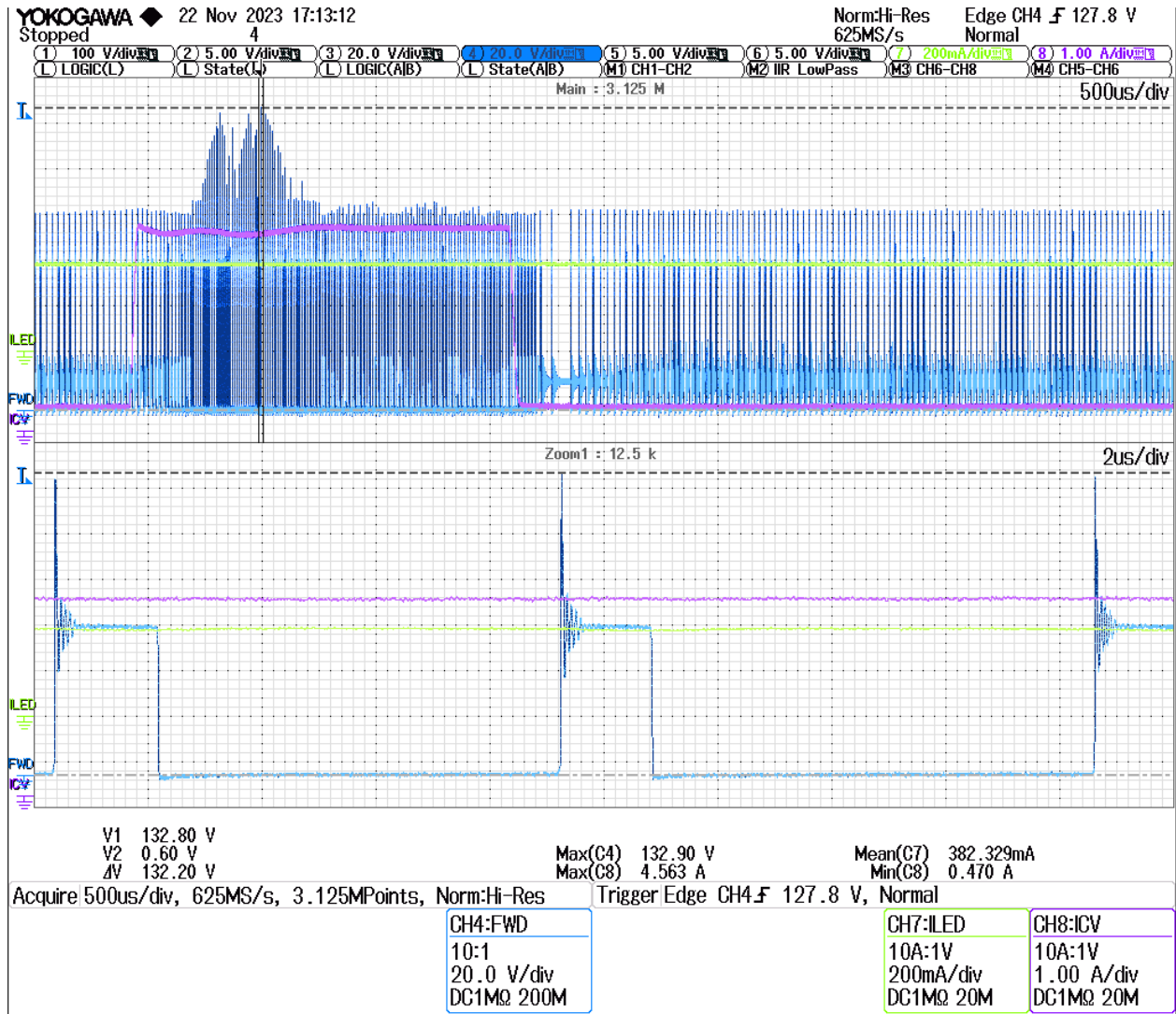


Figure 53 – SR (D8) Reverse Voltage Under Peak Load at 265 VAC.

Ch4: V_{SR}, Ch7: I_{LED}, Ch8: I_{CV}

Maximum reverse voltage across the SR Diode is 133 V.

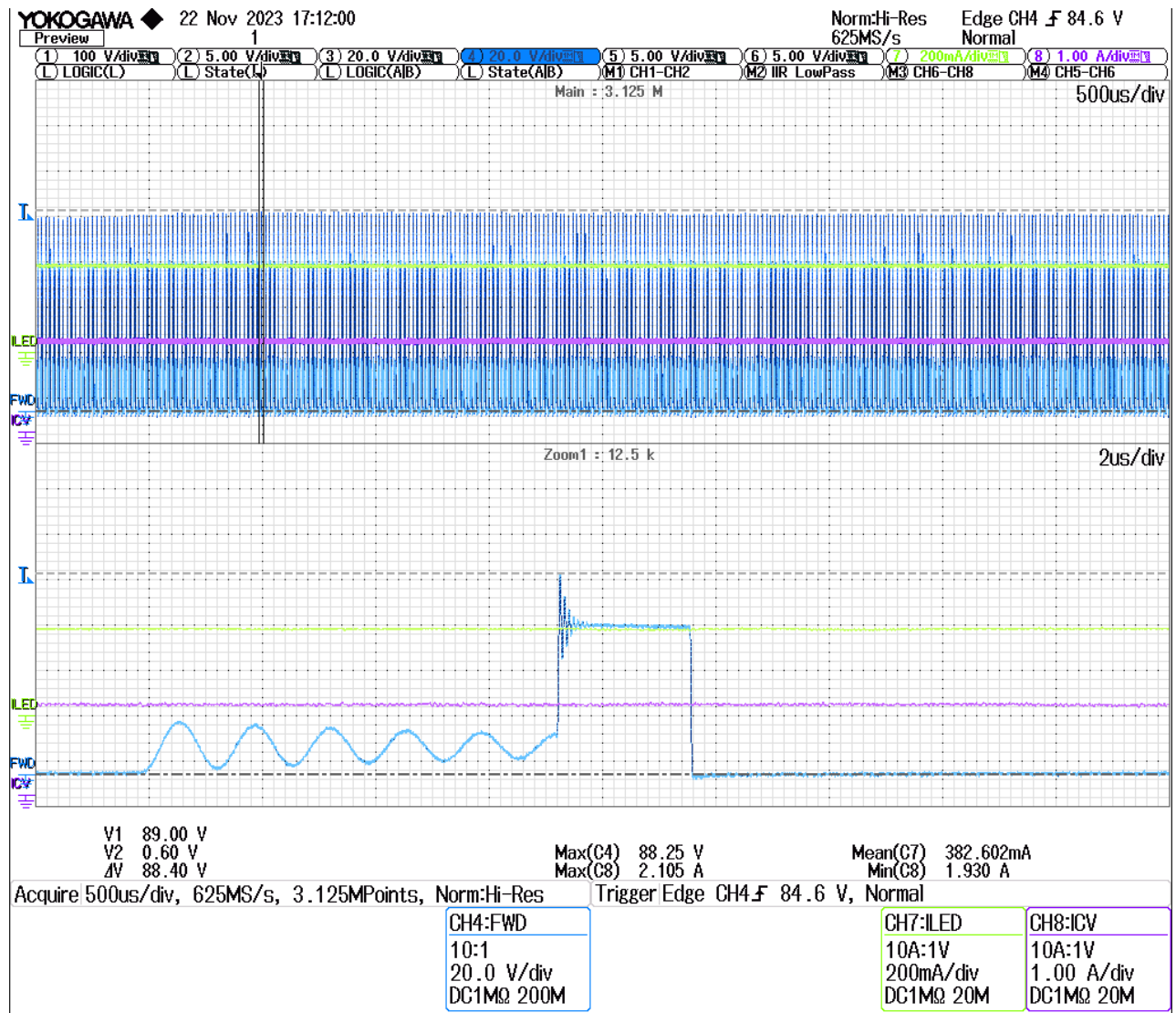


Figure 54 – SR (D8) Reverse Voltage Under Nominal Load at 265 VAC.

Ch4: V_{SR}, Ch7: I_{LED}, Ch8: I_{CV}

Maximum reverse voltage across the SR Diode is 89 V.

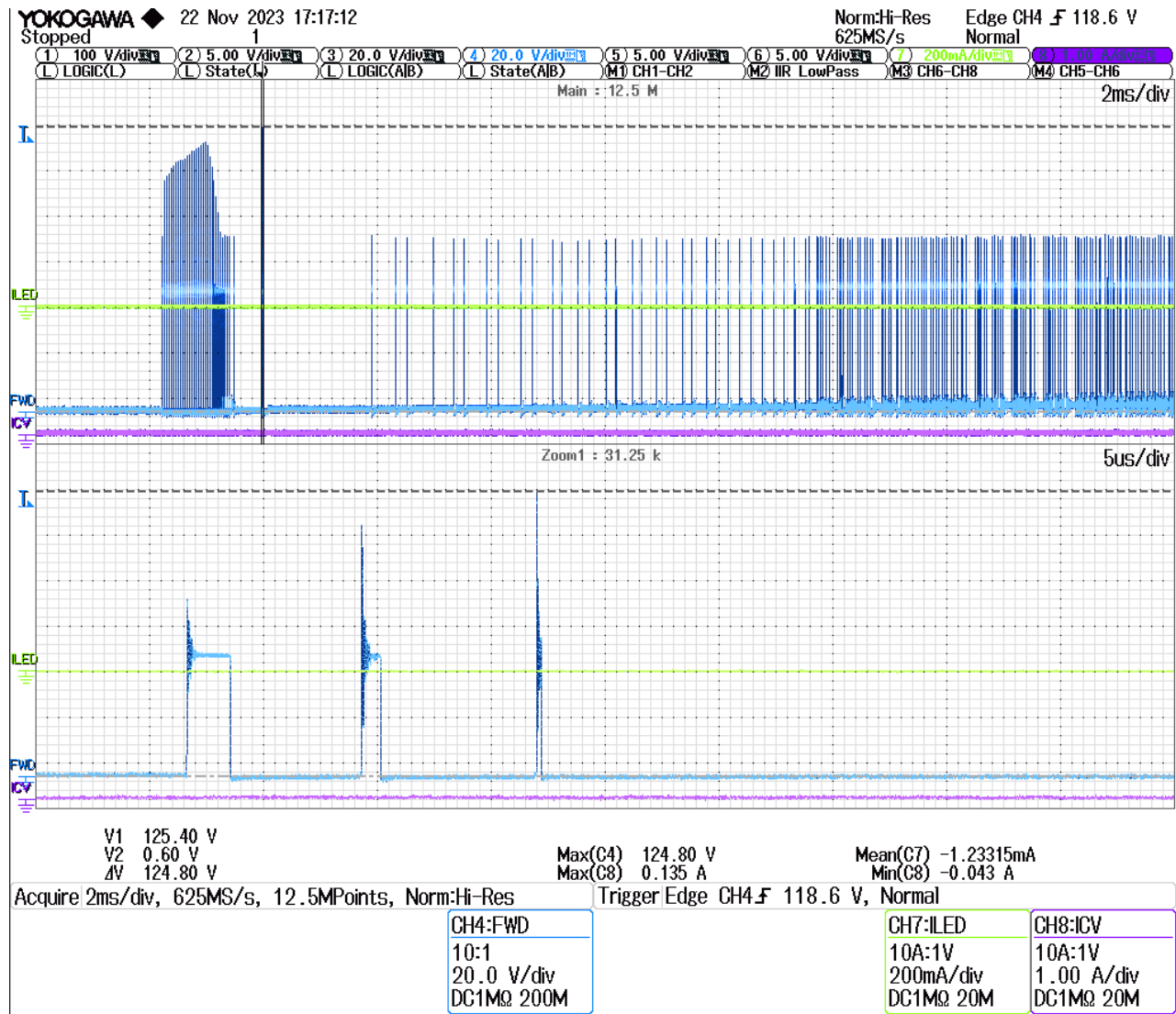


Figure 55 – SR (D8) Reverse Voltage at Start-up at 265 VAC.

Ch4: V_{SR}, Ch7: I_{LED}, Ch8: I_{CV}

Maximum reverse voltage across the SR Diode is 125 V.

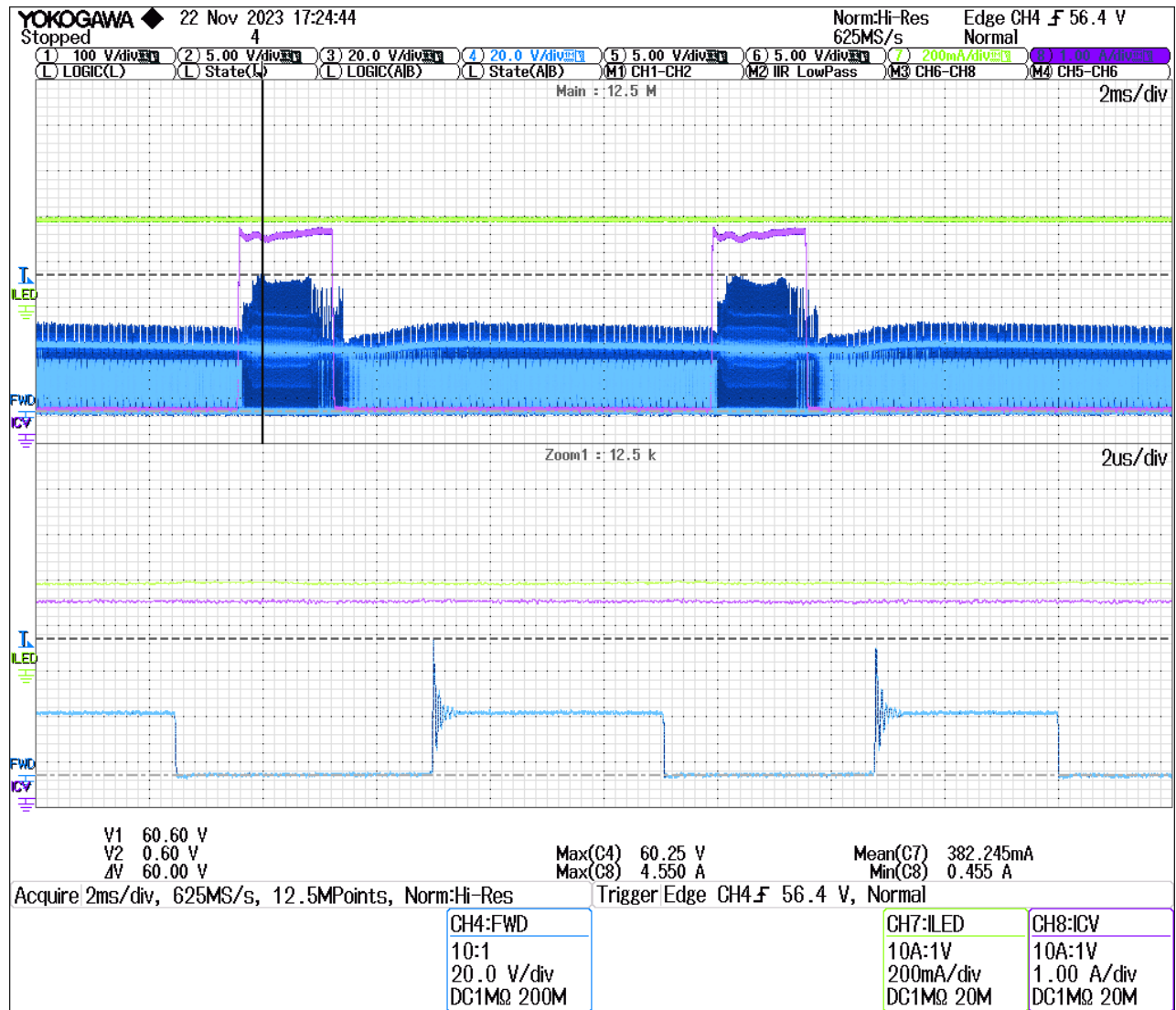


Figure 56 – SR (D8) Reverse Voltage under Peak Load at 90 VAC.

Ch4: V_{SR}, Ch7: I_{LED}, Ch8: I_{CV}

Maximum reverse voltage across the SR Diode is 60 V.

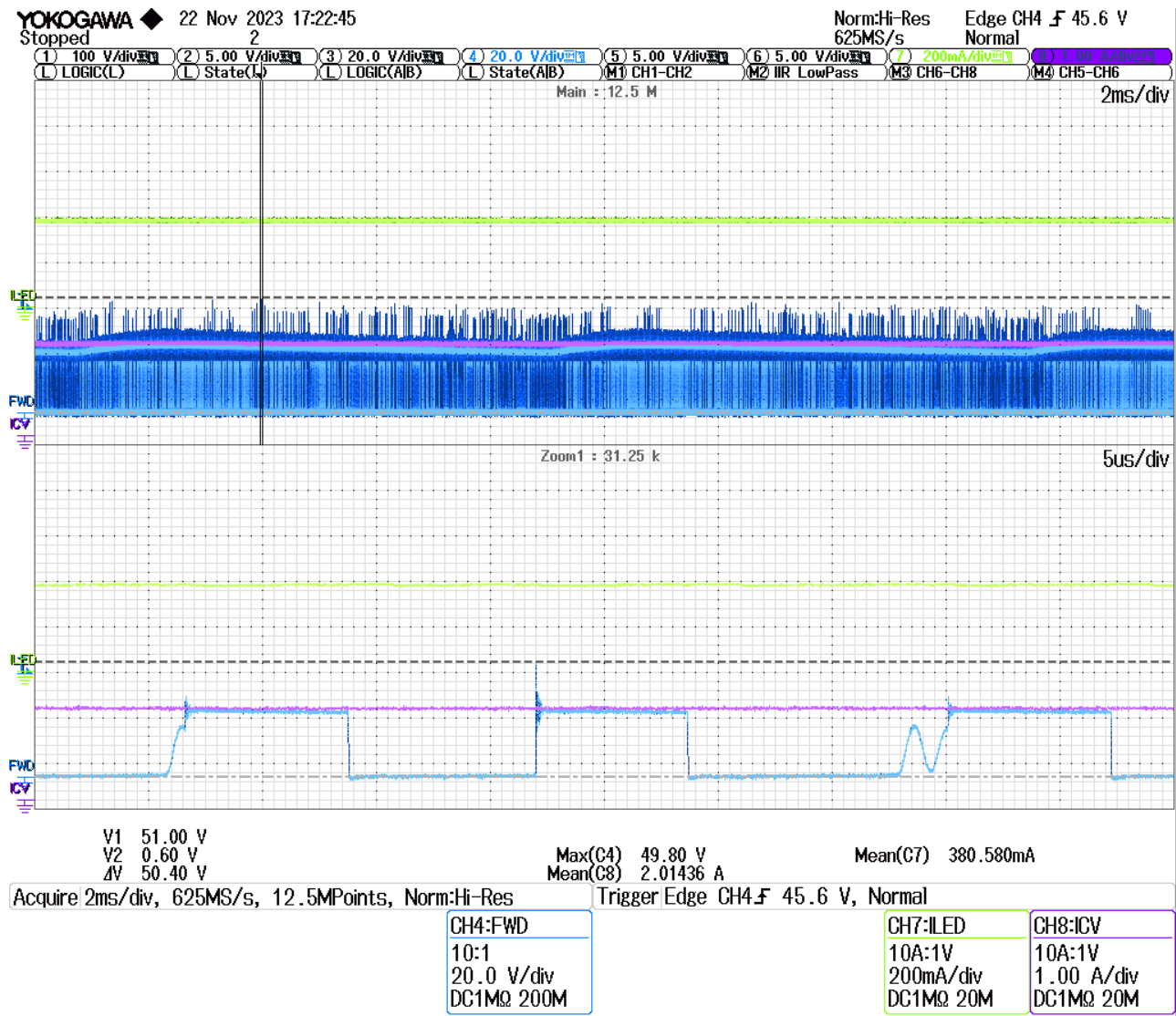


Figure 57 – SR (D8) Reverse Voltage under Nominal Load at 90 VAC.

Ch4: V_{SR}, Ch7: I_{LED}, Ch8: I_{CV}

Maximum reverse voltage across the SR Diode is 50 V.

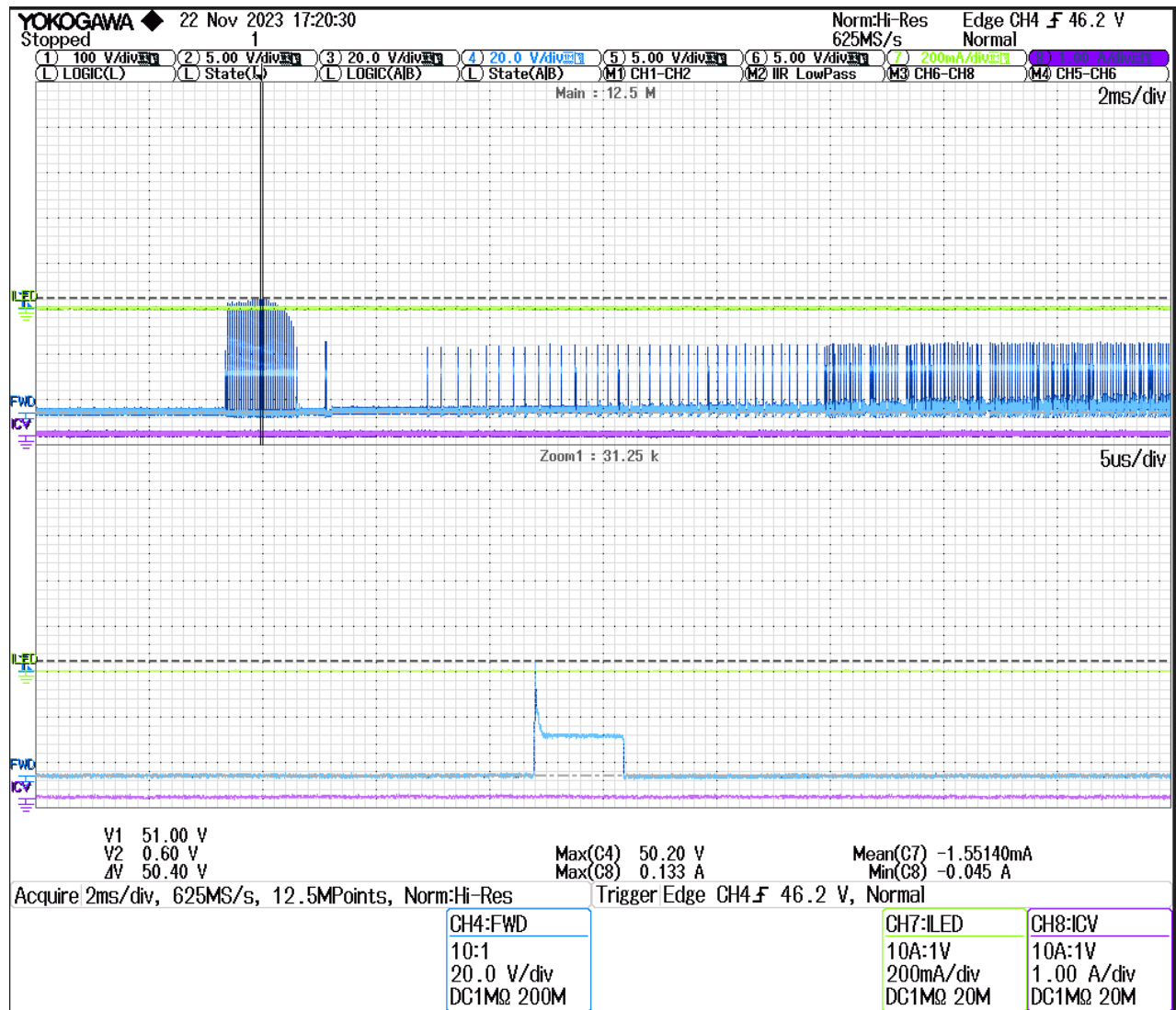


Figure 58 – SR (D8) Reverse Voltage at Start-up at 90 VAC.

Ch4: V_{SR}, Ch7: I_{LED}, Ch8: I_{CV}

Maximum reverse voltage across the SR Diode is 51 V.

8.19.2 CV1 Selection FET Maximum Voltage

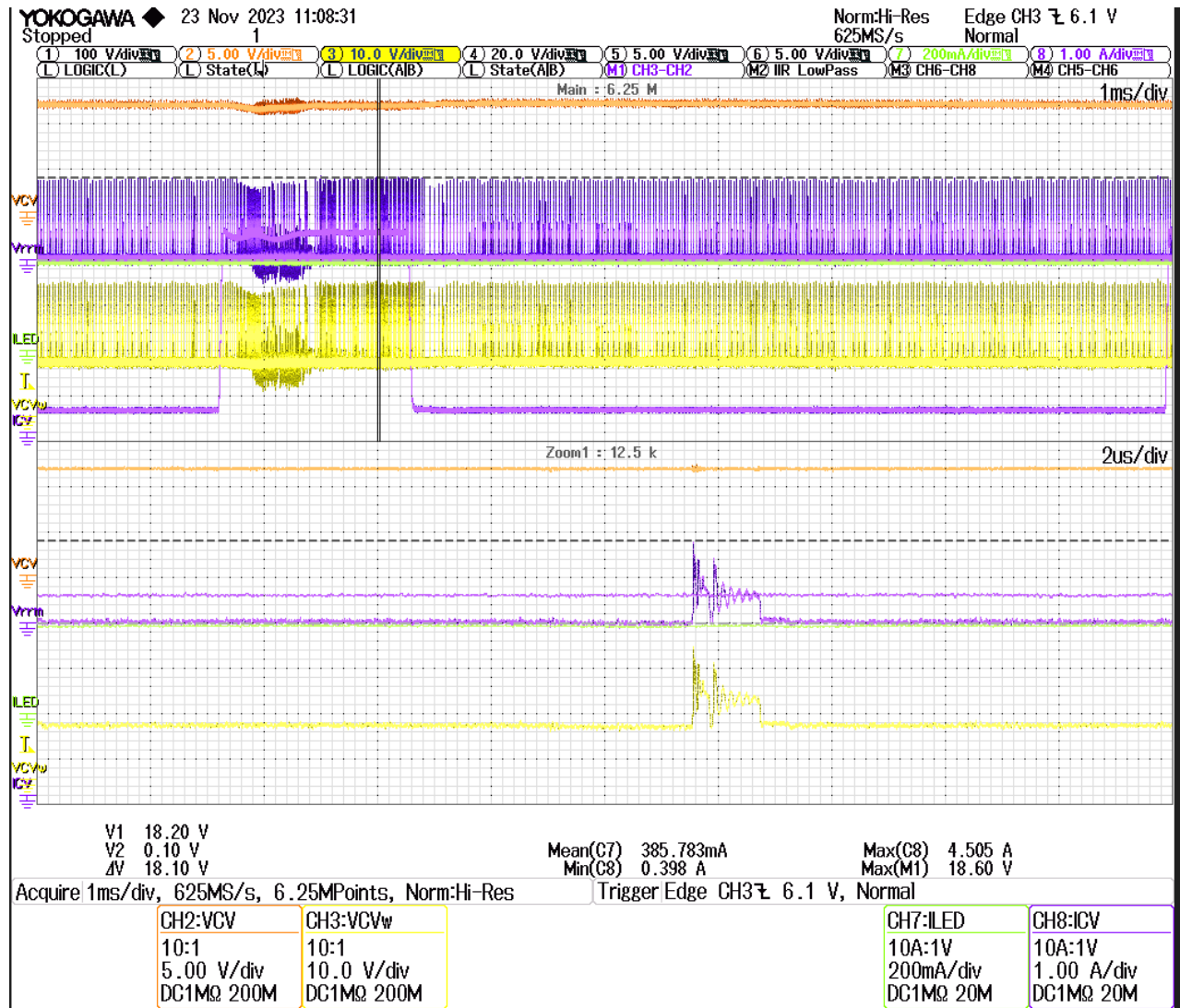


Figure 59 – CV1 Selection FET (Q1) D-S Voltage Under Peak Load at 265 VAC.

Ch2: V_{CV}, Ch3: V_{CVWINDING}, Ch7: I_{LED}, Ch8: I_{CV}

The maximum D-S voltage across the selection FET of CV1 is 18.6 V.

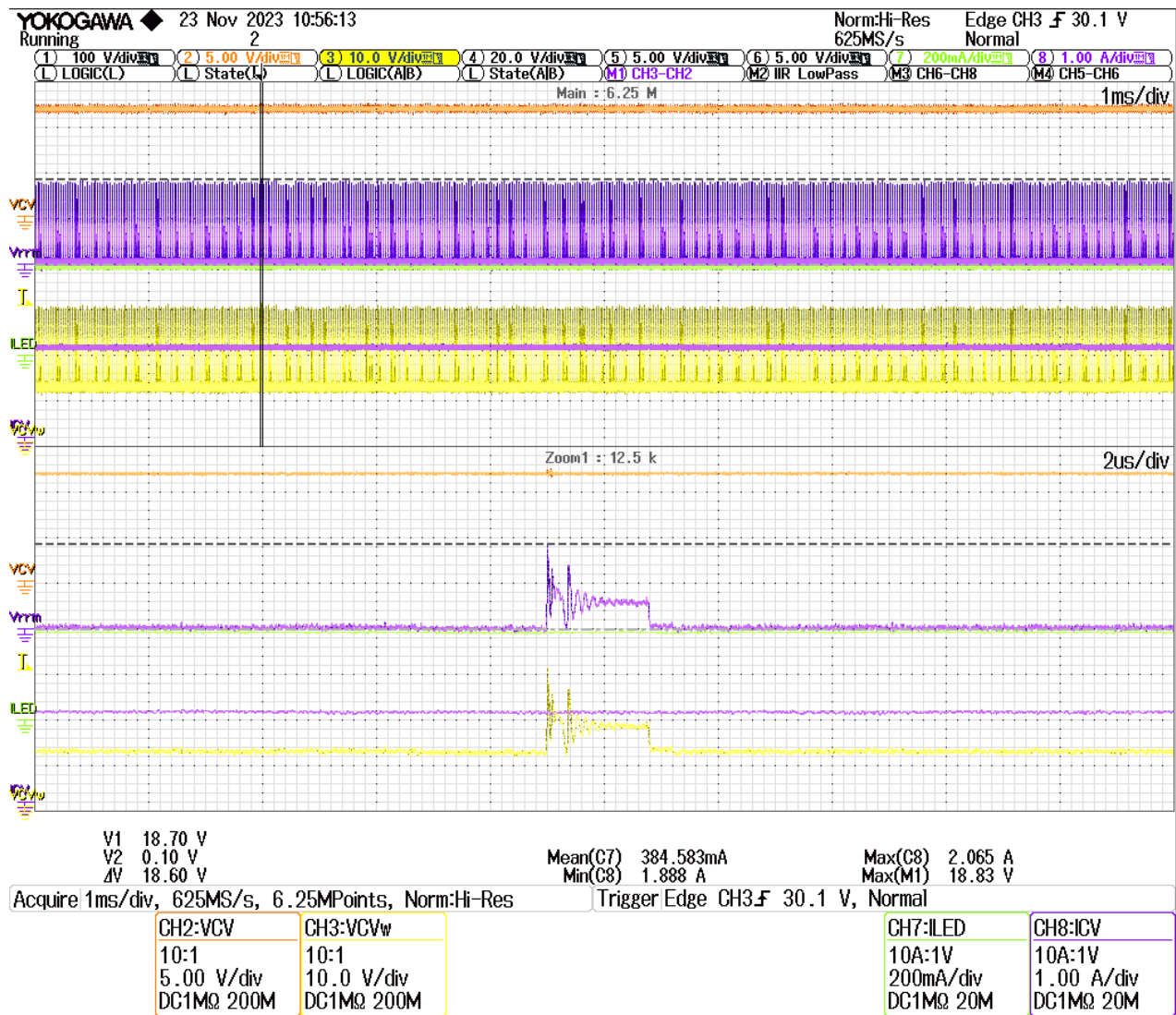


Figure 60 – CV1 Selection FET (Q1) D-S Voltage Under Nominal Load at 265 VAC.

Ch2: V_{CV}, Ch3: V_{CVWINDING}, Ch7: I_{LED}, Ch8: I_{CV}

The maximum D-S voltage across the selection FET of CV1 is 18.9 V.

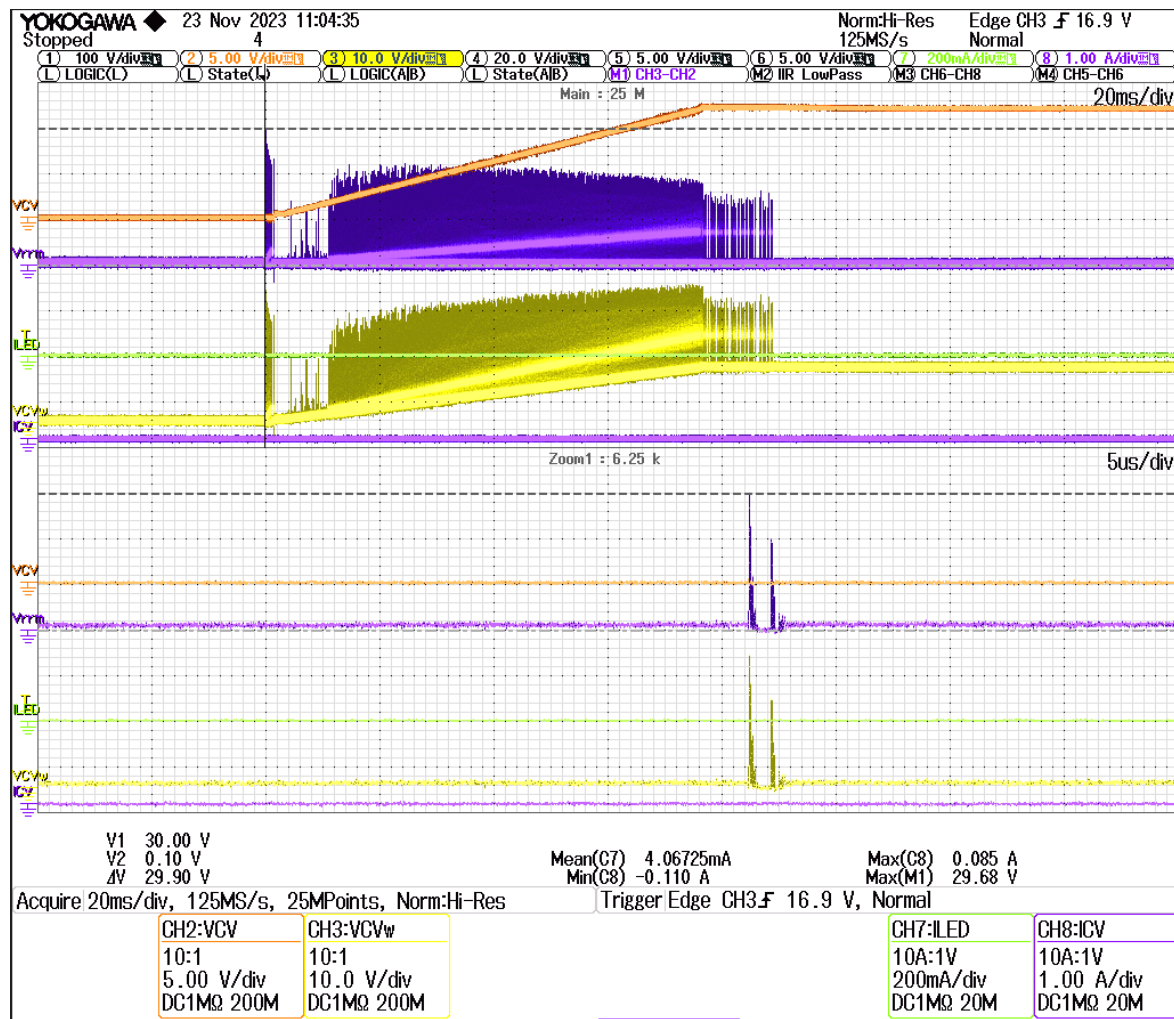


Figure 61 – CV1 Selection FET (Q1) D-S Voltage at Start-up at 265 VAC.

Ch2: V_{CV}, Ch3: V_{CVWINDING}, Ch7: I_{LED}, Ch8: I_{CV}

The maximum D-S voltage across the selection FET of CV1 is 30 V.



Figure 62 – CV1 Selection FET (Q1) D-S Voltage Under Peak Load at 90 VAC.

Ch2: V_{CV}, Ch3: V_{CVWINDING}, Ch7: I_{LED}, Ch8: I_{CV}

The maximum D-S voltage across the selection FET of CV1 is 17.2 V.



Figure 63 – CV1 Selection FET (Q1) D-S Voltage Under Nominal Load at 90 VAC.

Ch2: V_{CV}, Ch3: V_{CVWINDING}, Ch7: I_{LED}, Ch8: I_{CV}

The maximum D-S voltage across the selection FET of CV1 is 17.5 V.

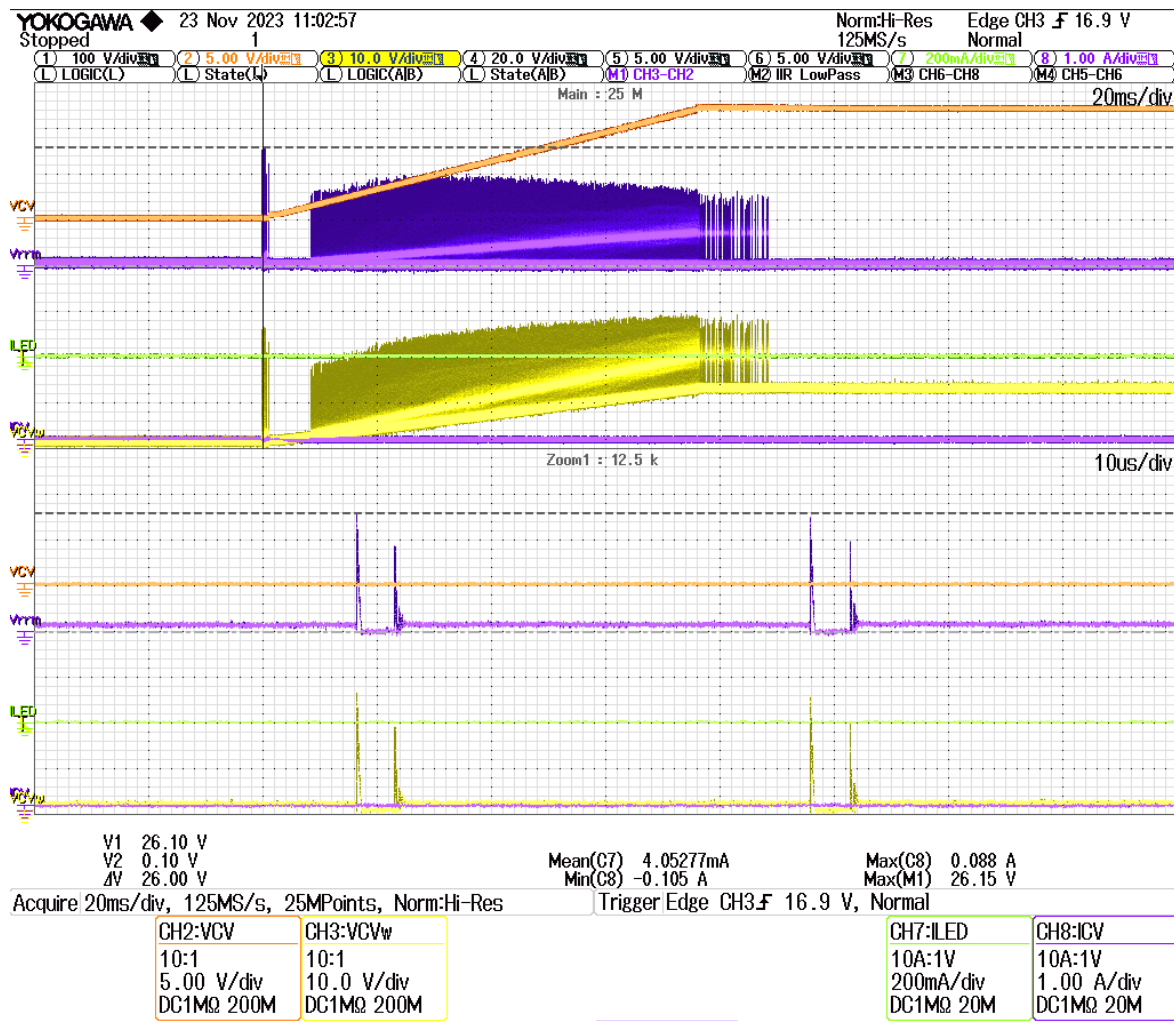


Figure 64 – CV1 Selection FET (Q1) D-S Voltage at Start-up at 90 VAC.

Ch2: V_{CV}, Ch3: V_{CVWINDING}, Ch7: I_{LED}, Ch8: I_{CV}

The maximum D-S voltage across the selection FET of CV1 is 26.2 V.

8.19.3 LED Rectifier Diode Maximum Reverse Voltage

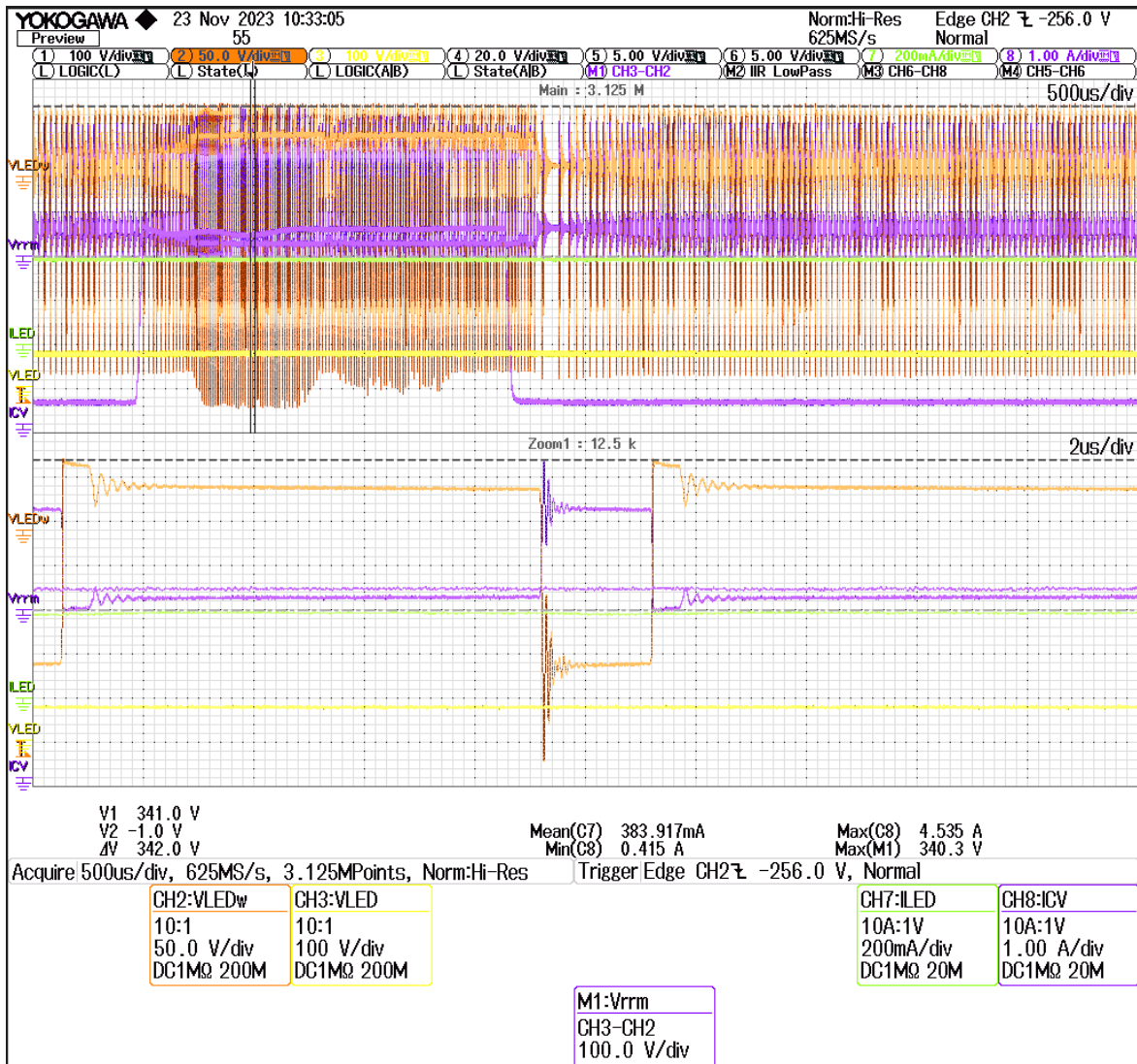


Figure 65 – Reverse Voltage on LED Diode Under Peak Load at 265 VAC.

Ch2: V_{LEDWINDING}, Ch3: V_{LED}, Ch7: I_{LED}, Ch8: I_{CV}, ChM1: V_{RRM}

The worst-case peak reverse voltage across the LED rectifier diode (D3) is 340 V.

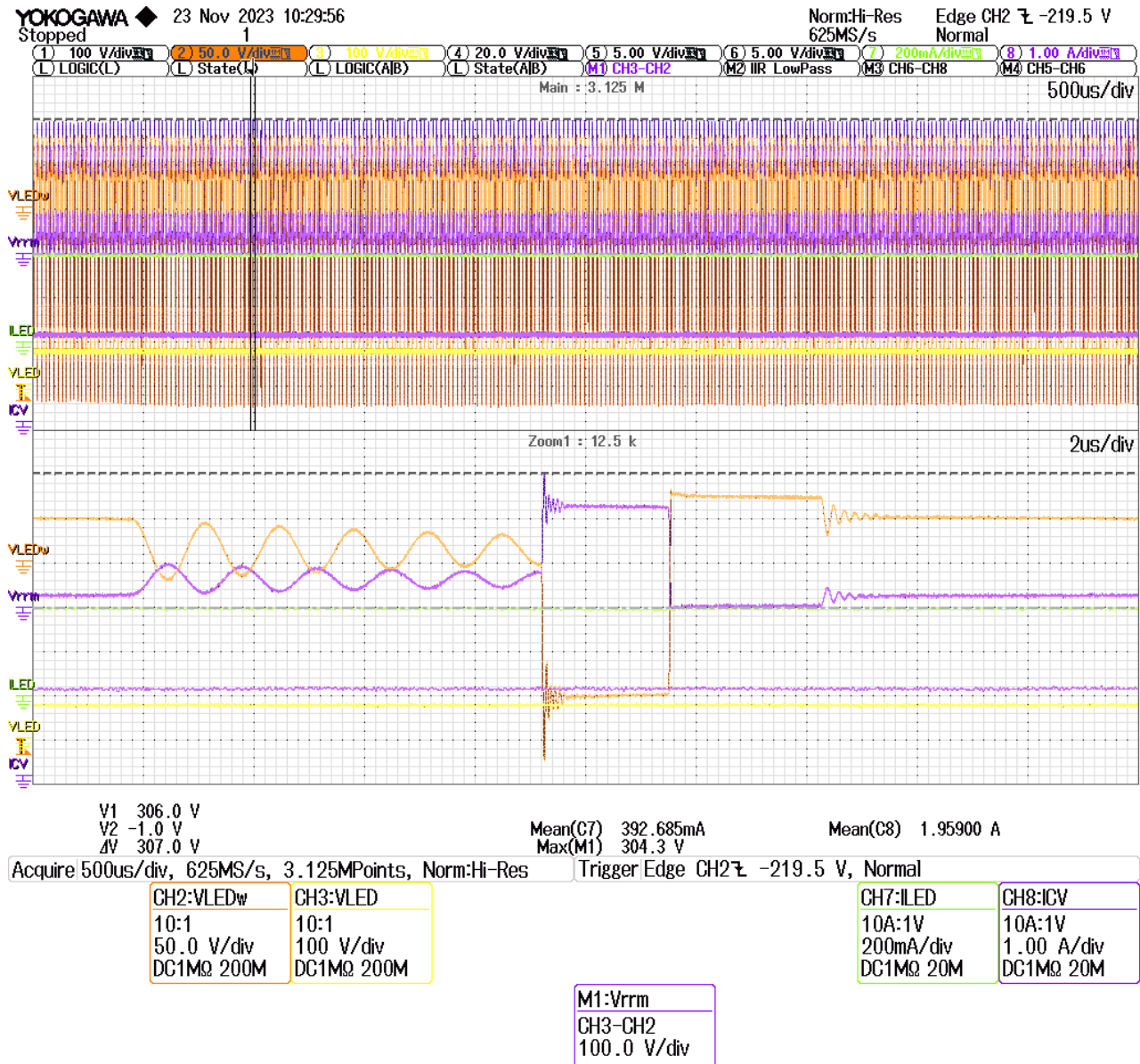


Figure 66 – Reverse Voltage on LED Diode Under Nominal Load at 265 VAC.

Ch2: V_{LEDWINDING}, Ch3: V_{LED}, Ch7: I_{LED}, Ch8: I_{CV}, ChM1: V_{RRM}

The worst-case peak reverse voltage across the LED rectifier diode (D3) is 304 V.

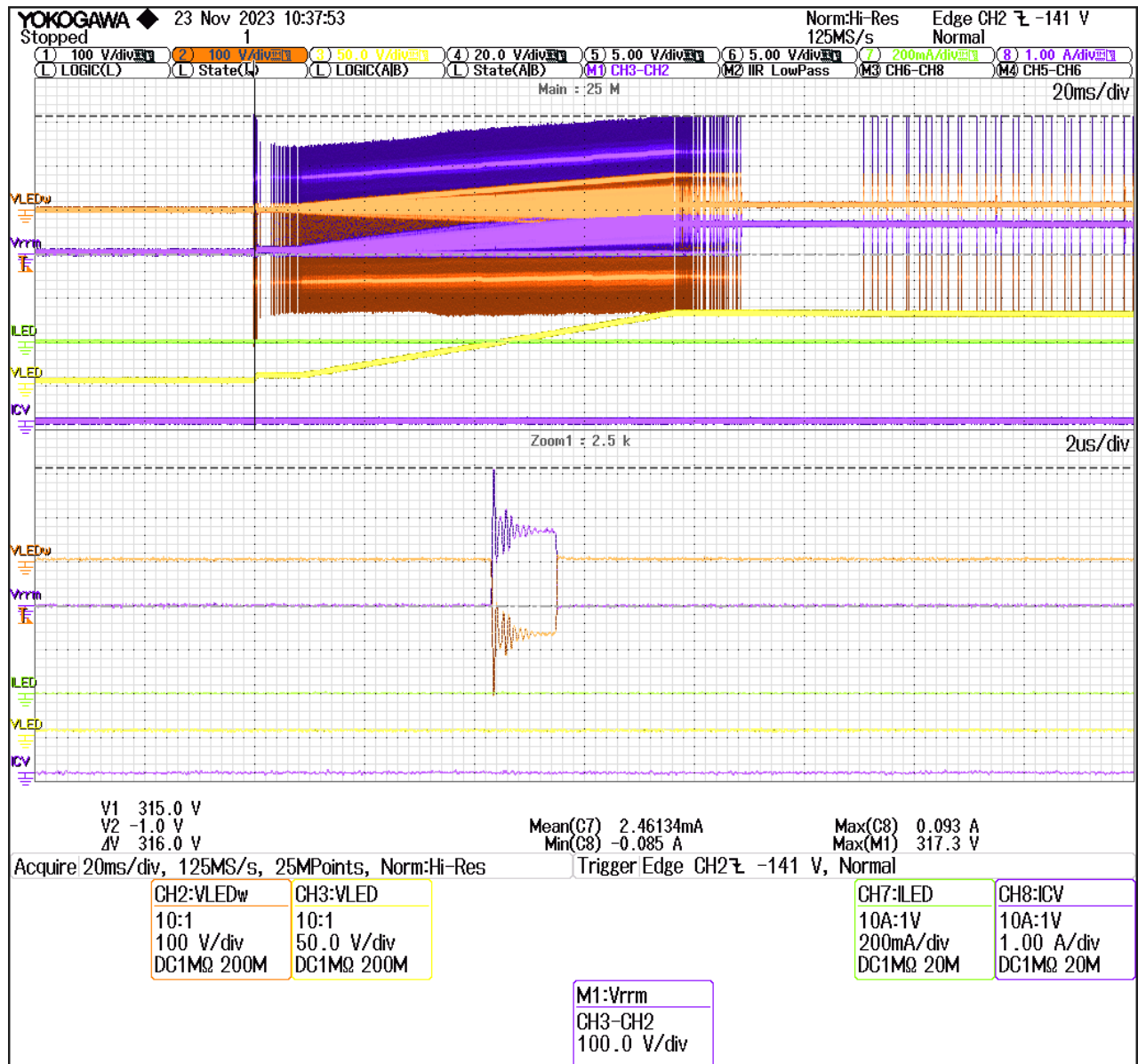


Figure 67 – Reverse Voltage on LED Diode at Start-up at 265 VAC.

Ch2: VLEDWINDING, Ch3: VLED, Ch7: ILED, Ch8: ICV, ChM1: VRRM

The worst-case peak reverse voltage across the LED rectifier diode (D3) is 317 V.

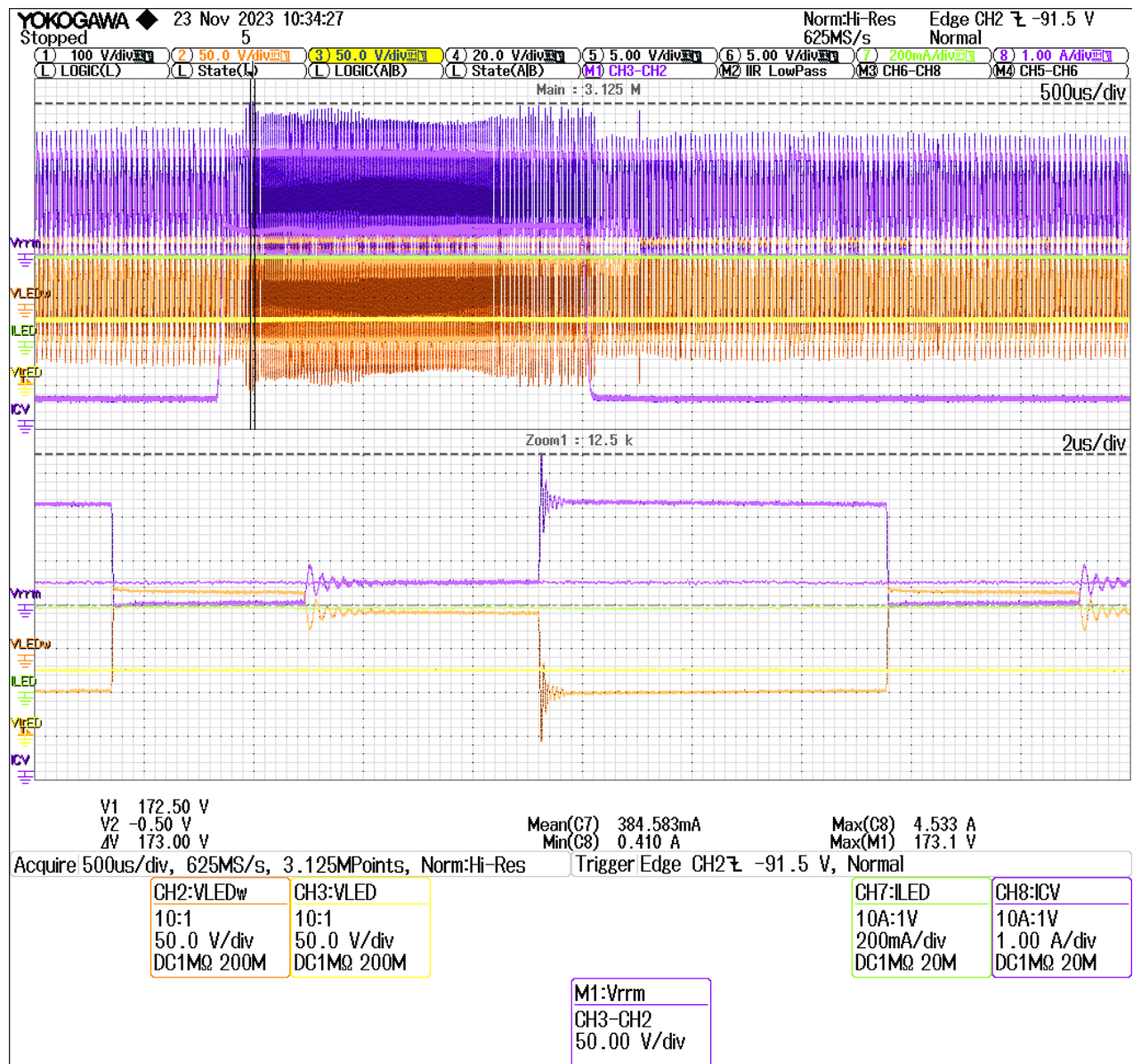


Figure 68 – Reverse Voltage on LED Diode Under Peak Load at 90 VAC.

Ch2: V_{LEDWINDING}, Ch3: V_{LED}, Ch7: I_{LED}, Ch8: I_{CV}, ChM1: V_{RRM}

The worst-case peak reverse voltage across the LED rectifier diode (D3) is 173 V.

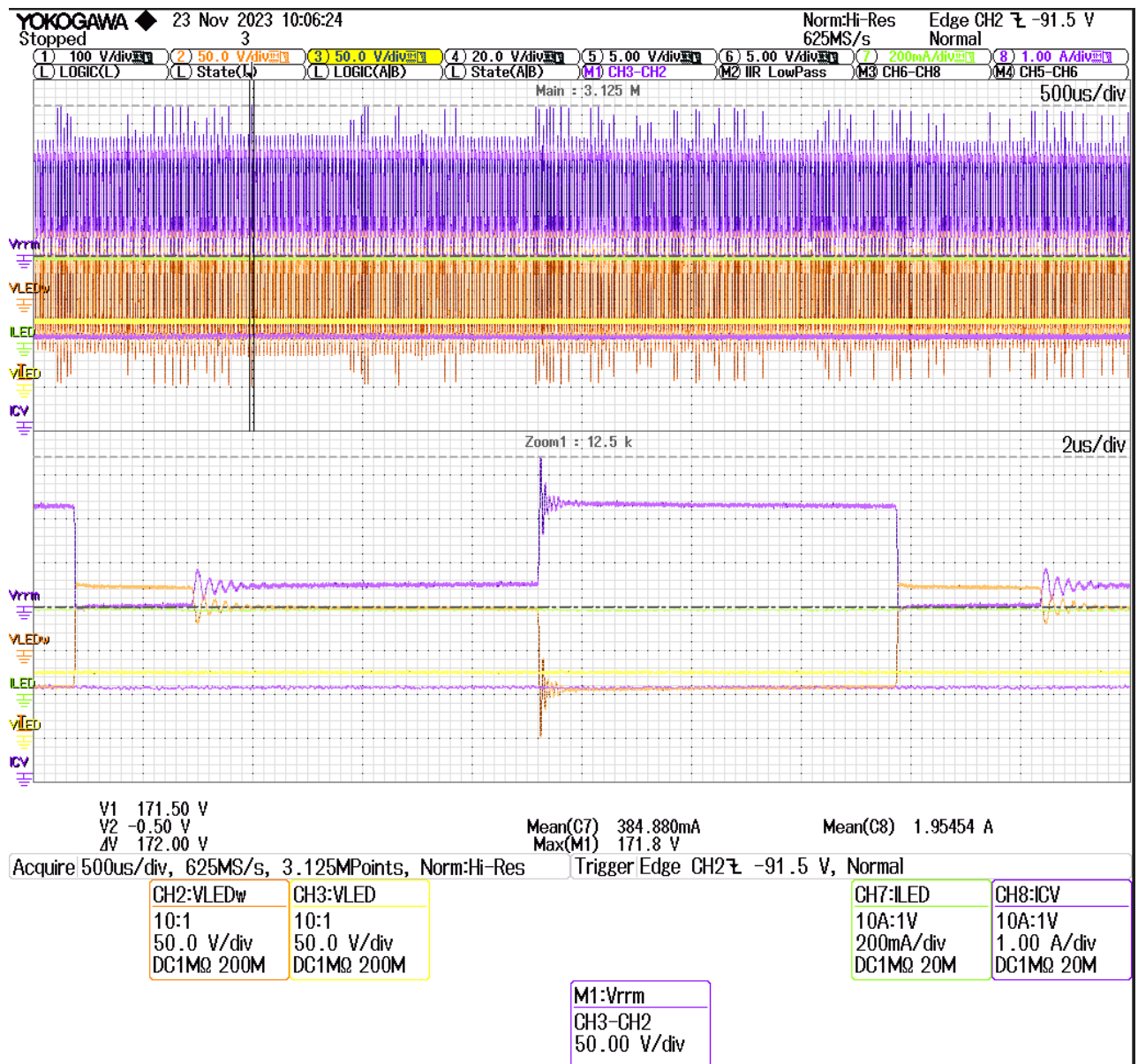


Figure 69 – Reverse Voltage on LED Diode Under Nominal Load at 90 VAC.

Ch2: V_{LEDWINDING}, Ch3: V_{LED}, Ch7: I_{LED}, Ch8: I_{CV}, ChM1: V_{RRM}

The worst-case peak reverse voltage across the LED rectifier diode (D3) is 171 V.

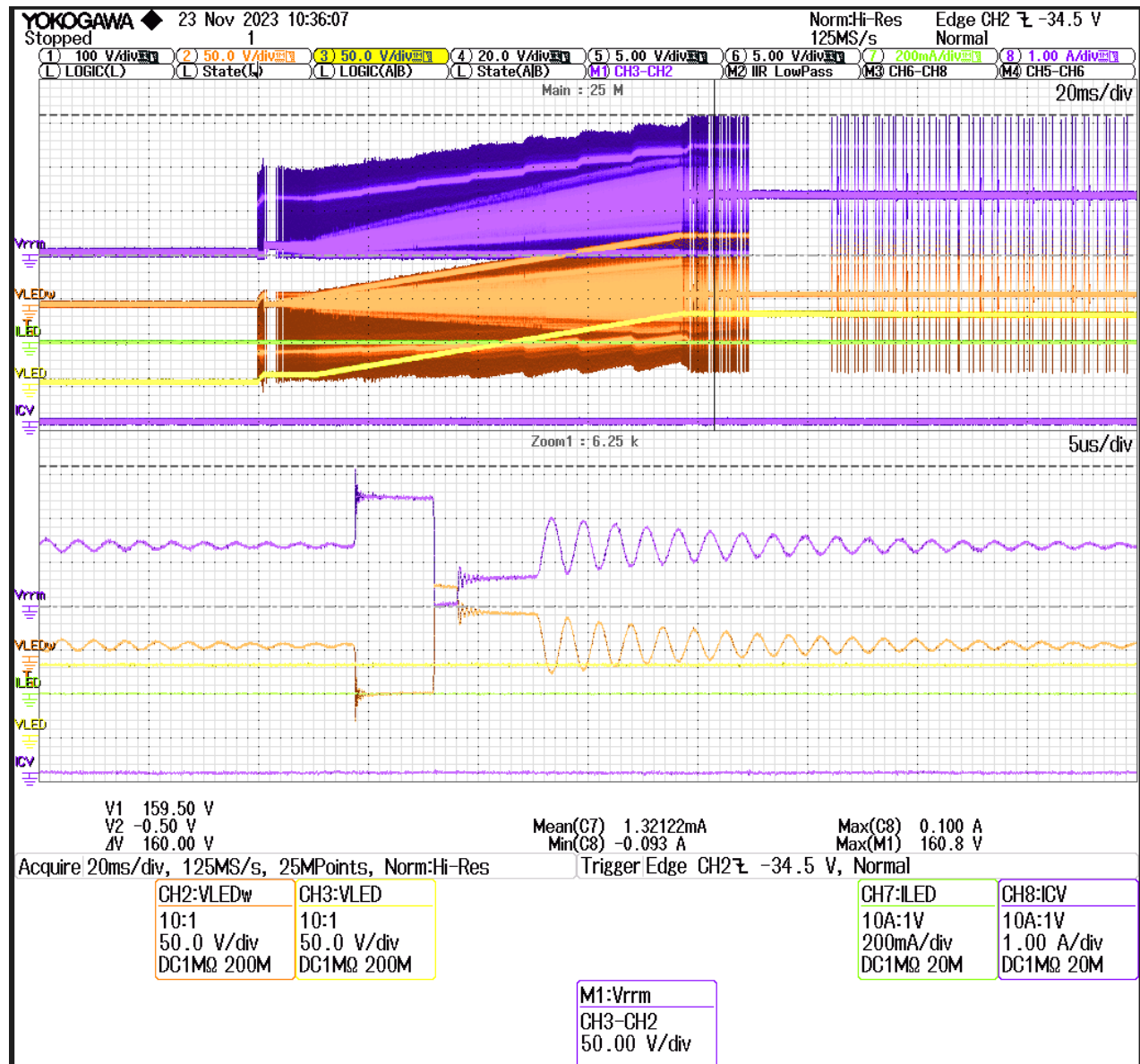


Figure 70 – Reverse Voltage on LED Diode at Start-up at 90 VAC.

Ch2: V_{LEDWINDING}, Ch3: V_{LED}, Ch7: I_{LED}, Ch8: I_{CV}, ChM1: V_{RRM}

The worst-case peak reverse voltage across the LED rectifier diode (D3) is 161 V.

8.19.4 BPP Rectifier Diode Reverse Voltage

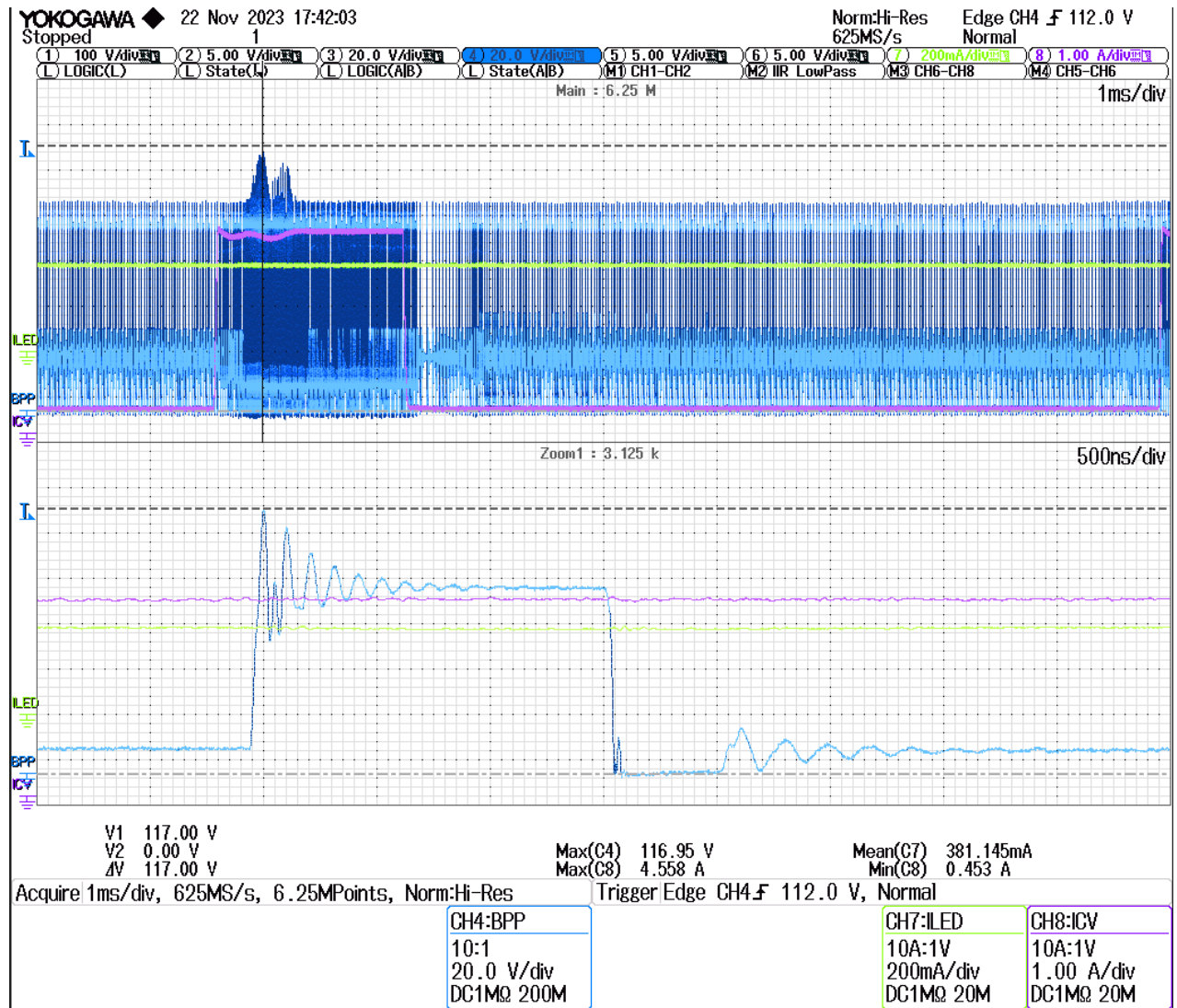


Figure 71 – Auxiliary Diode Reverse Voltage Under Peak Load at 265 VAC.

Ch4: V_{BPPWINDNG}, Ch7: I_{LED}, Ch8: I_{CV}

Maximum reverse voltage across the Auxiliary winding diode is 117 V.

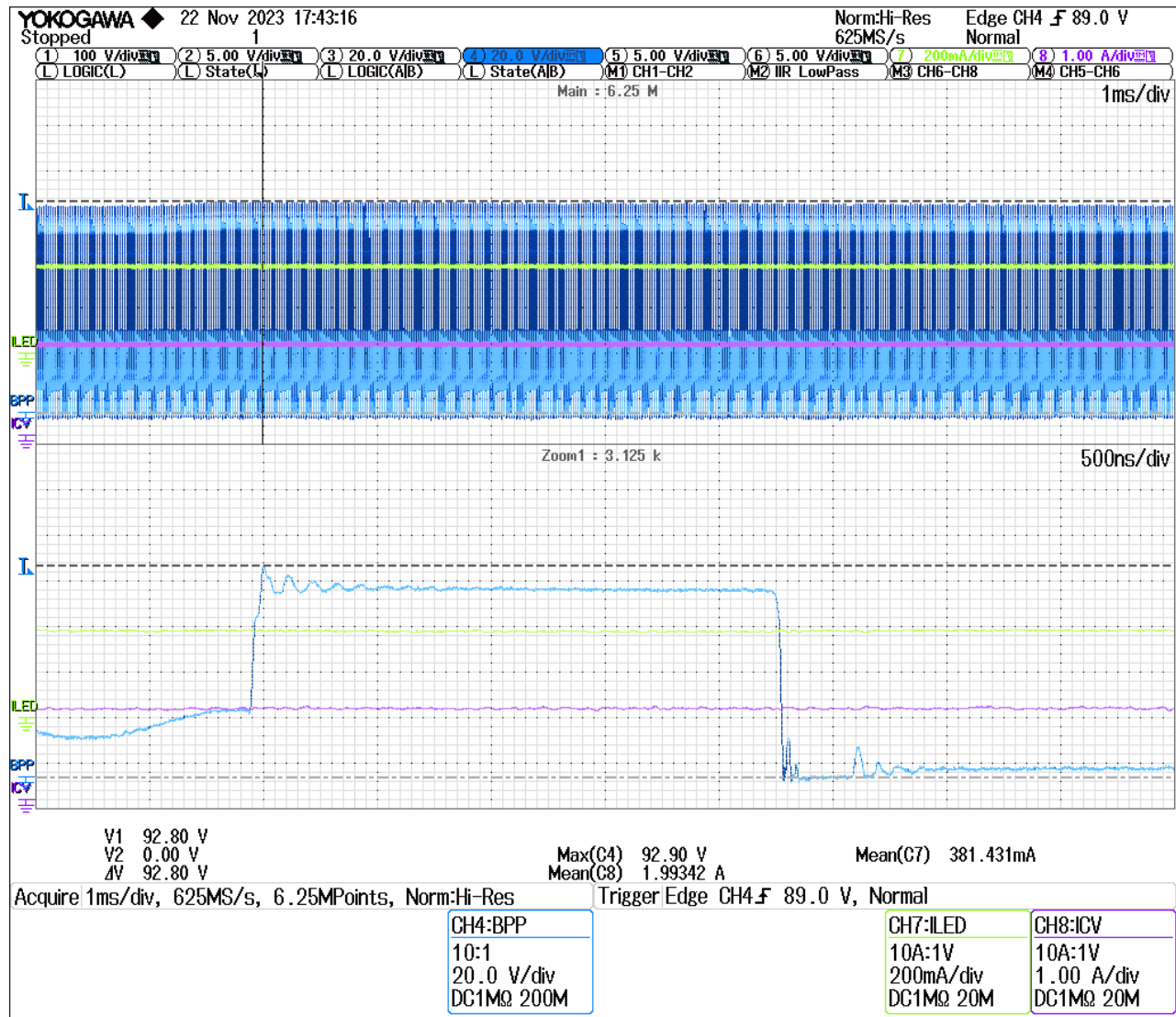


Figure 72 – Auxiliary Diode Reverse Voltage Under Nominal Load at 265 VAC.

Ch4: V_{BPPWNDNG}, Ch7: I_{LED}, Ch8: I_{CV}

Maximum reverse voltage across the auxiliary winding diode is 93 V.



Figure 73 – Auxiliary Diode Reverse Voltage at Start-up at 265 VAC.

Ch4: V_{BPPWINDNG}, Ch7: I_{LED}, Ch8: I_{CV}

Maximum reverse voltage across the Auxiliary winding diode is 123 V.

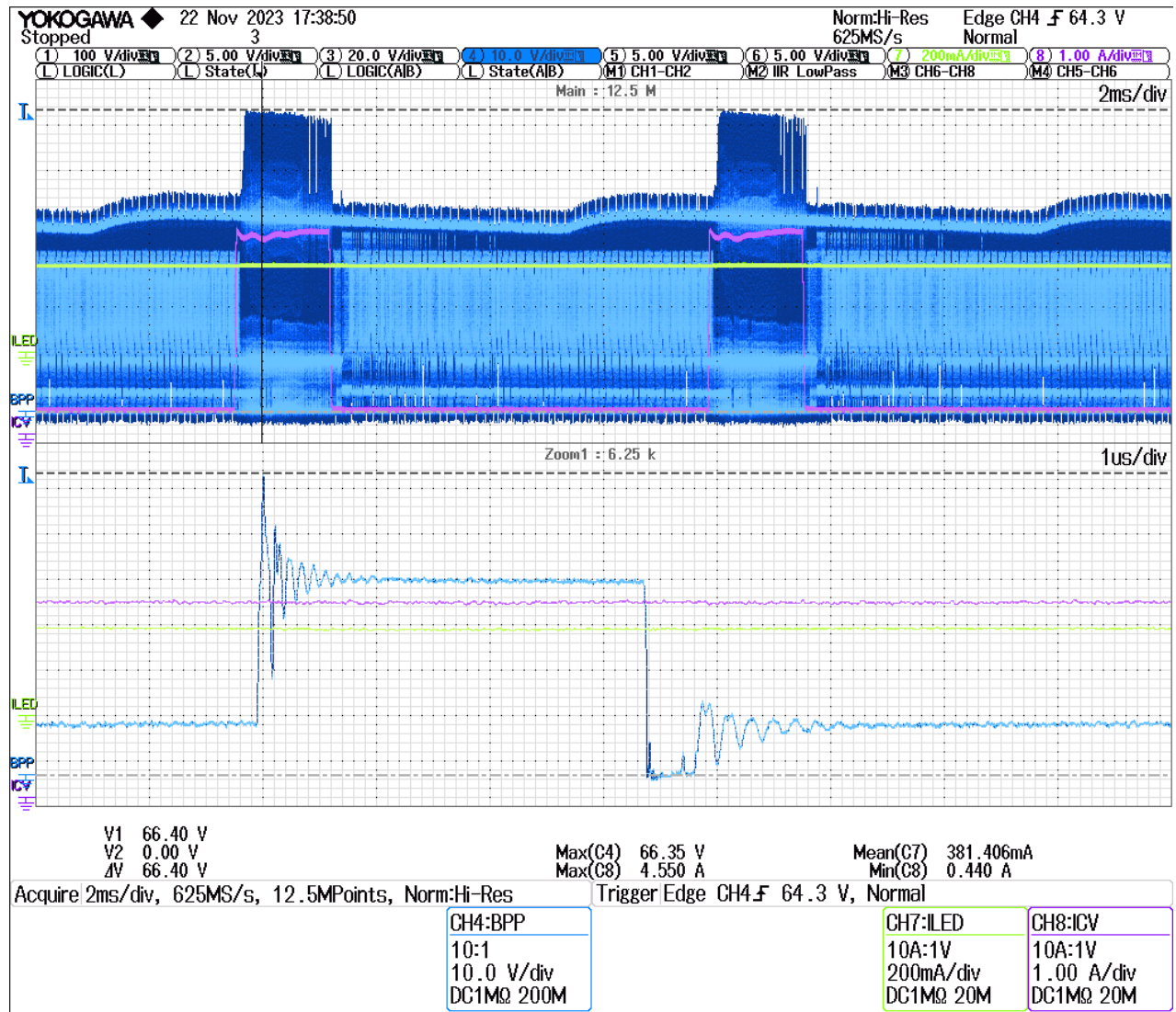


Figure 73 – Auxiliary Diode Reverse Voltage under Peak Load at 90 VAC.

Ch4: V_{BPPWNDNG}, Ch7: I_{LED}, Ch8: I_{cV}

Maximum reverse voltage across the Auxiliary winding diode is 66 V.

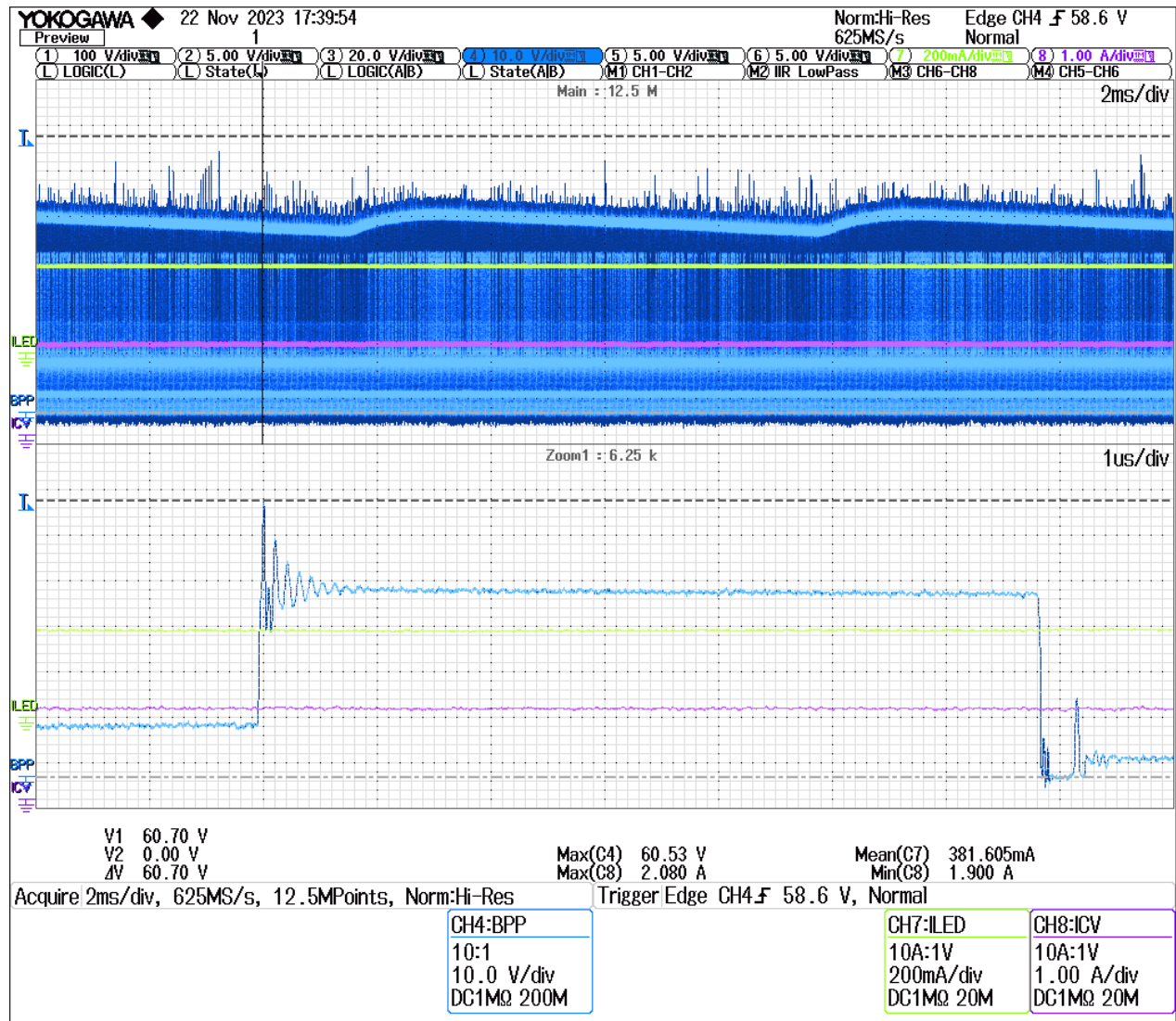


Figure 74 – Auxiliary Diode Reverse Voltage under Nominal Load at 90 VAC.

Ch4: V_{BPPWNDNG}, Ch7: I_{LED}, Ch8: I_{CV}

Maximum reverse voltage across the Auxiliary winding diode is 61 V.

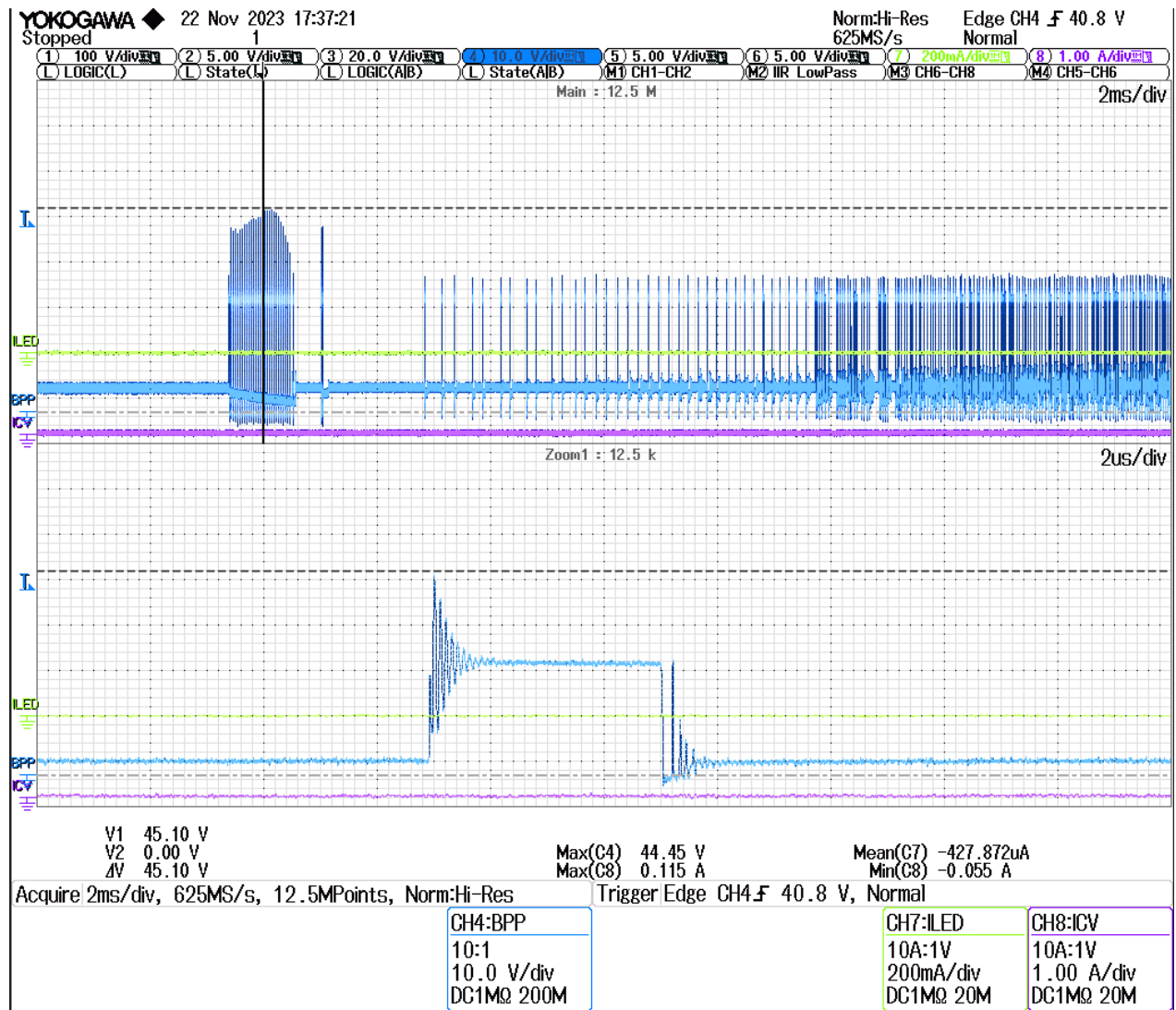


Figure 75 – Auxiliary Diode Reverse Voltage at Start-up at 90 VAC.

Ch4: V_{BPPWINDNG}, Ch7: I_{LED}, Ch8: I_{CV}

Maximum reverse voltage across the Auxiliary winding diode is 45 V.

8.20 Brown-Out and Brown-In

The brown-in and brown-out results were measured at full load on all outputs. The results are shown in the table below. Screenshots illustrating the tests are shown in Figures 76 and 77.

| Brown-Out Threshold | Brown-In Threshold |
|---------------------|---------------------|
| [V _{RMS}] | [V _{RMS}] |
| 63.5 | 73.3 |

Table 3 – Brown-In and Brown-Out Thresholds at Full power.



Figure 76 – Brown-Out Response at Full Power.

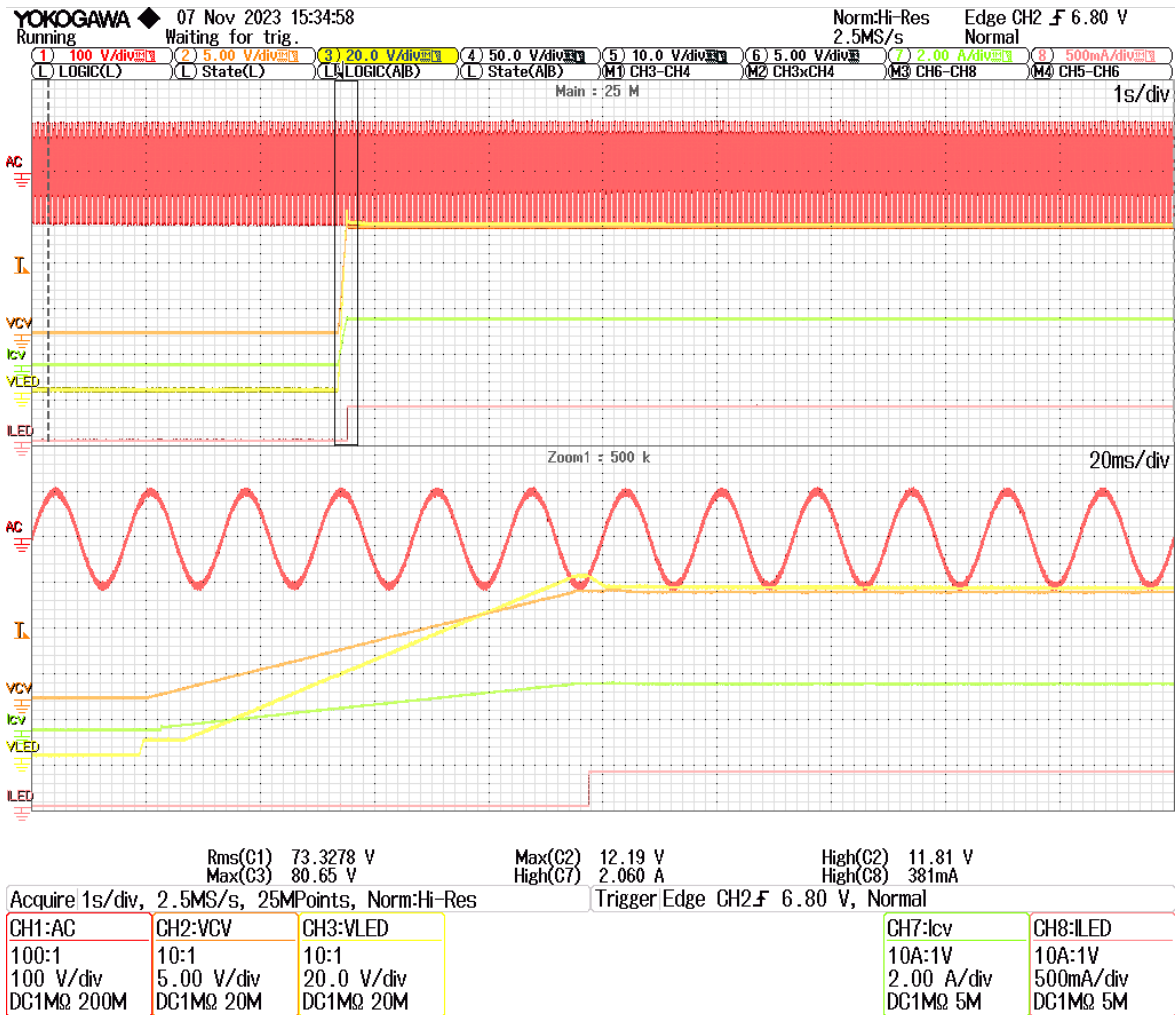


Figure 77 – Brown-In Response at Full Power.

8.21 Output Protections

8.21.1 CV Output Overvoltage Protection

The overvoltage protection threshold of the CV output was tested. Additional charge was injected into the output filter capacitor of the output under test until the converter went into a restart. The test was carried out at line voltages 115 V with full LED current.

In all cases of LED no-load and full load and CV no-load and full-load, OV protection disables the system at 13.48 V - 13.52 V which is around 112% of nominal CV voltage.

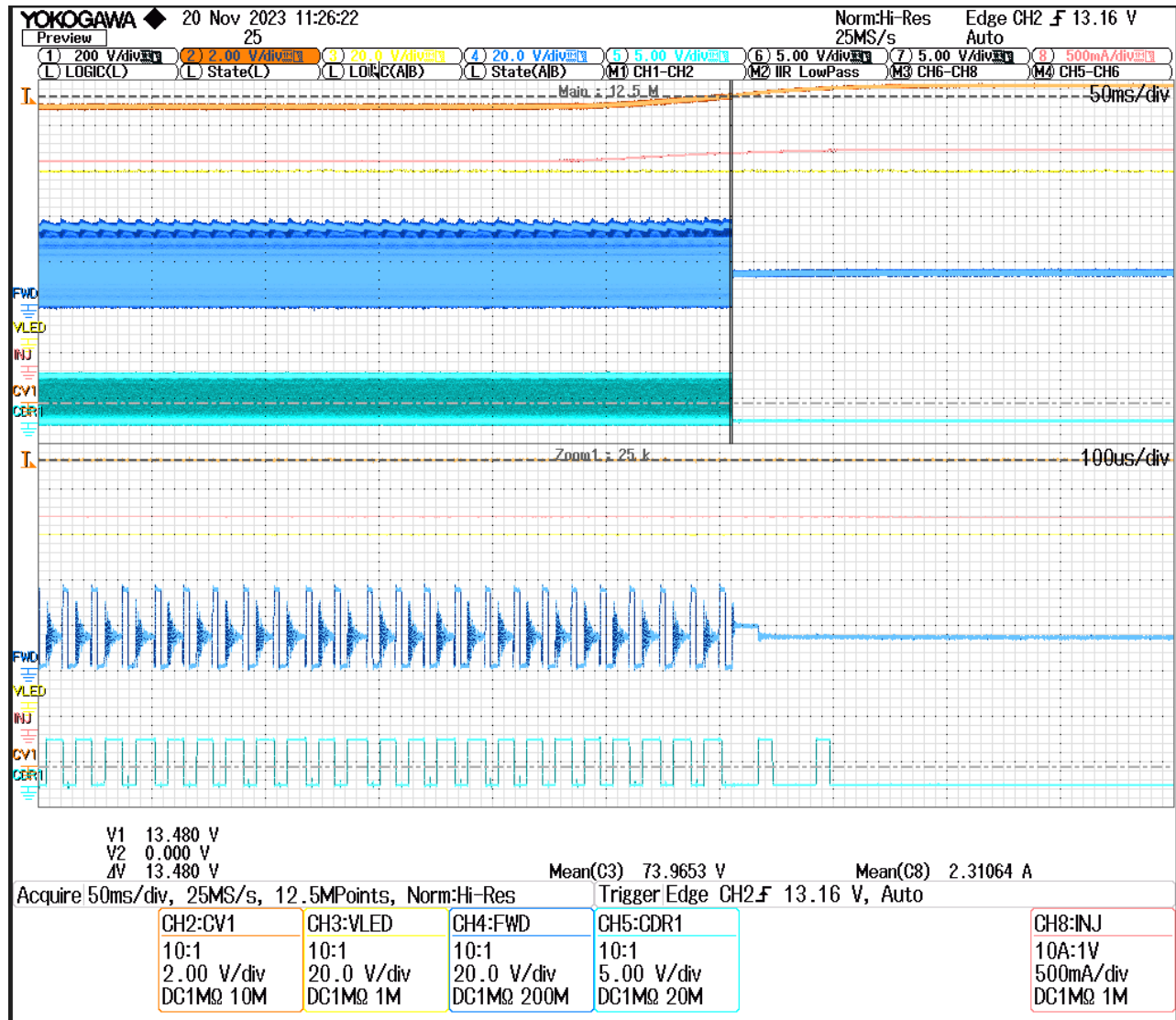


Figure 78 – CV OVP at Full LED Load.

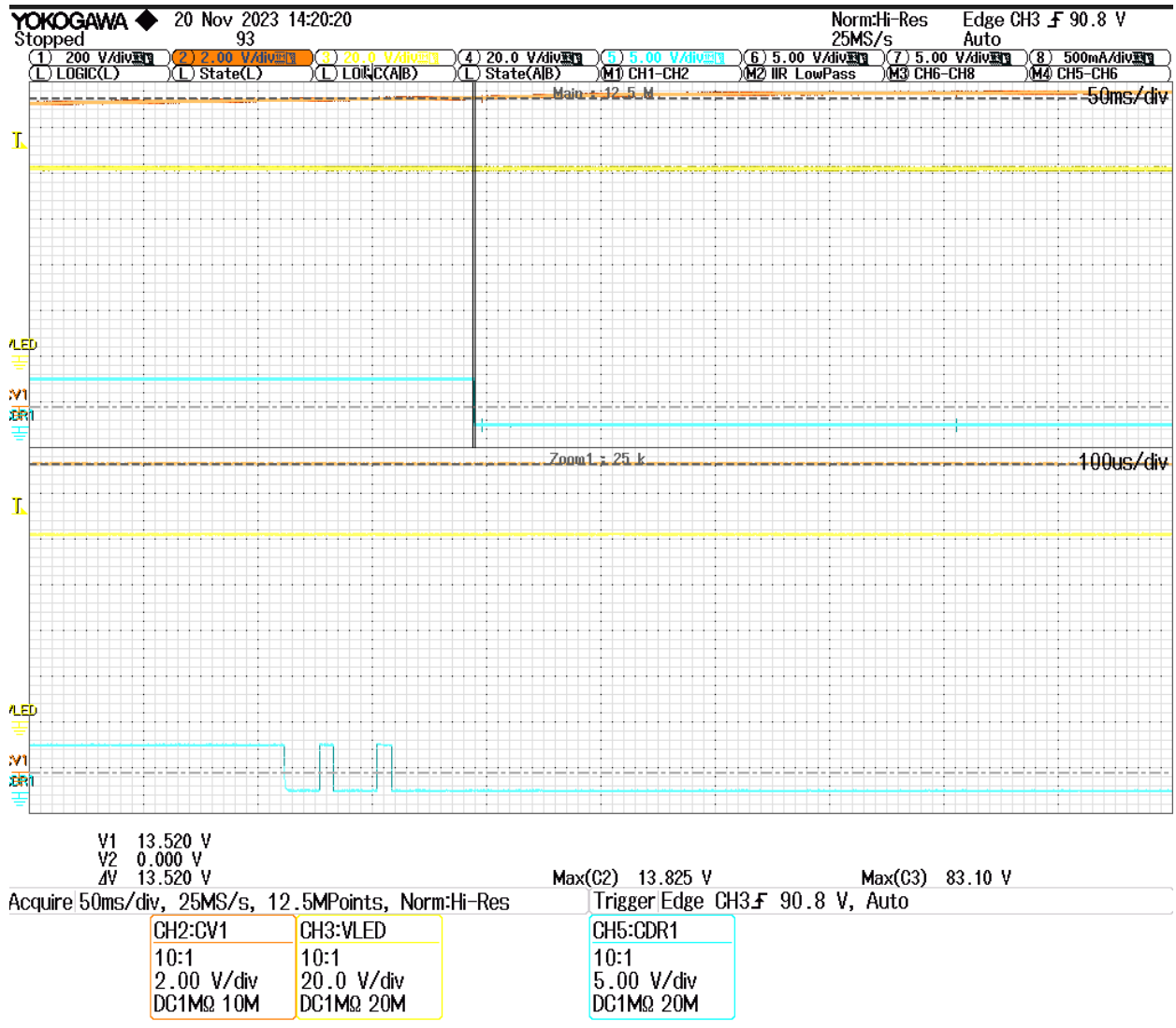


Figure 79 – CV OVP No LED Load.

8.21.2 LED Output Overvoltage Protection

The overvoltage protection thresholds of the LED output were tested at full power on CV output. CDR1 gate opens at steady-state to charge the LED capacitors for triggering LED overvoltage protection.

LED OVP has been triggered at 93.4 V which is 116% of LED voltage.

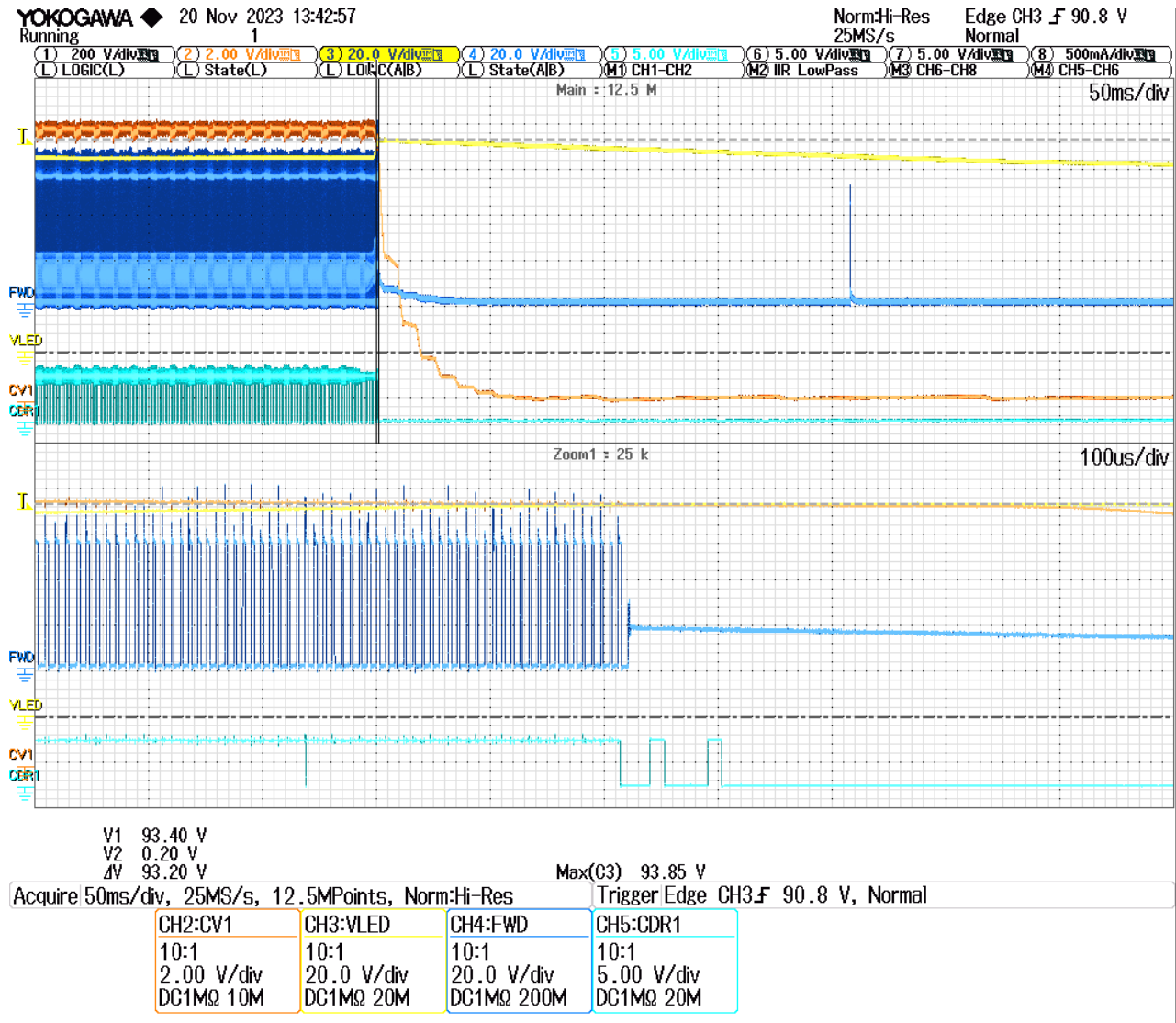


Figure 80 – LED OVP.

8.22 Output Ripple Measurements

8.22.1 Ripple Measurement Technique

For DC output ripple measurements, a modified oscilloscope test probe were utilized in order to reduce noise pick-up. Details of the probe modification are provided in Figure .

The probe adapter is shown in Figure . It includes a coaxial cable with two parallel capacitors connected to the points of measurement. The capacitors include a 0.1 μF / 100 V ceramic type and a 10 μF / 50 V aluminum electrolytic type. The aluminum electrolytic type capacitor is polarized, so proper polarity across DC outputs must be ensured.

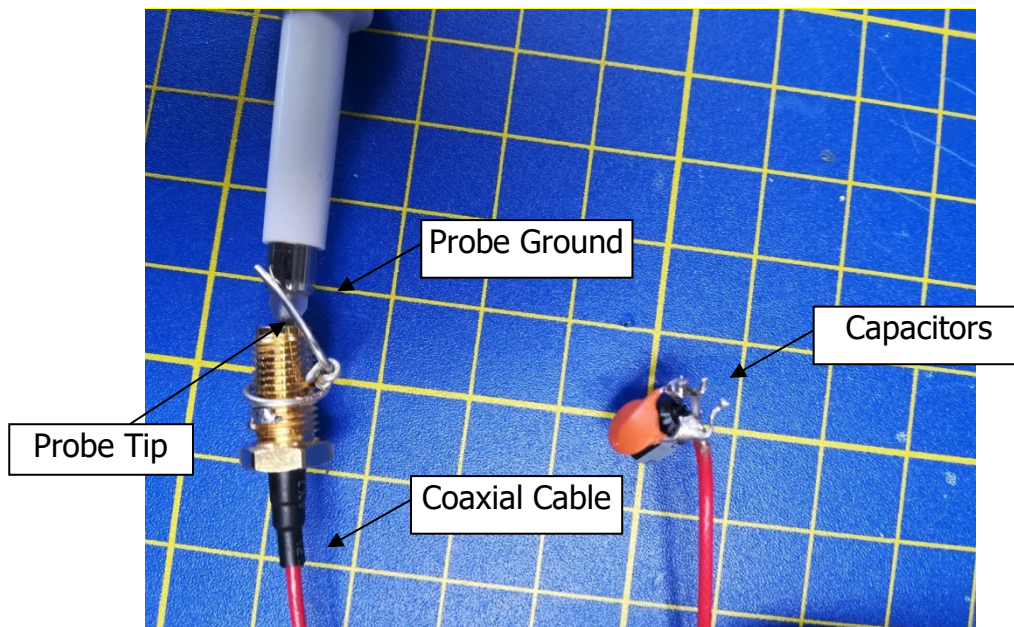


Figure 81 – Oscilloscope Probe Used in Ripple Measurement.

8.22.2 CV Output Ripple

8.22.2.1 Test Set-up

- 90 VAC – 265 VAC
- Output 12 V @ 24 W and LED_72 V @ 27, 36 W
- 200 MHz bandwidth in the scope, 100 nF ceramic capacitor and 10 μF @ 50 V electrolytic capacitor with sniffing connected to output pin

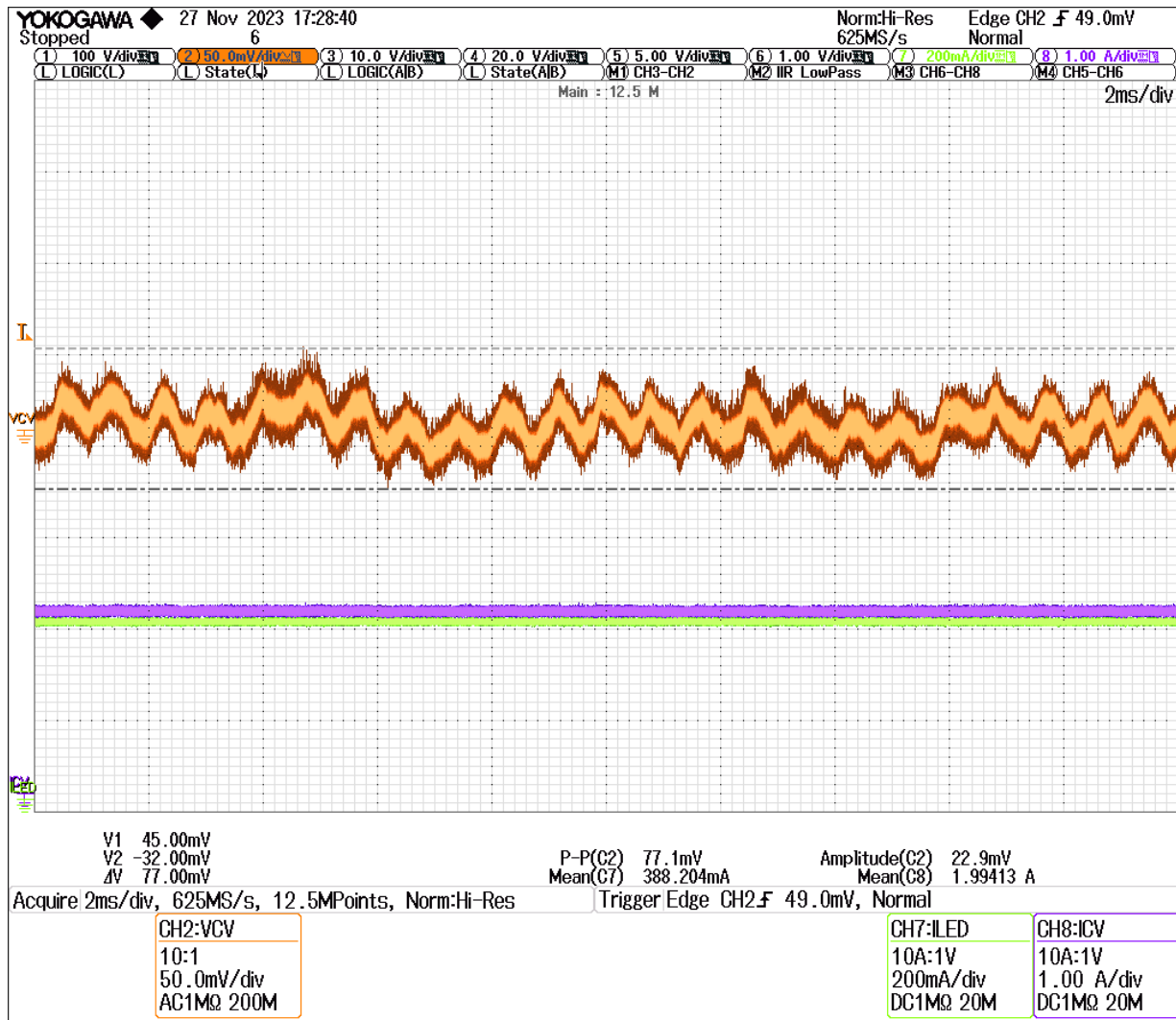


Figure 82 – VCV Ripple and Noise under nominal load at 90 VAC.

CH2: V_{CV}, CH7: I_{LED}, CH8: I_{CV}

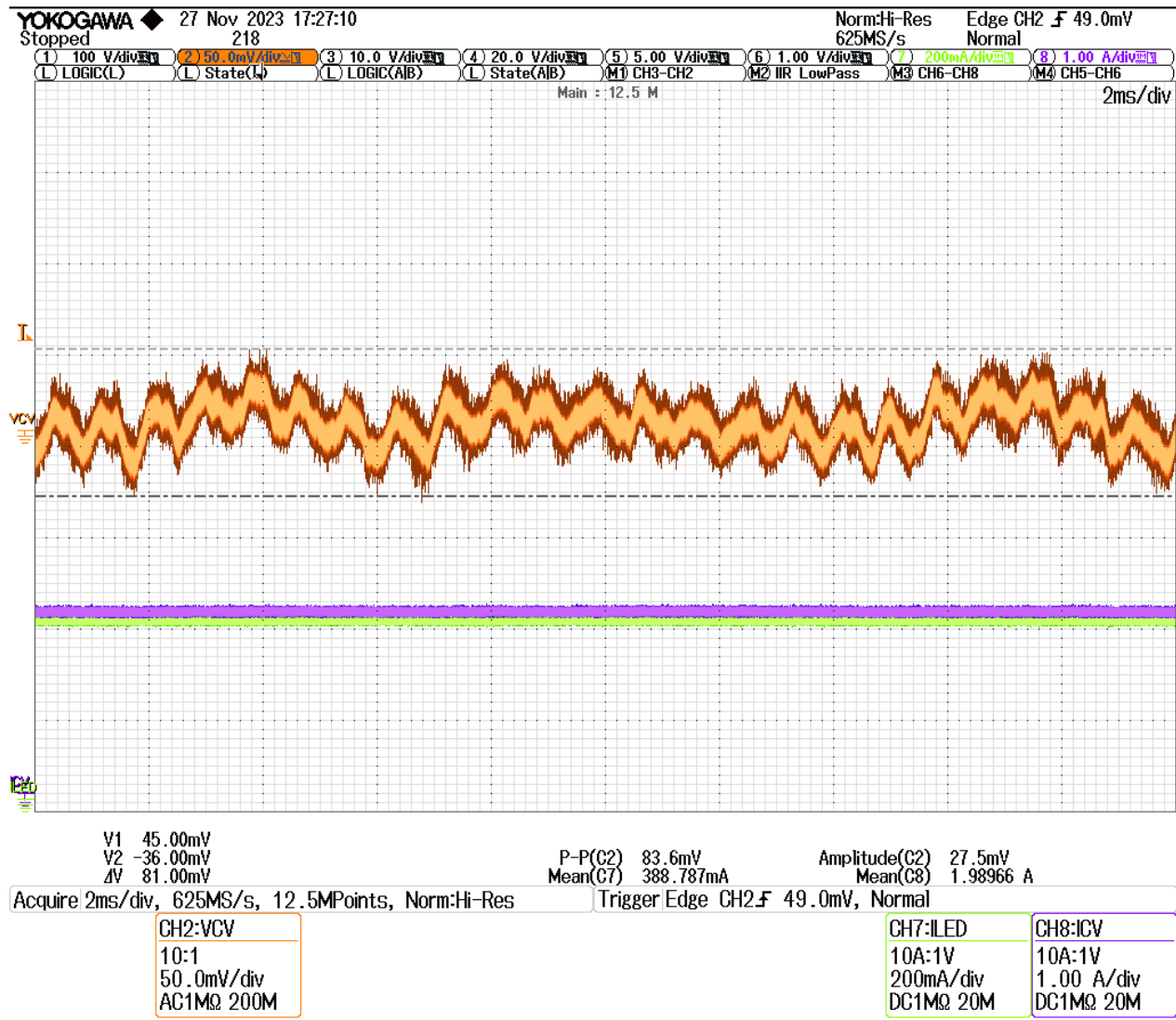


Figure 83 – VCV Ripple and Noise under nominal load at 265 VAC.

CH2: V_{CV}, CH7: I_{LED}, CH8: I_{CV}

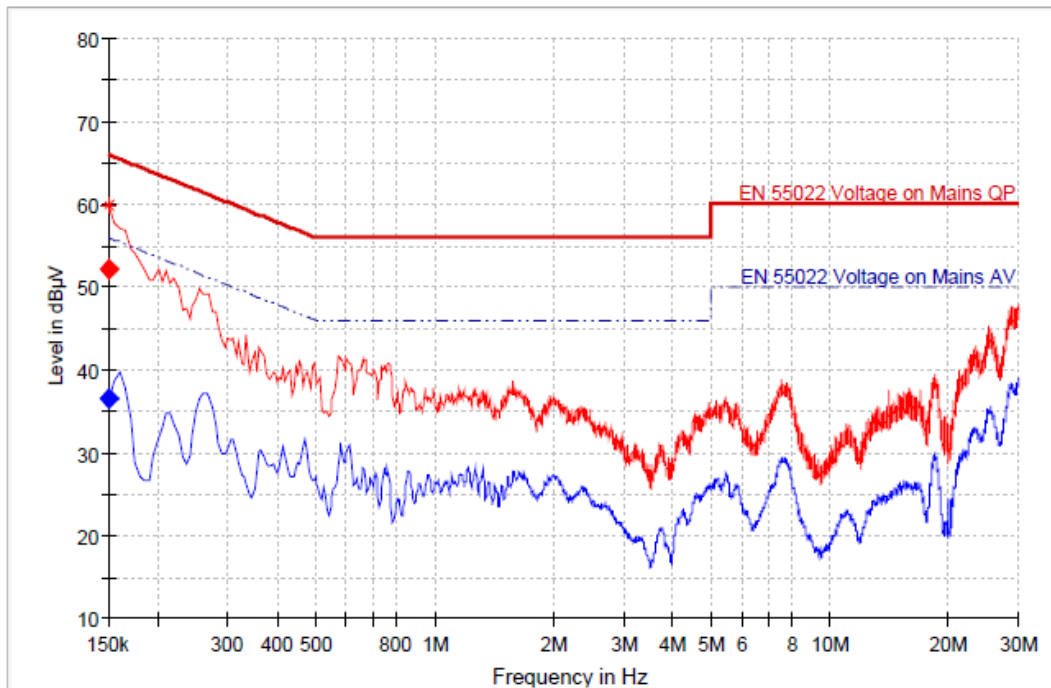
The worst-case ripple and noise at the CV output of the converter was measured as 84 mV_{P-P} at 200 MHz bandwidth at the connector output.

9 Conducted EMI

The EMI scans were carried out at full power. PE connection was not considered in the test to simulate a TV system.

The conducted emissions were more than 8 dB below the limits set by CISPR22B / EN55022B.

9.1 Line Input 115 VAC

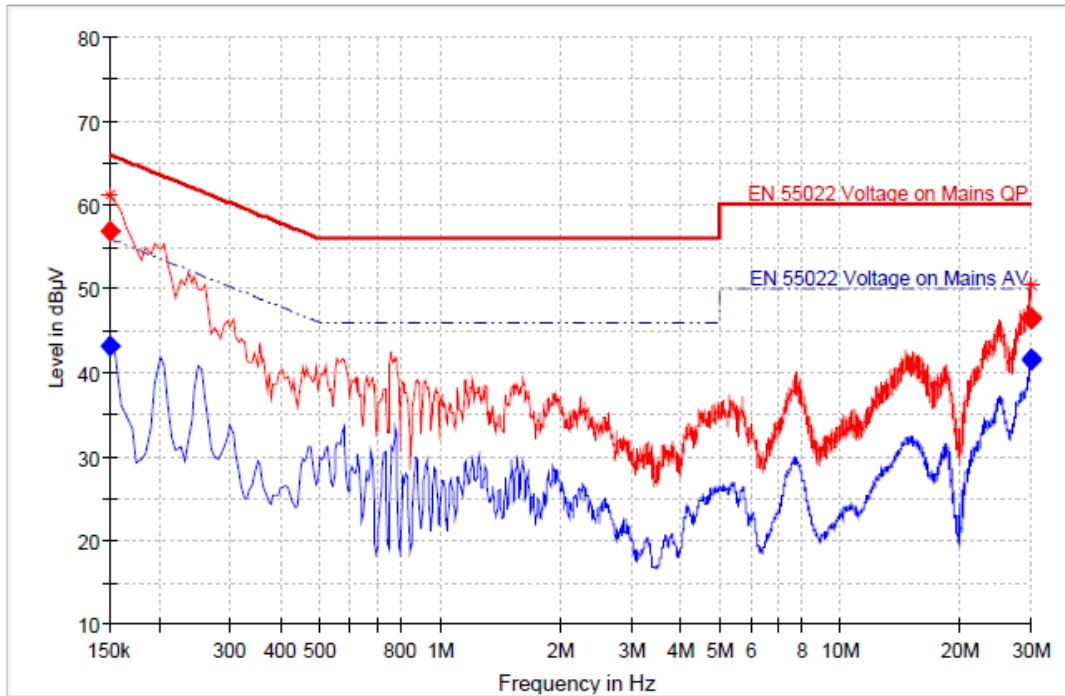


Final Result

| Frequency (MHz) | QuasiPeak (dBµV) | Average (dBµV) | Limit (dBµV) | Margin (dB) | Bandwidth (kHz) | Line | Filter | Corr. (dB) |
|-----------------|------------------|----------------|--------------|-------------|-----------------|------|--------|------------|
| 0.150000 | --- | 36.56 | 56.00 | 19.44 | 10.000 | N | ON | 20.3 |
| 0.150000 | 52.13 | --- | 66.00 | 13.87 | 10.000 | N | ON | 20.3 |

Figure 84 – EMI Test Results at 115 V.

9.2 Line Input 230 VAC



Final Result

| Frequency (MHz) | QuasiPeak (dBµV) | Average (dBµV) | Limit (dBµV) | Margin (dB) | Bandwidth (kHz) | Line | Filter | Corr. (dB) |
|-----------------|------------------|----------------|--------------|-------------|-----------------|------|--------|------------|
| 0.150000 | --- | 43.12 | 56.00 | 12.88 | 10.000 | N | ON | 20.3 |
| 0.150000 | 56.83 | --- | 66.00 | 9.17 | 10.000 | N | ON | 20.3 |
| 29.935000 | --- | 41.54 | 50.00 | 8.46 | 10.000 | N | ON | 20.4 |
| 29.935000 | 46.57 | --- | 60.00 | 13.43 | 10.000 | N | ON | 20.4 |
| 29.965000 | --- | 41.59 | 50.00 | 8.41 | 10.000 | N | ON | 20.4 |
| 29.965000 | 46.44 | --- | 60.00 | 13.56 | 10.000 | N | ON | 20.4 |

Figure 85 – EMI Test Results at 230 V.

10 Thermal Performance

There are no heat sinks in cooling arrangements of the assembly. Copper pours are used for the cooling of the control IC. No forced air-cooling was deployed during the test. The temperatures of the hottest components in the assembly are shown in the table. Ambient temperature is 23 ±2°C.

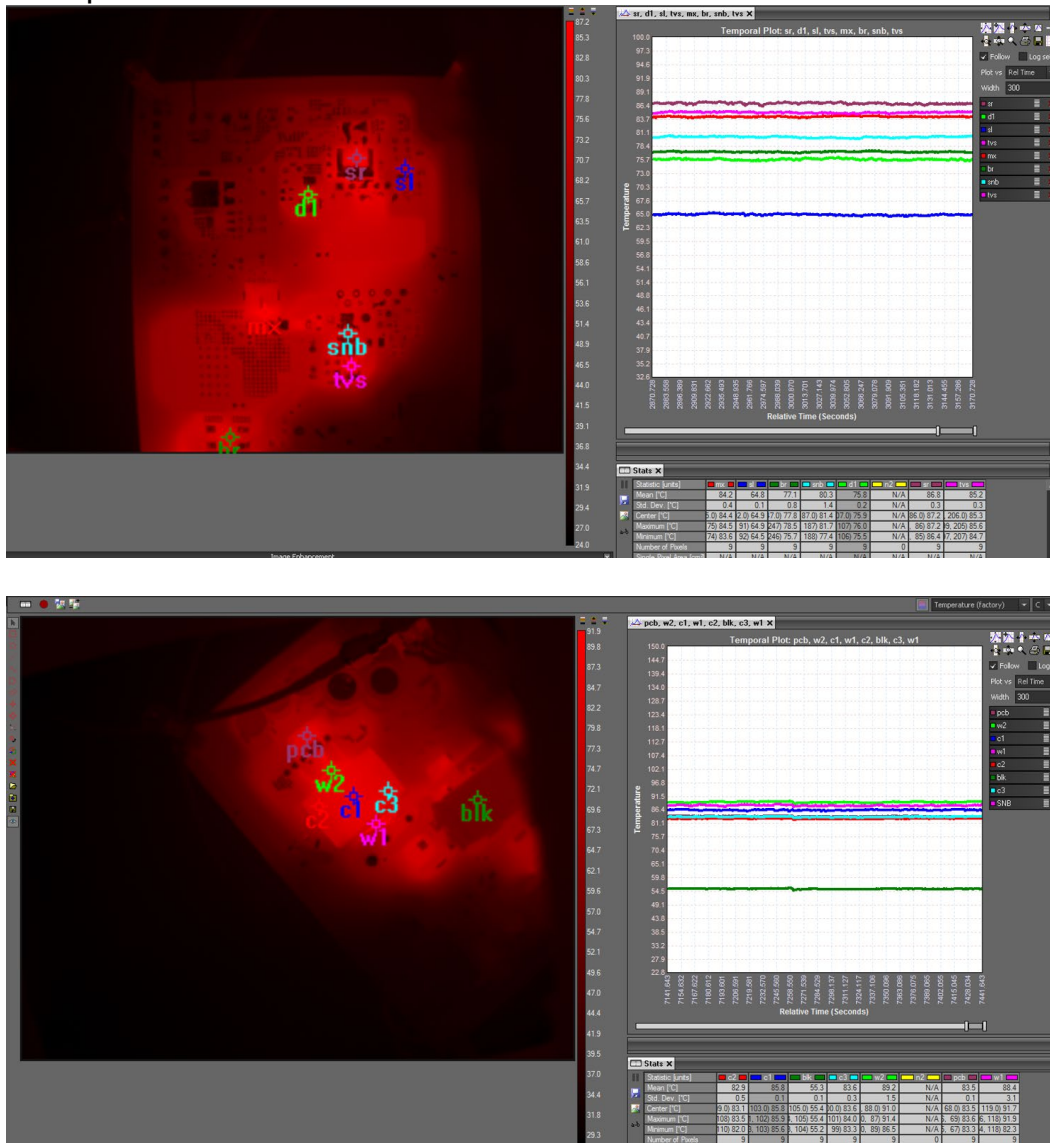


Figure 86 – Line = 90 V Nominal Power - Thermal Image – Bottom and Top Views.

| PART | U1 IC | BR1 BRIDGE | VR2 SNUB TVS | SNUB RES | D1 LED DIODE | Q1 SEL FET | D8 SR DIODE | TRF CORE | TRF WINDING |
|---------|-------|------------|--------------|----------|--------------|------------|-------------|----------|-------------|
| T [°C] | 84.2 | 77.8 | 85.2 | 80.3 | 75.8 | 64.8 | 87.2 | 85.9 | 91 |
| ΔT [°C] | 63.2 | 56.8 | 64.2 | 59.3 | 54.8 | 43.8 | 66.2 | 64.9 | 70 |

Table 9 – Line = 90 V Full Power – Component Case Temperatures.

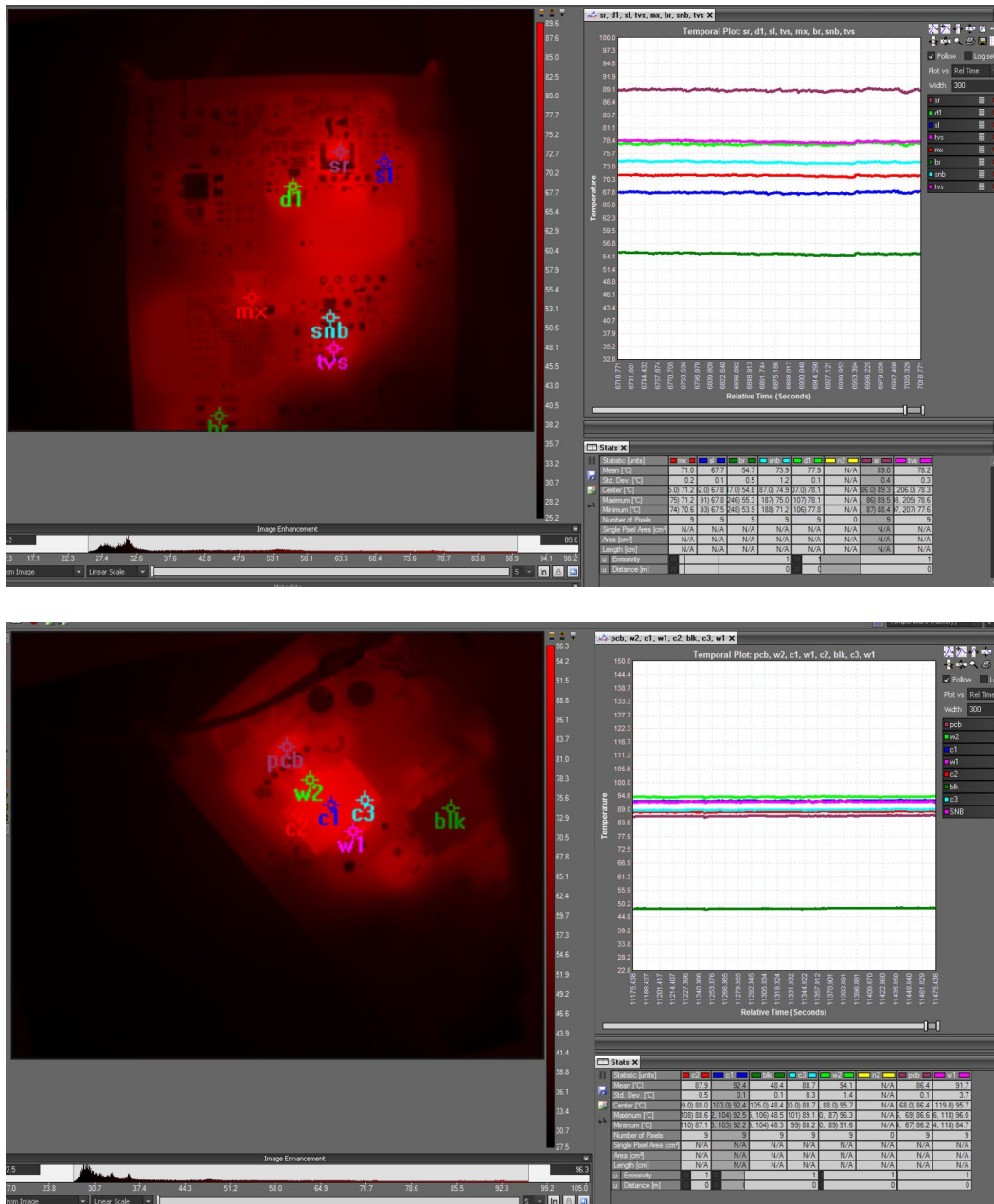


Figure 87 – Line = 265 V Nominal Power - Thermal Image – Bottom and Top Views.

| PART | U1 IC | BR1 BRIDGE | VR2 SNUB TVS | SNUB RES | D1 LED DIODE | Q1 SEL FET | D8 SR DIODE | TRF CORE | TRF WINDING |
|---------|-------|------------|--------------|----------|--------------|------------|-------------|----------|-------------|
| T [°C] | 71 | 54.7 | 78.2 | 73.9 | 77.9 | 67.7 | 89.5 | 92.4 | 94.1 |
| ΔT [°C] | 50 | 33.7 | 57.2 | 52.9 | 56.9 | 46.7 | 69.5 | 71.4 | 73.1 |

Table 9 – Line = 265 V Full Power – Component Case Temperatures.

11 Audible Noise Performance

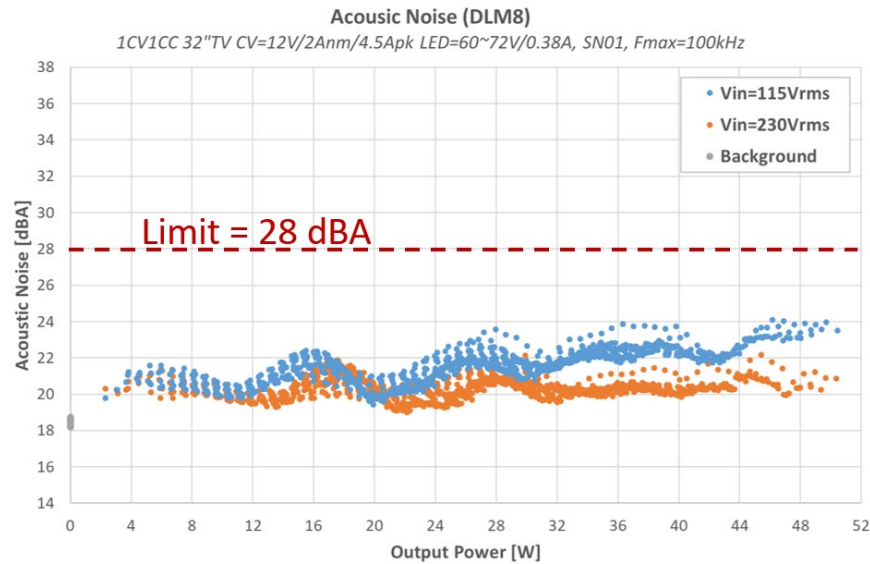


Figure 87 – Audible Noise at Normal Operation Mode.

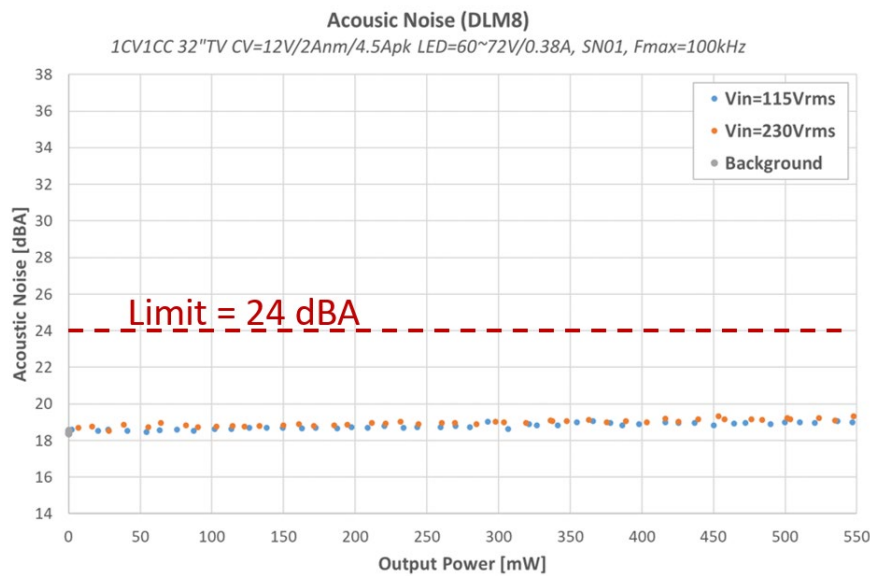


Figure 88 – Audible Noise at Standby Mode.

12 Combination Wave Surge Test

The unit was subjected to ± 1000 V differential mode and ± 2000 V common mode combination wave surge at several line phase angles with 5 strikes for each condition.

A test failure was defined as an output latch-off that needs operator intervention to recover, or a complete loss of function that is not recoverable.

12.1 Differential Mode Surge (L1 to L2), 230 VAC Input

| Surge Level (V) | Injection Location | Injection Phase (°) | Test Result |
|-----------------|--------------------|---------------------|-------------|
| +1000 | L1 to L2 | 0 | Pass |
| -1000 | L1 to L2 | 0 | Pass |
| +1000 | L1 to L2 | 90 | Pass |
| -1000 | L1 to L2 | 90 | Pass |
| +1000 | L1 to L2 | 180 | Pass |
| -1000 | L1 to L2 | 180 | Pass |
| +1000 | L1 to L2 | 270 | Pass |
| -1000 | L1 to L2 | 270 | Pass |

Table 10 – Differential Mode Surge Test Result.

12.2 Common Mode Surge (L1 to PE), 230 VAC Input

| Surge Level (V) | Injection Location | Injection Phase (°) | Test Result |
|-----------------|--------------------|---------------------|-------------|
| +2000 | L1 to PE | 0 | Pass |
| -2000 | L1 to PE | 0 | Pass |
| +2000 | L1 to PE | 90 | Pass |
| -2000 | L1 to PE | 90 | Pass |
| +2000 | L1 to PE | 180 | Pass |
| -2000 | L1 to PE | 180 | Pass |
| +2000 | L1 to PE | 270 | Pass |
| -2000 | L1 to PE | 270 | Pass |

Table 11 – Common Mode Surge Test Result – L1 to PE.

PE is connected to secondary GND to perform common mode test.

12.3 Common Mode Surge (L2 to PE), 230 VAC Input

| Surge Level (V) | Injection Location | Injection Phase (°) | Test Result |
|-----------------|--------------------|---------------------|-------------|
| +2000 | L2 to PE | 0 | Pass |
| -2000 | L2 to PE | 0 | Pass |
| +2000 | L2 to PE | 90 | Pass |
| -2000 | L2 to PE | 90 | Pass |
| +2000 | L2 to PE | 180 | Pass |
| -2000 | L2 to PE | 180 | Pass |
| +2000 | L2 to PE | 270 | Pass |
| -2000 | L2 to PE | 270 | Pass |

Table 12 – Common Mode Surge Test Result – L2 to PE.

PE is connected to secondary GND to perform common mode test.

12.4 Common Mode Surge (L1+L2+PE), 230 VAC Input

| Surge Level (V) | Injection Location | Injection Phase (°) | Test Result |
|-----------------|--------------------|---------------------|-------------|
| +2000 | L2 to PE | 0 | Pass |
| -2000 | L2 to PE | 0 | Pass |
| +2000 | L2 to PE | 90 | Pass |
| -2000 | L2 to PE | 90 | Pass |
| +2000 | L2 to PE | 180 | Pass |
| -2000 | L2 to PE | 180 | Pass |
| +2000 | L2 to PE | 270 | Pass |
| -2000 | L2 to PE | 270 | Pass |

Table 13 – Common Mode Surge Test Result – L1, L2 and PE.

PE is connected to secondary GND to perform common mode test.

12.5 ESD Test

The unit was tested with ± 15 kV air discharge and ± 8 kV contact discharge with 10 strikes for each condition at the following locations at 230 VAC and 115 VAC:

- VCV+
- VCV-

A test failure was defined as an output latch-off that needs operator intervention to recover, or a complete loss of function that is not recoverable.

| Contact Discharge (kV) | ESD Location | Input Voltage (VAC) | Test Result |
|------------------------|--------------|---------------------|-------------|
| +8 | VCV+ | 115 | Pass |
| -8 | VCV+ | 230 | Pass |
| +8 | VCV- | 115 | Pass |
| -8 | VCV- | 230 | Pass |

Table 14 – Contact Discharge Test Result.

| Air Discharge (kV) | ESD Location | Input Voltage (VAC) | Test Result |
|--------------------|--------------|---------------------|-------------|
| +15 | VCV+ | 115 | Pass |
| -15 | VCV+ | 230 | Pass |
| +15 | VCV- | 115 | Pass* |
| -15 | VCV- | 230 | Pass |

*power supply might initiate AR

Table 15 – Air Discharge Test Result.

13 Revision History

| Date | Author | Revision | Description & Changes | Reviewed |
|-------------|---------------|-----------------|----------------------------------|-----------------|
| 26-Feb-24 | YL | 1.0 | Initial Release. | Apps & Mktg |
| | | | | |
| | | | | |
| | | | | |

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